

YAESU

FT-1000MP

HF Transceiver

Technical Supplement



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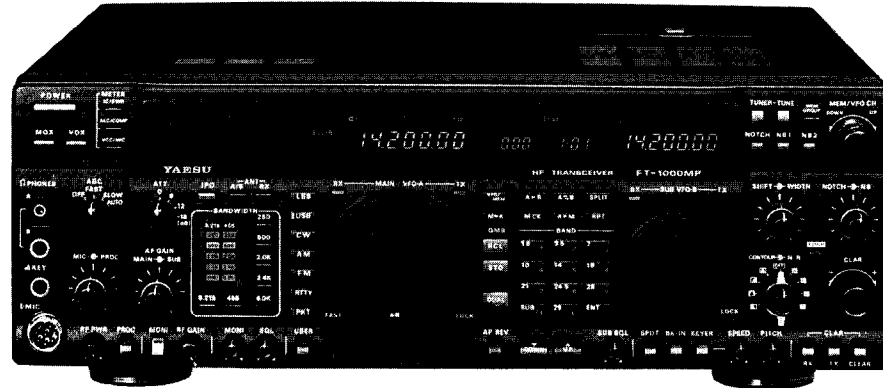
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FT-1000MP
Technical Supplement



This manual provides technical information necessary for servicing the Yaesu FT-1000MP HF transceiver. It does not include information on installation and operation, which are described in the FT-1000MP Operating Manual, provided with each transceiver, or on FT-1000MP accessories, which are described in manuals provided with each.

The FT-1000MP is carefully designed to allow the knowledgeable operator to make nearly all adjustments required for various station conditions, modes and operator preferences simply from the controls on the panels, without opening the case of the transceiver. The FT-1000MP Operating Manual describes these adjustments, plus certain internal settings.

Servicing this equipment requires expertise in handling surface mount chip components. Attempts by non-qualified persons to service this equipment

may result in permanent damage not covered by warranty. For the major circuit boards, each side of the board is identified by the type of the majority of components installed on that side. In most cases one side has only chip components, and the other has either a mixture of both chip and lead components (trimmers, coils, electrolytic capacitors, packaged ICs, etc.), or lead components only.

While we believe the technical information in this manual is correct, Yaesu assumes no liability for damage that may occur as a result of typographical or other errors that may be present. Your cooperation in pointing out any inconsistencies in the technical information would be appreciated. Yaesu Musen reserves the right to make changes in this transceiver and the alignment procedures, in the interest of technological improvement, without notification of the owners.

Specification

General

Rx frequency range: 100 kHz — 30 MHz
 Tx frequency ranges: 160 -10m amateur bands only
 Freq. Stability: $< \pm 10$ ppm ($-10 \sim +50^\circ\text{C}$)
 $< \pm 2.0$ ppm ($0^\circ \sim +50^\circ\text{C}$) w/TCXO-4
 $< \pm 0.5$ ppm ($0^\circ \sim +50^\circ\text{C}$) w/TCXO-6
 Freq. Accuracy: $< \pm 7$ ppm (except FM, $< \pm 500$ Hz)
 w/TCXO-4: $< \pm 2$ ppm (FM $< \pm 460$ Hz)
 w/TCXO-6 $< \pm 0.5$ ppm (FM $< \pm 500$ Hz)
 Operating temperature Range: $(-10 \sim +50^\circ\text{C})$
 Emission modes: LSB, USB, CW, FSK, AM, FM
 Frequency steps: 0.625/1.25/2.5/5/10 Hz for SSB,
 CW, RTTY & Packet; 100 Hz for AM and FM
 Antenna impedance: 50 Ω unbalanced
 Power Consumption:

Input	Rx (no signal)	Rx (signal)	Tx (100W)
100~125 VAC	70 VA	80 VA	550 VA
200~240 VAC	80 VA	90 VA	600 VA
13.8 VDC	2.4 A	2.8 A	19 A

Supply voltage: 100~125, 200~234 VAC, 50/60 Hz
 Dimensions (WHD): 410 × 135 × 347 mm
 Weight (approx.): 15 kg. (33 lbs)

Transmitter

Power output: adjustable up to 100 watts
 (25 watts AM carrier)
 Duty cycle: 100% @ 50 watts, 50% @ 100 watts
 (FM & RTTY, 3-minute Tx)
 Modulation types:
 SSB: J3E Balanced, filtered carrier
 AM: A3E Low-level (early stage)
 FM: F3E Variable reactance
 AFSK: J1D, J2D Audio frequency shift keying
 Maximum FM deviation: ± 2.5 kHz
 FSK shift frequencies: 170, 425 and 850 Hz
 Packet shift frequencies: 200, 1000 Hz
 Harmonic radiation: at least 50 dB below peak output

SSB carrier suppression: at least 40 dB below peak output
 Undesired sideband suppression: at least 50 dB below peak output
 Audio response (SSB): not more than -6 dB from 400 to 2600 Hz
 3rd-order IMD: -31 dB @ 100 watts PEP, or better
 Microphone impedance: 500 to 600 Ω

Receiver

Circuit type: quad-conversion superheterodyne
 (triple conversion for FM)
 Intermediate frequencies: **Main Rx** **Sub Rx**
 70.455 MHz 47.21 MHz
 8.215 MHz 455 kHz
 455 kHz

(with preamp on, for 10 dB S/N, 0 dB μ - 1 μ V)				
Frequency \Rightarrow Mode (BW) \downarrow	150 - 250 kHz	250 - 500 kHz	0.5 - 1.8 MHz	1.8 - 30 MHz
SSB, CW (2.4 kHz)	5 μ V	4 μ V	2 μ V	0.25 μ V
AM (6 kHz)	40 μ V	32 μ V	16 μ V	2 μ V
29-MHz FM (12 dB SINAD)	—	—	—	0.5 μ V

Sensitivity:
 Selectivity ($-6/-60$ dB):
 Dynamic Range: 108 dB (@50 kHz, 500-Hz BW, IPO on)
 Squelch sensitivity:
 1.8 ~ 30 MHz (CW, SSB, AM): < 2.0 μ V
 28 ~ 30 MHz (FM): < 0.32 μ V
 IF rejection (1.8 ~ 30 MHz): 80 dB or better (Main Rx)
 60 dB or better (Sub Rx)
 Image rejection (1.8 ~ 30 MHz): 80 dB or better (Main)
 50 dB or better (Sub)
 IF shift range: ± 1.12 kHz
 Max. audio output: 1.5 W into 4 Ω with $< 10\%$ THD
 Audio output impedance: 4 to 8 Ω

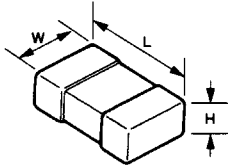
Specifications are subject to change, in the interest of technical improvement, without notice or obligation.

Chip Component Information

Chip Component Information

The diagrams below indicate some of the distinguishing features of common chip components.

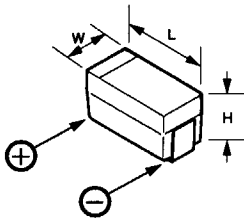
Capacitors



(Unit: mm)

Type	L	W	H
2125	2.0	1.25	0.35~0.50
1608	1.6	0.8	0.65~0.95
1005	1.0	0.5	0.45~0.55

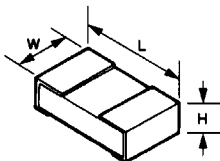
Tantalum Capacitors



(Unit: mm)

Type	L	W	H
P	2.0	1.25	1.2
A	3.2	1.6	1.6
B	3.4	2.8	1.9
C	5.8	3.2	2.3

Resistors



Type RMC 1/10W, 1/16W

Marking* 100, 222, 473 ...

Indicated Letters

1 2 3 4
5 6 7 :
9 0 .

(Unit: mm)

Type	L	W	H
1/10	2.0	1.25	0.5
1/16	1.6	0.8	0.45
1/16S	1.0	0.5	0.35

473

Ten unit	One unit	Multiplier code
0	0	10 ⁰
1	1	10 ¹
2	2	10 ²
3	3	10 ³
4	4	10 ⁴
5	5	10 ⁵
6	6	10 ⁶
7	7	10 ⁷
8	8	10 ⁸
9	9	10 ⁹

Examples:

100 = 10Ω
 222 = 2.2kΩ
 473 = 47kΩ

Chip Component Information

Replacing Chip Components

Chip components are installed at the factory by a series of robots. The first one places a small spot of adhesive resin at the location where each part is to be installed, and later robots handle and place parts using vacuum suction.

For single sided boards, solder paste is applied and the board is then baked to harden the resin and flow the solder. For double sided boards, no solder paste is applied, but the board is baked (or exposed to ultra-violet light) to cure the resin before dip soldering.

In our laboratories and service shops, small quantities of chip components are mounted manually by applying a spot of resin, placing with tweezers, and then soldering by very small dual streams of hot air (without physical contact during soldering). We remove parts by first removing solder using a vacuum suction iron, which applies a light steady vacuum at the iron tip, and then breaking the adhesive with tweezers.

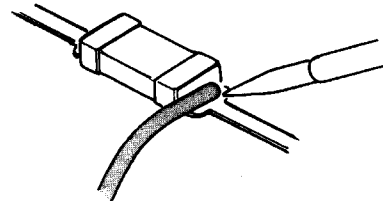
The special vacuum/desoldering equipment is recommended if you expect to do a lot of chip replacements. Otherwise, it is usually possible to remove and replace chip components with only a tapered, temperature-controlled soldering iron, a set of tweezers and braided copper solder wick. Soldering iron temperature should be below 280° C (536° F).

Precautions for Chip Replacement

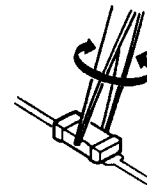
- Do not disconnect a chip forcefully, or the foil pattern may peel off the board.
- Never re-use a chip component. Dispose of all removed chip components immediately to avoid mixing with new parts.
- Limit soldering time to 3 seconds or less to avoid damaging the component and board.

Removing Chip Components

- Remove the solder at each joint, one joint at a time, using solder wick whetted with non-acidic fluxes as shown below. Avoid applying pressure, and do not attempt to remove tinning from the chip's electrode.



- Grasp the chip on both sides with tweezers, and gently twist the tweezers back and forth (to break the adhesive bond) while alternately heating each electrode. Be careful to avoid peeling the foil traces from the board. Dispose of the chip when removed.

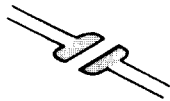


- After removing the chip, use the copper braid and soldering iron to wick away any excess solder and smooth the land for installation of the replacement part.

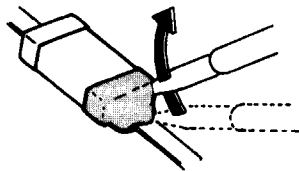
Installing a Replacement Chip

As the value of some chip components is not indicated on the body of the chip, be careful to get the right part for replacement.

- Apply a small amount of solder to the land on one side where the chip is to be installed. Avoid too much solder, which may cause bridging (shorting to other parts).



- Hold the chip with tweezers in the desired position, and apply the soldering iron with a motion line as indicated by the arrow in the diagram below. Do not apply heat for more than 3 seconds.



- Remove the tweezers and solder the electrode on the other side in the manner just described.

Chip Component Information

Notes:

As the value of some chip components is not indicated on the body of the chip, be careful to get the right part for replacement.

Apply a small amount of solder to the lead on one side where the chip is to be installed. Avoid too much solder, which may cause bridging (shorting to other parts).



Hold the chip with tweezers in the desired position, and apply the soldering iron with a motion line as indicated by the arrow in the diagram below. Do not apply heat for more than 3 seconds.



Remove the tweezers and solder the electrode on the other side in the manner just described.

Transceiver Disassembly & PCB Unit Access

Disassembly Tips

The FT-1000MP uses over 35 individual unit/assemblies, interconnected for maximum performance and compactness. With the exception of routine installations (filters, options, backup battery replacement, etc.), we do not recommend further disassembly. Circuit repair and alignment require familiarity with complex analog and digital circuitry, and access to the specialized test equipment needed for circuit analysis. Therefore, we recommend repairs be conducted by at an authorized repair facility via the Yaesu dealer where the unit was purchased.

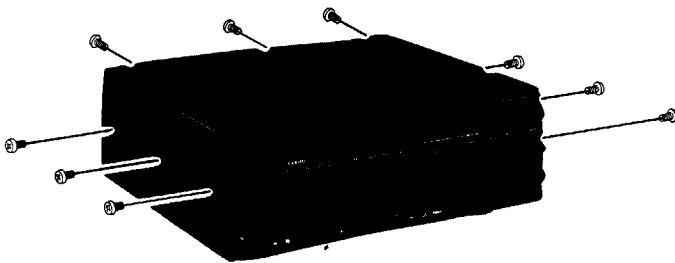
When proceeding with transceiver disassembly, keep the following items in mind -

- Various types of screws sizes and thread pitch are used - separate screws and keep them with the unit they were removed from.
- When unplugging wiring connectors or mini coax cables, make note of any color coding to facilitate easy identification during reassembly.

Top Cover Removal

Turn the transceiver off, and disconnect all cables. Remove the 9 screws affixing the top cover, then tilt and pull the cover off. This exposes the ALC and ANT Units.

⚠ Warning! - high voltages present inside!



ALC & ANT Unit

- Remove the 4 screws from the plate (cradle) mounting the ALC and ANT Units, being careful not to lose the two copper grounding strips on the rear pair of screws. Also note how the tin grounding strap from the RX2 Unit is affixed.

- Tilt the mounting plate up slightly, then slide it forward and upward to loosen the assembly. Flip the unit over to expose the TUNER Unit underneath
- To remove the ANT Unit, desolder the leads from the two SO-239 jacks and ground lead. Remove the green-banded coax from J8702, the plug from J8701, and the two mounting screws from the PCB to free the ANT Unit.
- To remove the ALC Unit, remove the plugs from jacks J6801, 6802, 6803, 6804, 6805, 6806, 6807, 6808, 6809, 6810, and 6811, being careful to note lead color coding. Remove the 3 mounting screws from the PCB to free the ALC Unit.

TUNER Unit

- Flip the mounting plate over to expose the TUNER Unit, then remove the red and green banded coax cables from their respective connectors.
- Remove the three plugs from jacks J6504, 6505, and 6506. Next remove the 3 mounting screws affixing the TUNER Unit to the mounting plate

Loudspeaker Unit

- Remove the 4 rubber-grommeted screws from the loudspeaker frame-mount to loosen the assembly.
- Next remove the red and black leads to free the speaker and mount, exposing the EDSP Unit. To remove the speaker from its mount, remove the remaining 4 screws

LOCAL Unit

- Remove 1 rear-panel screw and the 6 remaining screws from the steel plate to expose the LOCAL Unit.
- To remove the LOCAL Unit, remove the amber, green and blue-banded coax cables, the plugs from J4005, 4006, 4007, 4008, 4009, and the ribbon cable from J4004. Next remove its 5 mounting screws and lift the unit free.

EDSP Unit

- Remove the two screws from the mounting tabs to loosen the EDSP Unit.
- Remove the red and blue banded plug from J7001, then remove the 4 screws affixing the shield cover and remove the cover to expose the DSP-A Unit.

Transceiver Disassembly & PCB Unit Access

- Remove the 3 mounting screws to loosen the DSP-A PCB, then remove the flat ribbon cable from J7003 to remove the DSP-A Unit.
- Remove the 4 screws from the remaining cover to expose the DSP-B Unit. Next remove the plugs from J7101 and 7102, and the remaining 2 screws to remove the DSP-B Unit PCB.

DC Fan

- Remove the 2 screws from the fan mounting bracket to loosen the unit.

PA/LPF Assembly

- Remove the remaining 4 screws from the aluminum PA Unit heatsink (the other 2 screws were removed in the previous step), and lift the unit slightly to loosen it.
- On the underside of the unit, remove the single screw affixing the cover plate, and remove the plate to expose the PA and LPF Units.
- Remove the amber, green, and red color-coded coax cables from J6002, 6003, and 6005, and the regular coax cable from J6001 on the LPF Unit.
- On the PA Unit, remove the plug from J6203, the amber color-coded coax cable from J6201, and the red & black DC leads from J6204 & 6205.
- To remove the LPF Unit with its frame assembly from the aluminum heatsink, remove the 4 screws from the from, and lift the unit free.
- To remove the LPF Unit from the frame, remove the four mounting screws and free the unit.
- To remove the PA Unit from the aluminum heatsink, remove the four mounting screws from drive and PA transistors Q6001, 6205, 6202 and 6203. Next, remove the 4 mounting screws from the PCB to free the Unit.
- Take care not to lose the mica insulator sheet for Q6001, and do not remove the paper insulator cutout affixed to the heatsink surface.

RF Unit

- Remove the 4 screws from the steel mounting plate from which the LPF-PA heatsink assembly was previously removed to expose the RF and REG Units.
- To remove the RF unit, first remove the coax cables from J1003, 1004, 1006, 1007, 1011, and 1013. Desolder the solder bead attaching the copper grounding sheet to the REG Unit.
- Next, remove the plug from J1010, and the flat ribbon cable from J1012. Now remove the 2 rear-

panel screws from the **BAND DATA** jack, then the 5 screws from the RF Unit PCB.

- Slide the RF Unit forward so that the rear panel connectors clear the rear panel, then

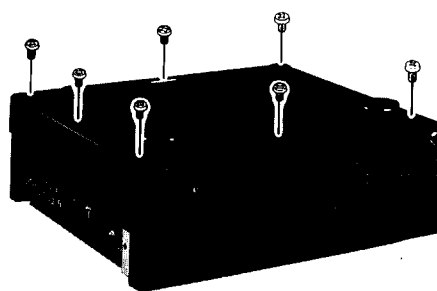
REG Unit

- To remove the REG Unit, first remove the 9 plugs from J9003, 9004, 9009, 9010, 9011, 9013, 9014, 9015, and 9017 (the fan unit can now be freed at this time). Next remove the 6 wiring leads from each screw terminal, carefully noting lead colors.
- Remove the single screw from the chassis side, then the 4 screws from the REG Unit PCB to free the unit (be careful not to remove the 3 screws attaching the REG Unit PCB to the regulator heatsink).

Bottom Cover Removal

- With the top cover off, remove the 7 screws affixing the bottom cover, then tilt and pull the cover off. This exposes the IF, AF, and CNTL Units on the bottom chassis, and the RX2 and REF Units on the left chassis side.

Warning! - high voltages present inside!



REF Unit (left side chassis)

- To remove the REF Unit, remove the 4 mounting screws from the PCB and free the unit.

RX2 Unit (left side chassis)

- To remove the RX2 Unit, first remove the flat ribbon cable from J8003, then the plug from J8001.
- Remove the 6 mounting screws from the PCB, slide the PCB forward slightly and lift it free.

Transceiver Disassembly & PCB Unit Access

CNTL Unit (chassis bottom)

- To remove the CNTL Unit, first remove the flat ribbon cables from J5003, 5004, 5008, 5009, 5010, 5014, 5015, 5016, 5017, 5018, 5019, 5026, 5030, and 5032.
- Next remove the plugs from J5001, 5002, 5011, 5013, 5020, 5021, 5022, and 5031.
- Remove the 6 mounting screws from the PCB, and the 2 screws affixing the rear panel DB-9 (CAT) jack.
- Slide the PCB forward slightly and lift it free.

AF Unit (chassis bottom)

- To remove the AF Unit, first remove the flat ribbon cables from J3006, 3015, 3024, 3028, and 3029.
- Next remove the plugs from J3003, 3004, 3005, 3007, 3012, 3013, 3017, 3018, 3022, 3026, 3031, 3032, 3033, 3035, 3037.
- Remove the 6 rear-panel screws affixing the DVS-3, PACKET, and RTTY jacks, then the 6 mounting screws affixing the AF Unit PCB.
- Slide the PCB forward slightly, tilt, and lift the unit free.

IF Unit

- To remove the IF Unit, first remove the flat ribbon cables from J2004, 2013, and 2014.
- Next, remove the plugs from J2002, 2009, 2011, and 2012. Then, remove the blue, amber, and yellow color-coded coax cables from J2007, 2003, and 2005, respectively. Also remove the coax cable from J2008.
- Remove the 6 mounting screws from the PCB to free the unit.

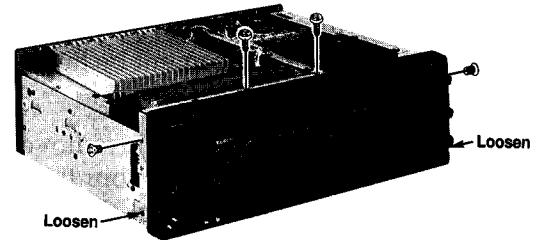
Front Panel Disassembly

- Remove the 2 large screws from the center of each side panel, and the 2 screws from the panel top. Also loosen the 2 screws at the bottom of each side panel.
- Slide the front panel assembly forward slightly, then fold it open and down. Take care to unravel the twisted white cable from its nylon tie down to permit folding the front panel fully.

AC Switched-Mode Power Supply

- To remove the power supply, first remove the two nylon plugs from their connectors on the power supply case, and front chassis cutout (for the front connector, first remove the plug, then use a small

 **Warning!** - high voltages present inside!



flat screwdriver to press the locking tabs in to remove the jack).

- Remove the 2 mounting screws from the main chassis, and the 2 from the chassis front to free the unit.

Display Unit

- To remove the display unit, first remove the plugs from jacks J5501, 5505, 5506, 5507, 5508, 5509, 5516, 5519, 5520, 5521, 5522, 5523, 5524, 5525, 5526, 5527, 5528, and 5529.
- Disconnect the flat ribbon cables from J5502, 5503, 5504, 5510, 5511, and 5518.
- Remove the 6 mounting screws from the PCB, and pull off the **AGC** and **ATT** knobs from the front panel.
- Slide the PCB forward, tilt and lift it free. This now exposes the KEY Unit, VR A, B, C, D, E, and F Units, SW Units A, B, C, and D, MIC and HP Units.

INV Unit

- First remove the 3 screws affixing the shield cover to expose the INV Unit.
- Unplug the Display Unit power cord from jack CN3 to free the Display Unit, then remove the 2 mounting screws from the PCB to free the INV unit.

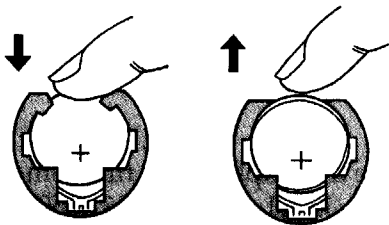
This completes overall transceiver disassembly, and further disassembly is not recommended.

Battery/Fuse Replacement & CPU Resetting

Lithium Battery Replacement

A 3-V Type CR2032 Lithium Battery (BT5001) is located on the CNTL UNIT board (underside) of the transceiver. This maintains the memorized data in your radio. Battery life is normally greater than five years, however, should replacement be needed, perform the following steps:

- With the top and bottom covers removed, note the location of the battery. Using your finger, slide the battery inward (you will feel slight pressure by the mounting spring), then slightly pry it up and outward so that it ejects freely through the slots in the battery holder.
- Carefully note battery polarity with the positive (+) side facing upward, and battery-type information. Install the replacement battery in the reverse manner.



Memory Back-Up Switch

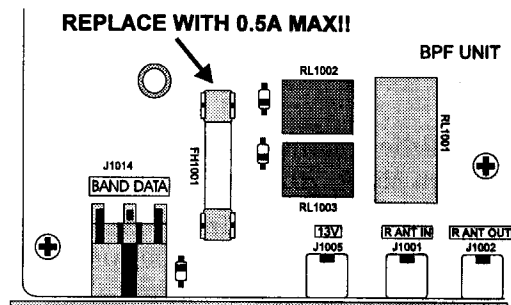
The rear panel memory **BACK UP** switch is normally kept in the ON position to ensure your memorized data is maintained (by a small amount of power from the lithium battery) when the radio is off, or the DC power source is removed.

- If you do not plan to operate your radio for extended periods of time, slide this switch to the OFF position to conserve battery life.
- Ensure the radio is on when sliding the switch back to the ON position, as this reduces the initial current demand on the battery by the radio's circuits from an un-powered state.
- Note: Memorized settings are lost and the radio returns to factory default settings when turning off the backup battery.

Internal 13.5V Fuse Replacement

The rear panel **13.5V** jack provides regulated, *separately fused* 13.5 VDC at up to 200 mA, to power external low-current devices. If your device requires more current, use a separate power source. In the event the internal fuse blows, it can be replaced. However, this requires moderate transceiver disassembly.

- With the top cover removed, locate the two screws mounting the fan assembly to the PA Unit heat sink. Remove the screws and move the fan assembly to one side.
- Remove the remaining four heat sink screws and lift the PA assembly from the chassis. You will need to unplug the mini coax (with the yellow band) from the RX ANT IN connector on the BPF UNIT.
- Remove the four screws from the PA Unit mount, and remove the mount to expose the BPF UNIT, and fuse labeled FH1001 (below).



- Using a pair of fuse pullers, remove the blown fuse and replace only with a similar fast-blow type fuse (0.5A maximum).

Reassemble the PA UNIT mount, yellow-banded coax cable, PA UNIT, and fan assembly in reverse order, then replace the top cover.

CPU Keypad Reset

You can return *all transceiver settings* (menu selections) to their default values at any time by performing a CPU reset. Simply hold the **MEM**, **ENT** & **ENT** keys together while turning the transceiver on.

Introduction and Precautions

The following procedures cover adjustments that are not normally required once the transceiver has left the factory. However, if damage occurs and some parts subsequently be replaced, realignment may be required. If a sudden problem occurs during normal operation, it is likely due to component failure; realignment should not be done until after the faulty component has been replaced.

We recommend that servicing be performed by authorized Yaesu service technicians, experienced with the circuitry and fully equipped for repair and alignment. If a fault is suspected, contact the selling dealer for instructions regarding repair. Authorized Yaesu service technicians have the latest modification information, and realign all circuits and make complete performance checks to ensure compliance with factory specifications after repairs.

Those who do undertake any of the following alignments are cautioned to proceed at their own risk. Problems caused by unauthorized attempts at realignment are not covered by the warranty policy. Also, Yaesu must reserve the right to change circuits and alignment procedures in the interest of improved performance, without notifying owners. Under no circumstances should any alignment be attempted unless the normal function and operation of the transceiver are clearly understood, the cause of the malfunction has been clearly pinpointed and any faulty components replaced, and the need for realignment determined to be absolutely necessary.

The following test equipment (and thorough familiarity with its correct use) is necessary for complete realignment. Correction of problems caused by misalignment resulting most step do not require all of the equipment listed, the interactions of some adjustments may require that more complex adjustments be performed afterwards. Do not attempt to perform only a single step unless it is clearly isolated electrically from all other steps. Rather, have all test equipment ready before beginning, and follow all of the steps in a section in the order they are presented.

Required Test Equipment

- Digital DC Voltmeter (high-Z, 1M Ω /V)
- RF Millivoltmeter

- AC Voltmeter
- RF Standard Signal Generator w/ calibrated output and dB scale, 0 dB μ =0.5 μ V
- AF Signal Generator with calibrated output
- Spectrum Analyzer or receiver (30 MHz)
- Frequency Counter
- 50- Ω Dummy Load (150~250 watts)
- 16.6- Ω Dummy load (150 watts)
- In-Line Wattmeter (150~250 watts, 50- Ω)
- Linear Detector
- RF Attenuator (150 watts, 40 dB) or coupler

Alignment Preparation & Precautions

A 50- Ω dummy load and in-line wattmeter must be connected to the antenna jack in all procedures that call for transmission, except where specified otherwise. Correct alignment is not possible with an antenna. Except where specified otherwise, the transceiver should be tuned to 14.2000 MHz, USB mode, and these controls set as indicated:

- **MOX, VOX, AGC, PROC, IPO, ATT** OFF
- **MIC & RF PWR** fully CCW (minimum)
- **AF** as required
- **SQL** fully CCW (minimum)
- **NOTCH & SHIFT** to 12-o'clock

Read each step to determine if the same test equipment will be required. If not, remove the test equipment (except dummy load and wattmeter, if connected) before proceeding. Correct alignment requires that the ambient temperature be the same as that of the transceiver and test equipment, and that this temperature be held constant between 20~30°C (68~86°F). If the transceiver is brought into the shop from hot or cold air it should be allowed time for thermal equalization with the environment before alignment. Alignments must only be made with oscillator shields and circuit boards firmly affixed in place. Also, the test equipment must be thoroughly warmed up before beginning.

Note: Signal levels in dB referred to in alignment are based on 0 dB μ =0.5 μ V.

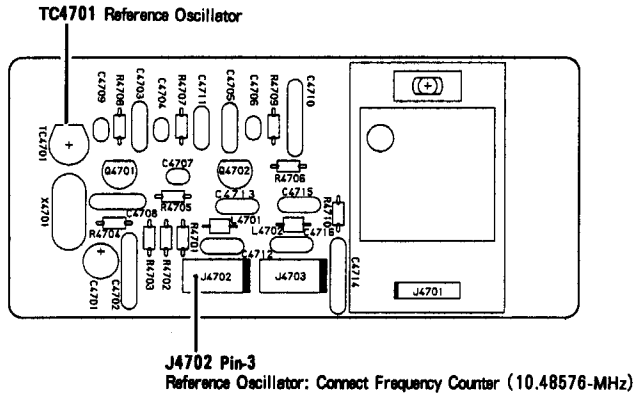
Table Note: DC voltages should be within $\pm 10\%$ of those listed in the voltage tables.

Alignment

REF Unit

Carrier Frequency

Refer to the photograph below for REF Unit component locations and alignment points.



RX2 UNIT Test & Alignment Points

- Connect the frequency counter to J4702 Pin 3 of the REF Unit. If the counter frequency differs by more than 5 Hz from 10.485760 MHz, adjust TC4701 as necessary.

RX2 Unit

Local Section 2nd OSC

Refer to the photograph at the page bottom for RX2 Unit component locations and alignment points.

- Connect the RF millivoltmeter to TP8004, then adjust T8018, T8016, T8017 in succession several times for peak RF millivoltmeter indication.

2nd Local Frequency

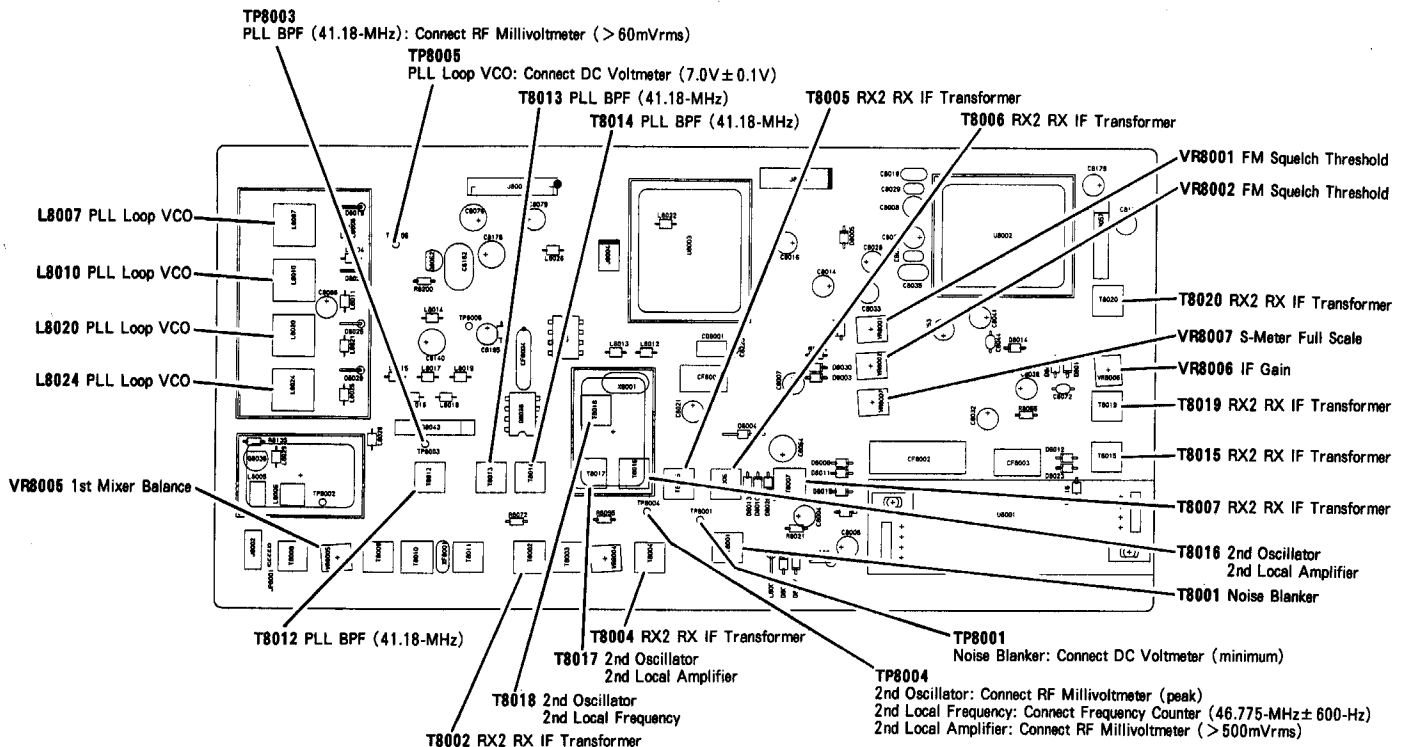
- Connect the frequency counter to TP8004, then adjust T8018 for 46.775 MHz \pm 600 Hz on the frequency counter.

2nd Local Amplifier

- Connect the RF millivoltmeter to TP8004, then adjust T8017, T8016 in succession several times for peak RF millivoltmeter indication (at least 500 mVrms).

PLL BPF

- Connect the RF millivoltmeter to TP8003, then adjust T8012, T8013, T8004 in succession several times for peak RF millivoltmeter indication (at least 60 mVrms).



RX2 UNIT Test & Alignment Points

PLL Loop VCO

- Connect the DC voltmeter to TP8005. Tune the transceiver display to the frequencies shown in the chart below, and adjust the components listed for the corresponding voltage, or else confirm required voltages.

PLL Loop VCO Alignment		
Tune to:	Adjust/Confirm	for
7.499 MHz	adjust L8007	$7.0 \pm 0.1V$
7.500 MHz	confirm	$1.8 \pm 0.5V$
14.499 MHz	adjust L8010	$7.0 \pm 0.1V$
14.500 MHz	confirm	$1.8 \pm 0.5V$
21.999 MHz	adjust L8020	$7.0 \pm 0.1V$
22.000 MHz	confirm	$2.0 \pm 0.5V$
30.000 MHz	adjust L8024	$7.0 \pm 0.1V$
0.100 MHz	confirm	$1.8 \pm 0.5V$

RX Section Interstage Transformers

- Connect the RF signal generator to the antenna jack, then select the transceiver to FM mode. Inject a RF signal modulated with ± 1.75 kHz deviation of a 1 kHz tone.
- Preset T8003 to within 3 turns from top of the coil case, then select SSB mode.
- Inject a RF signal (no modulation), and adjust T8002, T8004~T8007, T8015, T8019 and T8020 in succession several times for peak S-meter indication

(adjust the injection level as necessary to keep the meter around low scale).

IF Gain

- Inject a +8 dB μ signal to the antenna jack, and tune for peak on the S-meter. Adjust VR8006 for 1-dot S-meter deflection.

S-Meter Full Scale

- Inject +100 dB μ to the antenna jack, and tune for peak on the S-meter. Adjust VR8007 for S9 +60 dB on the S-meter.

1st Mixer Balance

- Set the VR8005 for 12-o'clock position.

FM squelch threshold

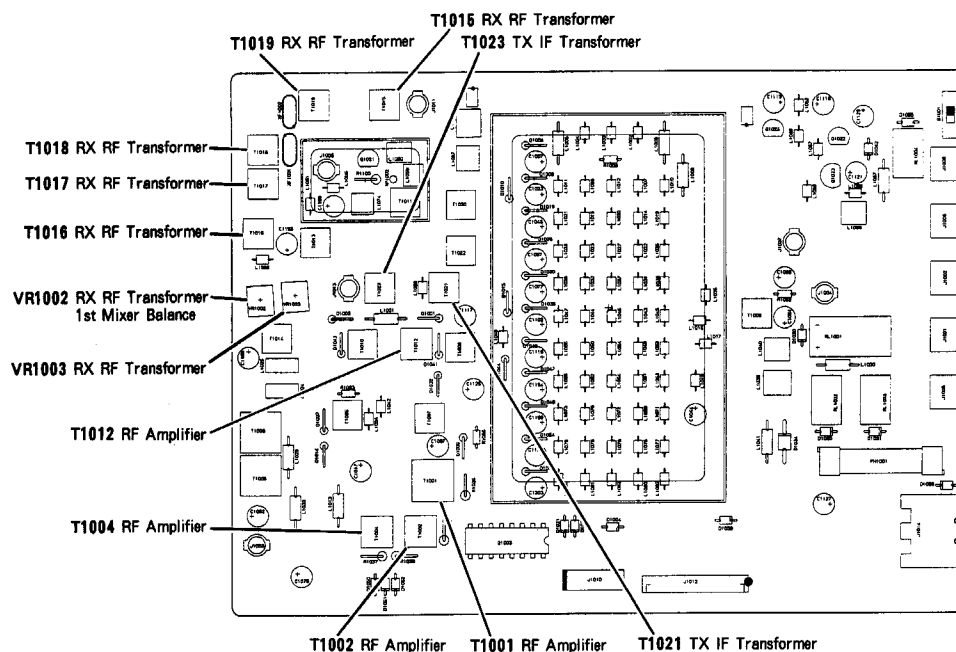
- In FM mode, with no signal at the antenna jack, set the **SQL** control 11-o'clock position. Adjust VR8001 so that the squelch just closes.

SSB Squelch Threshold

- In the SSB mode, with no signal at the antenna jack, set the **SQL** control 10-o'clock position. Adjust VR8002 so that the squelch just closes.

Noise Blanker

- Connect the DC voltmeter to TP8001, select **NB1** or **NB2**, then inject a +40 dBu signal to the antenna jack.
- Adjust T8001 for minimum indication in the DC voltmeter. Reduce the injection level +23 dBu and confirm less than 3.4 V.



RF Unit Test & Alignment Points

Alignment

Local Unit

Refer to the photograph at the page bottom for LOCAL Unit component locations and alignment points.

2nd Local Oscillator

- Connect the RF millivoltmeter to the TP4002, and adjust T4001 for maximum indication on the RF millivoltmeter (at least 400 mV_{RMS}).
- Replace the RF millivoltmeter with a frequency counter, and adjust T4001 for 62.240 MHz (± 200 Hz).

2nd Local Oscillator Amp

- Remove the coaxial plug from J4002, and connect a 50- Ω resistor in parallel with the RF millivoltmeter across the socket.
- Adjust T4006 and T4007 in succession several times for peak RF millivoltmeter indication (at least 170 mV_{RMS}).
- Remove the meter and resistor, and replace the plug in J4002.

WIDTH DDS Amp

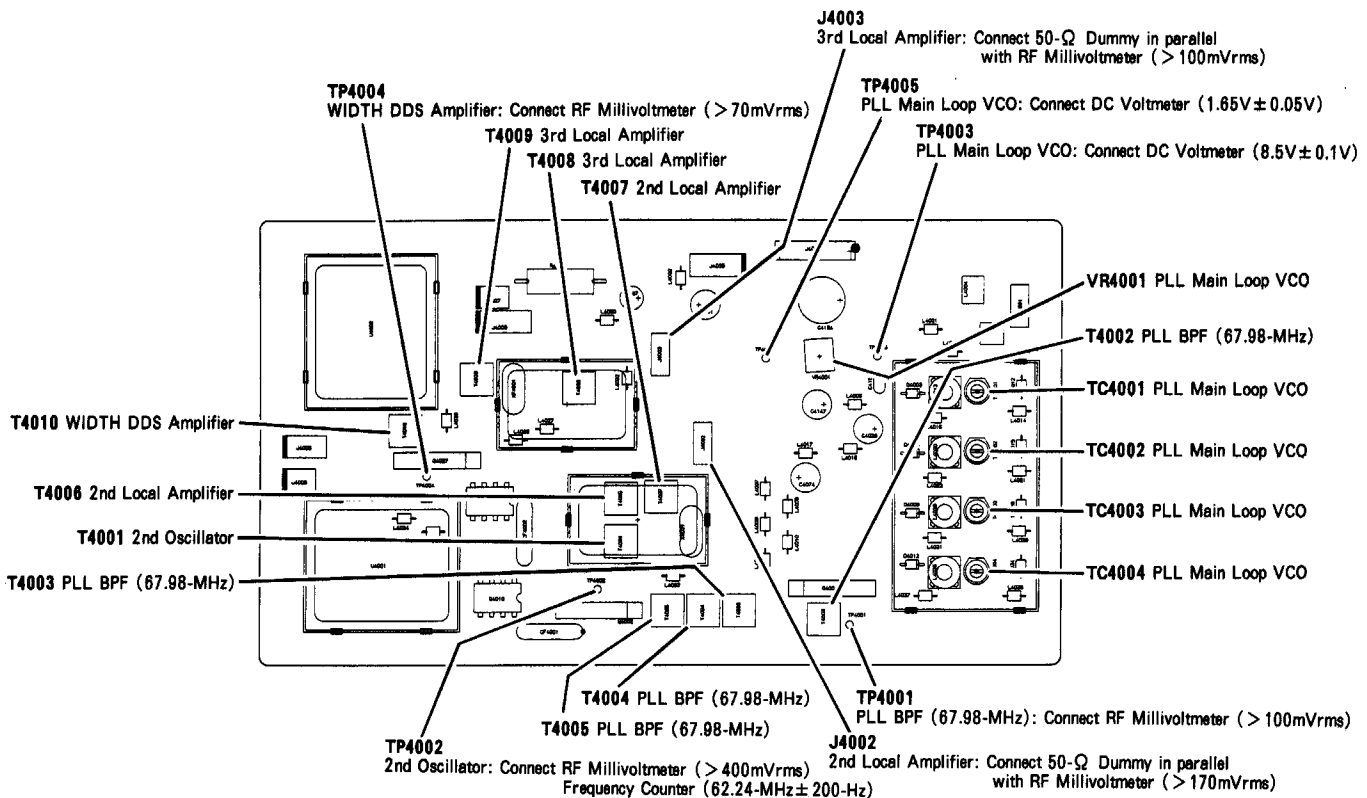
- Connect the RF millivoltmeter to the TP4004, and adjust T4010 for maximum indication on the RF millivoltmeter (at least 70 mV_{RMS}).

3rd Local Amp

- Remove the coaxial plug from J4003 and connect a 50- Ω resistor in parallel with the RF millivoltmeter across the socket.
- Adjust T4008 and T4009 in succession several times for peak RF millivoltmeter indication (at least 100 mV_{RMS}).
- Replace the RF millivoltmeter with a frequency counter, and confirm at 8.670 MHz (± 30 Hz).
- Remove the frequency counter and resistor, and replace the plug in J4003.

PLL BPF (67.98 MHz)

- Connect the RF millivoltmeter to TP4001, and adjust T4002~T4005 in succession several times for peak RF millivoltmeter indication (at least 100 mV_{RMS}).



LOCAL UNIT Test & Alignment Points

PLL Main Loop VCO

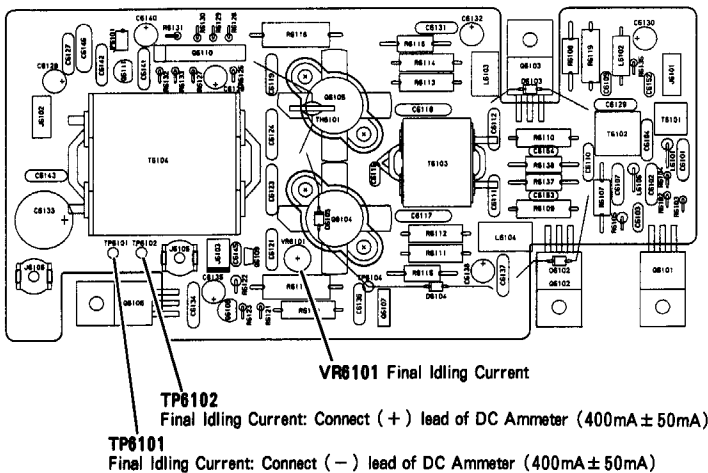
- Preset VR4001 to the 12-o'clock position, and connect the DC voltmeter to the TP4003.
- Referring to table below, tune the transceiver to each frequency, then confirm or adjust the listed component for the required voltage.

PLL Main Loop VCO Alignment		
Tune to:	Adjust/Confirm	for
7.499 MHz	adjust TC4001	$8.5 \pm 0.1V$
4.000 MHz	confirm	$2.4 \pm 1.1V$
3.999 MHz	confirm	$7.5 \pm 0.1V$
0.100 MHz	confirm	$2.0 \pm 0.5V$
14.499 MHz	adjust TC4002	$8.5 \pm 0.1V$
7.500 MHz	confirm	$1.8 \pm 0.5V$
21.999 MHz	adjust TC 4003	$8.5 \pm 0.1V$
14.500 MHz	confirm	$1.8 \pm 0.5V$
30.000 MHz	TC4004	$8.5 \pm 0.1V$
22.000 MHz	confirm	$1.8 \pm 0.5V$

- Tune the transceiver display to 14.200 MHz. Connect the DC voltmeter to the TP4005, and adjust VR4001 for $1.65V (\pm 0.05V)$ on the DC voltmeter.

PA Unit

Refer to the photograph below for PA Unit component locations and alignment points.



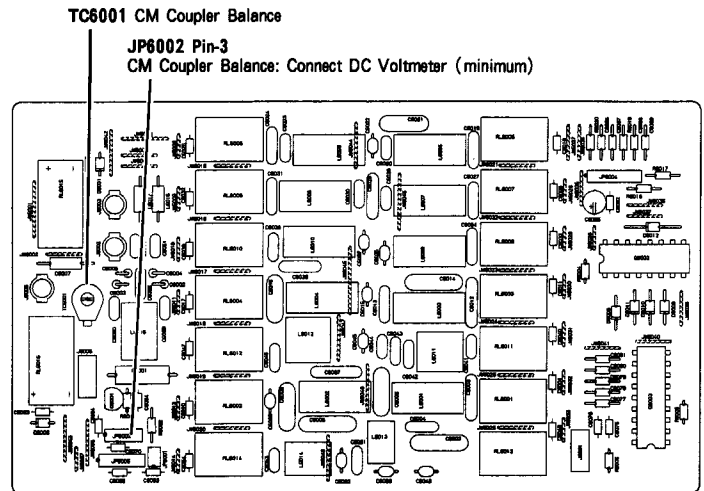
PA Unit Test & Alignment Points

Final Idling Current

- Temporarily disconnect the jumper between TP6101 and TP6102, and connect an ammeter in its place.
- Key the transmitter in either USB or LSB, then, with no microphone input, adjust VR6101 for 400 mA ($\pm 50 mA$). Reinstall the jumper.

LPF Unit

Refer to the photograph below for LPF Unit component locations and alignment points.



LPF Unit Test & Alignment Points

CM coupler balance

- Connect the DC voltmeter to pin 3 of JP6002, connect a 50-Ω dummy load to the antenna jack, and select CW mode.
- Key the transmitter and adjust TC6001 for minimum indication on the DC voltmeter.

Alignment

Tuner Unit

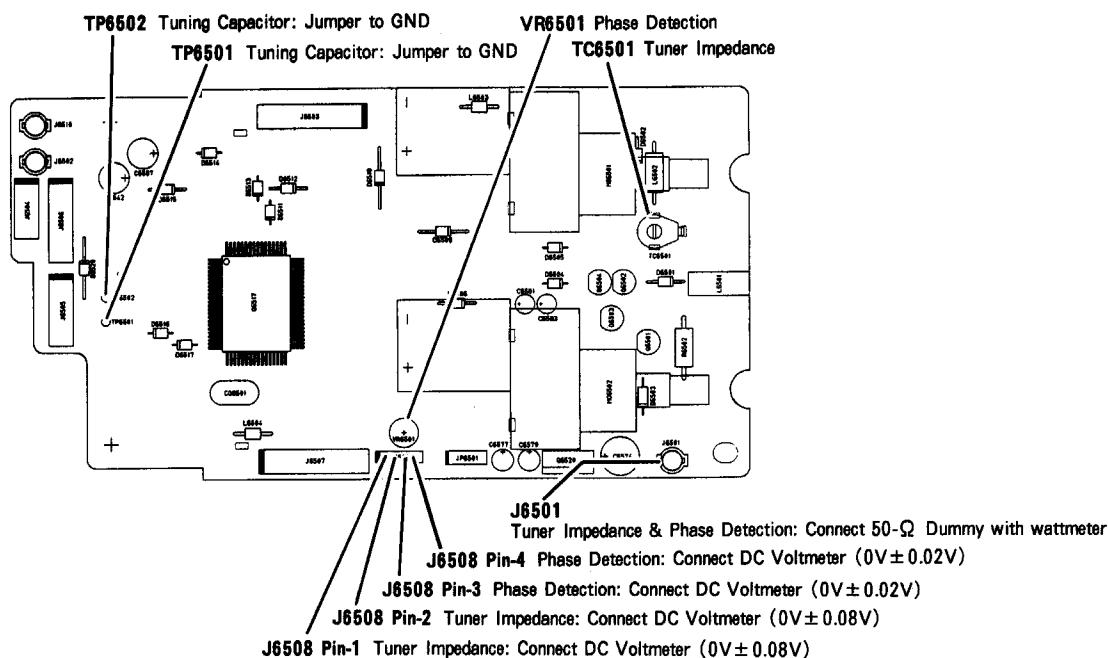
Refer to the photograph at the page bottom for TUNER Unit component locations and alignment points.

Tuning Capacitor/Motor (Mechanical check, setting & adjustment)

- Loosen all set screws in the shaft coupler, and turn the coupler by hand to confirm it moves freely (the motor and capacitor should not move).
- If the coupler binds, check the motor mounting position (it is soldered in place) and the capacitor mounting (screw).
- Turn the power switch off, and jumper TP6501 to chassis ground. Turn the power switch on. The motor should rotate, and then stop.
- Set the capacitor to its maximum capacitance position (plates fully meshed) by hand, and tighten all shaft coupler set screws, using care not to disturb the capacitor or motor positions.
- Turn the power off, and jumper TP6502 to chassis ground (along with TP6501). Turn the power back on. The motor should move 180°, and the capacitor should be then at minimum capacitance (fully unmeshed). Remove the grounding jumpers from TP6501 and TP6502.

Tuner impedance & Phase detection

- Connect the 50-Ω dummy load and wattmeter to J6501 (the output of the Tuner-Control Unit), and connect J6502 (RF IN) to J5002 (LPF OUT). Select CW mode.
- Connect the DC voltmeter between pin-1 ("I") and 2 ("V") of J6508 (either polarity).
- Press the **TUNER** and **MOX** buttons, adjust the **RF PWR** control for 50 watts output, and then adjust TC6501, if necessary, for meter indication within $\pm 0.08V$ of 0V.
- While still transmitting, move the DC voltmeter to pin-3 ("C") and 4 ("L") of J6508 (either polarity), and adjust VR6501, if necessary, for meter indication within $\pm 0.02V$ of 0V.



Tuner Unit Test & Alignment Points

IF Unit

Refer to the photograph at the page bottom for IF Unit component locations and alignment points.

2nd & 3rd Local Amp

- Connect the RF millivoltmeter to TP2003, and adjust T2010 for maximum indication on the RF millivoltmeter (at least 500 mVRMS).
- Next, connect the RF millivoltmeter to TP2005, and confirm at least 100 mVRMS.

Rx IF Interstage Transformer (I) (coarse alignment)

- Connect the RF signal generator to J2003, and inject +100 dBu at 70.455 MHz. Connect the AC voltmeter across and 8-Ω dummy load to the **EXT SP** jack on the rear panel.
- Preset VR2004 12-o'clock position, and adjust T2003~T2009, T2011 and T2012 in succession several times for peak on the AC voltmeter.

RF Interstage Transformers Coarse alignment

- Preset VR1002 and VR1003 to their 12-o'clock positions, and select either USB or LSB mode. Adjust T1015~T1019 on the IF Unit in succession several times for peak noise from the speaker.

S-Meter Coarse Alignment

- Preset VR2003 fully counter-clockwise, and adjust VR2003 so that all S-meter segments are just off. Preset the **RF GAIN** control fully counter-clockwise, and adjust VR2002 so that all S-meter segments are just on.

1st Mixer Balance

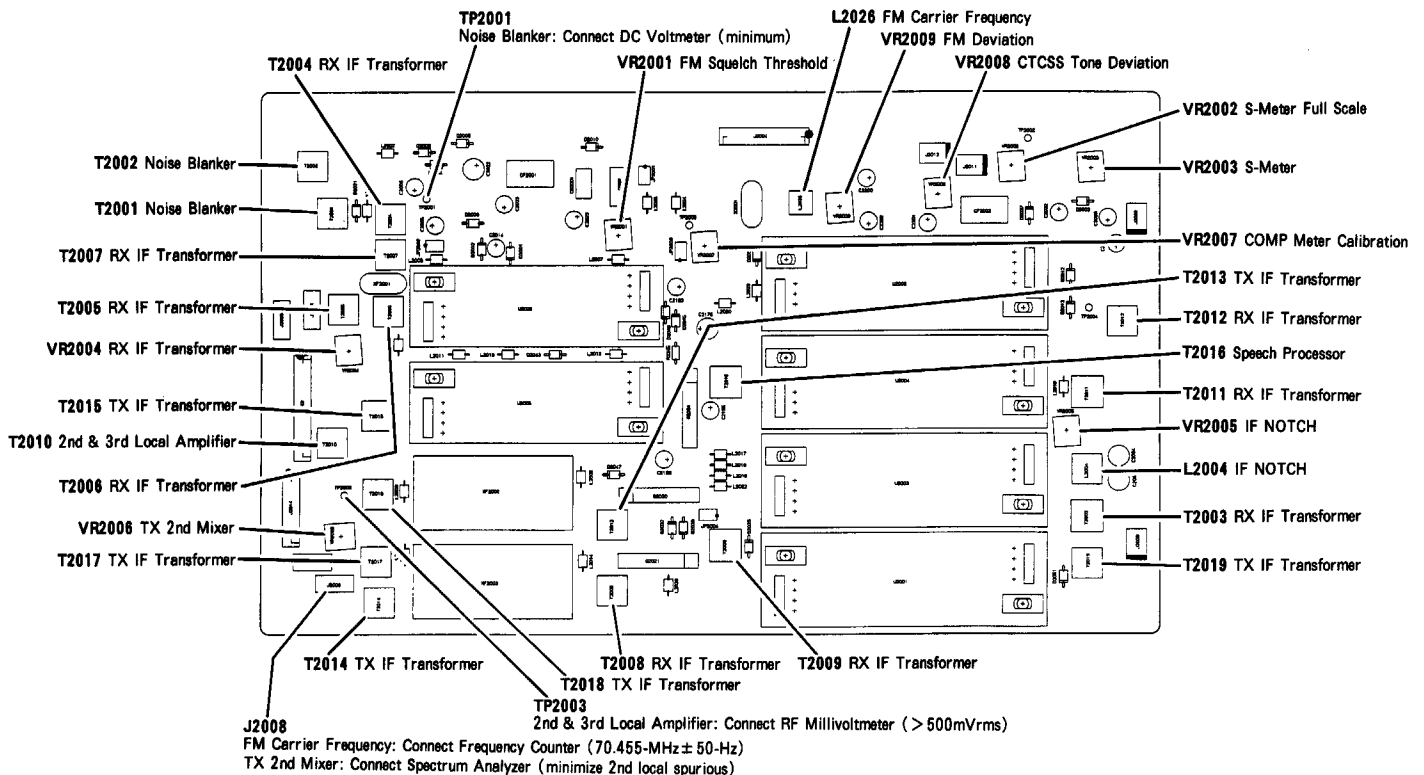
- Preset VR1002 for 12-o'clock position.

IF Interstage Transformers (II)

- Connect the RF signal generator to the antenna jack, and inject a +80 dBu signal. Adjust T1015~T1019, T2003~T2009, T2011 and T2012 in succession several times for peak S-meter indication (adjust the injection level as necessary to keep the meter around mid scale).

RF Amp

- Confirm that menu function 8-4 is set to "tuned" then connect the RF signal generator to the antenna jack, and inject a +20 dBu signal.
- Referring to the table at the top of the next page, tune the transceiver and RF signal generator to the listed frequencies, and adjust the corresponding components for the levels shown.



IF Unit: Test & Alignment Points

Alignment

RF Amp Alignment		
Tune SG & Radio to:	Adjust/Confirm	for
1.910 MHz	adjust T1001	Max S-meter
3.7250 MHz	adjust T1002	Max S-meter
7.110 MHz	adjust T1004	Max S-meter
28.200 MHz	adjust T1012	Max S-meter

IF Gain

- Turn the transceiver off, then press and hold the **FAST** and **LOCK** buttons (near main VFO knob), and turn the transceiver on again.
- Connect the RF signal generator to the antenna jack, and inject +8 dB μ . Select menu function 9-1, and adjust the main VFO knob for a 1-segment S-meter deflection.

S-meter full scale

- Connect the RF signal generator to the antenna jack, and inject a +100 dB μ signal. Tune for peak indication on the S-meter. Adjust VR2002 for S9+60 dB on the S-meter.

Noise Blanker

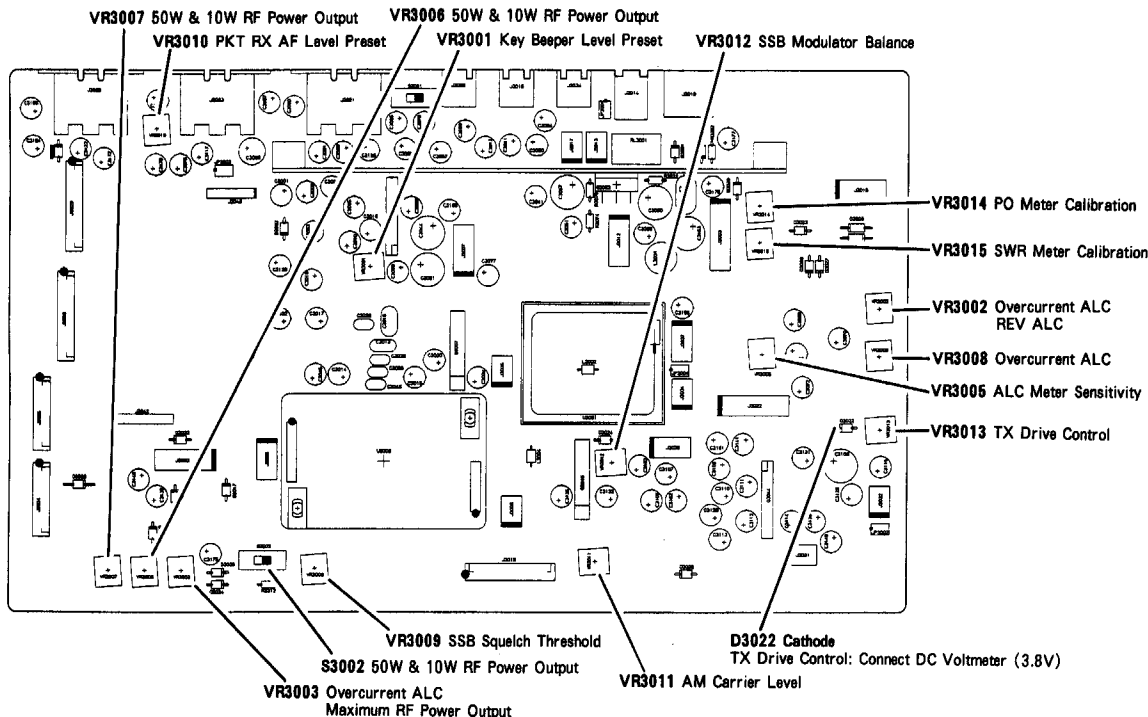
- Preset the **NB** control fully clockwise, press the **NB1** switch on, and connect the DC voltmeter to TP2001. Inject +40 dB μ , and adjust T2001 and T2002 in succession several times for minimum DC voltmeter indication.
- Reduce the RF signal level to +20 dB μ , and confirm at least 3.2 V on the DC voltmeter. Select **NB2**, and also confirm at least 3.2 V.

IF NOTCH

- Preset the **NOTCH** control for 12-o'clock, then inject a +40 dB μ signal at 14.2000 MHz to the antenna jack. Select USB, then tune the transceiver to 14.20150 MHz (so that a 1500 Hz tone is heard).
- Press the **NOTCH** button, then adjust VR2005 and L2004 for minimum S-meter indication.

FM squelch threshold

- With FM mode selected, and no signal present, set the **SQL** control to the 11-o'clock position, then adjust VR2001 so that the squelch just closes.



AF Unit: Receiver Alignment Points

SSB squelch threshold

- With USB selected, and no signal present, set the **SQL** control to the 10-o'clock position. Adjust VR3009 on the AF Unit so that the squelch just closes.

Tx 2nd mixer

- Select CW mode, and connect the spectrum analyzer to J2008. Key the transmitter, and adjust VR2006 to minimize the 2nd local spurious (± 8.2 MHz from the 2nd local frequency).

Transmitter IF interstage transformer

- Connect the 50- Ω dummy load to the antenna jack. Preset the **RF PWR** control fully clockwise, and **MIC** gain control fully counter-clockwise. Select CW mode.
- Key the transmitter, and adjust T2013~T2015, T2017~T2019, T2021, T2023 in succession several times for maximum indication on the ALC meter.

Overcurrent ALC

- With the inline wattmeter and 50- Ω dummy load connected to the antenna jack, preset VR3002, VR3003, VR3008 on the AF Unit and the **RF PWR** control fully clockwise.
- Tune the transceiver to 3.500 MHz, and select CW mode. Key the transmitter and adjust VR3008 for 140 watts on the meter.

Maximum RF power output

- Preset the **RF PWR** control fully clockwise, and tune the transceiver to 14.2000 MHz. Select CW mode, the key the transmitter and adjust VR3003 for 100 watts on the meter.

50W and 10W RF power output

- Move switch S3002 from "100W" to the "50W" position. Connect the in-line wattmeter and 50- Ω dummy load to the antenna jack, select CW mode and tune to 14.2000 MHz.
- Set the **RF PWR** control fully clockwise. Key the transmitter, and adjust VR3007 for 50W on the power meter. Recall menu function 4-0, and select "10W".
- Key the transmitter, and adjust VR3006 for 10W on the power meter. After adjustment, recall menu function 4-0, then select "100W". Move switch S3002 back to the "100W" position.

TX drive control

- Set the **RF PWR** control fully counter-clockwise, and select CW mode. Key the transmitter, and

adjust VR3013 for one segment displayed on the PO meter.

ALC meter sensitivity

- Set the meter function to ALC, then inject 4 mV at 1 kHz tone to the microphone jack. Key the transmitter, and adjust the **MIC** gain control so the meter just begins to deflect.
- Increase the injection level to 10 mV, and adjust VR3005 so that the meter deflects to the top edge of the ALC zone.

TX IF gain

- Turn the transceiver off. Next, press and hold **FAST** and **LOCK** (near MAIN VFO-A knob) button, then turn the transceiver on.
- For the frequencies listed in the table below, set the transceiver to LSB mode, and inject 0.5 mV at 1 kHz tone to the microphone jack. Set the **MIC** gain control fully clockwise.

TX IF Gain Alignment		
Note: For all adjustments below, set the transceiver to LSB, and inject a 0.5 mV, 1-kHz to the MIC jack. Set the MIC GAIN control fully clockwise.		
Tune to:	Menu Function 92	Key Tx and adjust MAIN VFO Dial for
1.800 MHz	T IF-018	Minimum ALC Indication
3.500 MHz	T IF-035	" "
7.000 MHz	T IF-070	" "
10.000 MHz	T IF-100	" "
14.000 MHz	T IF-140	" "
18.000 MHz	T IF-180	" "
21.000 MHz	T IF-210	" "
24.500 MHz	T IF-245	" "
28.000 MHz	T IF-280	" "
29.000 MHz	T IF-290	" "

PO meter calibration

- With the wattmeter and 50- Ω dummy load connected to the antenna jack, select CW mode and set the meter to read power output.
- Key the transmitter, and adjust the **RF PWR** control for 100 W on the wattmeter. Then adjust VR3014 so the PO meter also indicates 100 watts.

REV ALC

- Connect the 16.6- Ω dummy load (or three 50- Ω loads in parallel), preset the **RF PWR** control fully clockwise and select CW mode. Key the transmitter, and adjust VR3002 for 50 W on the PO meter.

Alignment

SWR Meter Calibration

- Connect the 16.6- Ω dummy load (or three 50- Ω loads in parallel) to the antenna jack, then preset the **RF PWR** control fully-clockwise. Select CW mode and set the meter to read SWR.
- Key the transmitter, and adjust VR3015 so the meter indicates 3.0:1 SWR (within 1 bargraph segment).

IC Meter Calibration

- With the wattmeter and 50- Ω dummy load connected to the antenna jack, select CW mode and set the meter to read IC. Preset the **RF PWR** control fully-clockwise.
- Key the transmitter, and confirm 15A (\pm 3A) IC meter indication (within 1 bargraph segment).

SSB Modulator Balance

- With the 50 dB attenuator and spectrum analyzer (or 50- Ω dummy load and sampling coupler) connected to the antenna jack, and the **MIC** gain control preset fully counterclockwise, select CW mode. Alternatively, a separate receiver can be used, with the transceiver connected to the dummy load.
- Key the transmitter, and adjust VR3012 for minimum power output (carrier leakage, should be less than -50 dB) as indicated on the spectrum analyzer or external receiver.

AM Carrier Level

- With the wattmeter and 50- Ω dummy load connected to the antenna jack, select AM mode, set the meter to read ALC. With no microphone input, preset the **RF PWR** control to the fully clockwise. Key the transmitter, and adjust VR3011 for ALC meter deflects to the top edge of the ALC zone.

Speech processor

- Preset the T2016 to top edge of the coil case.

COMP meter calibration

- Set the **PROC** and **RF PWR** controls fully clockwise, and press the **PROC** button to activate the speech processor.
- Set the meter to read **COMP**, and preset the **MIC** gain control to the 1-o'clock position. Inject 2 mV audio at 1 kHz tone to the mic jack, and adjust VR2007 so that the transceiver's meter deflects to the 10 dB mark on the COMP scale.

FM carrier frequency

- Connect the frequency counter to J2008, preset the FM mic gain control fully counter-clockwise, and select FM mode. Key the transmitter, and adjust L2026 for 70.455 MHz \pm 50 Hz on the frequency counter.

FM & CTCSS tone deviation

- With the 50 dB attenuator and liner detector (or 50- Ω dummy load and sampling coupler) connected to the antenna jack, select FM mode, and tune to 29.2000 MHz.
- Set the FM mic gain control fully clockwise, and inject 10 mV at 1 kHz tone to the mic jack. Key the transmitter, and adjust VR2009 for \pm 2.3 kHz \pm 0.1kHz on the linear detector.
- Select the 88.5 Hz (default) subaudible tone, and press the **RPT** button to activate CTCSS operation. Key the transmitter and with no microphone input, and adjust VR2008 for 0.5 kHz \pm 0.1kHz on the liner detector.

Transmitter carrier point

- Turn the transmitter off, press and hold **FAST** and **LOCK** button (near main VFO knob), then turn the transceiver on.
- Recall menu function 9-0 and select "t-LSbcAr" using the SUB VFO-B dial.
- Select LSB mode and then inject a 1 kHz tone to the mic jack. Adjust the injection level to the point where the ALC meter no longer deflects.
- Adjust to inject frequency (within 800~2000 Hz) for peak RF output. Then adjust injection level for 80 W RF output.
- Set the injection frequency to 350 Hz, and adjust the MAIN VFO-A knob for 20 W RF output. Select "t-uSbcAr" using the SUB VFO-B knob, and select USB mode.
- Inject a 1-kHz tone to the mic jack, and adjust the injection level to the point where the ALC meter no longer deflects.
- Adjust the injection frequency (from 800 ~2000 Hz) for peak RF output, then adjust the injection level for 80 W RF output.
- Set the injection frequency to 350 Hz, and adjust the MAIN VFO-A knob for 20 W RF output.

FM Mic Gain

- With the 50 dB attenuator and linear detector (or 50-Ω dummy load and sampling coupler) connected to the antenna jack, tune to 29.200 MHz, and select FM mode.
- Inject a 1.5 mV signal at 1 kHz to the mic jack. Key the transmitter, and adjust VR6807 for 1.75 kHz ± 0.1 kHz on the linear detector.

PKT Receiver AF Level Preset

- Preset VR3010 fully clockwise.

Key beeper level preset

- Preset VR3001 fully counter-clockwise.

Headphone Output Level Preset

- Preset VR6801, VR6802, VR6803 and VR6804 to their 12-o'clock positions.

Tuning Meter Center Preset

- Preset VR6809~VR6812 to their 12 o'clock positions. Select CW mode, and turn the **SPOT** function on.
- Connect the DC voltmeter to JW6803, and adjust the **PITCH** control for at least 4.0 V on the DC voltmeter.
- Connect the DC voltmeter to JW6804, and adjust VR6811 for 2.7 V ± 0.1 V on the DC voltmeter.
- Adjust VR6812 for a centered tuning meter indication.

Tuning Meter Preset (CW, RTTY and PKT mode)

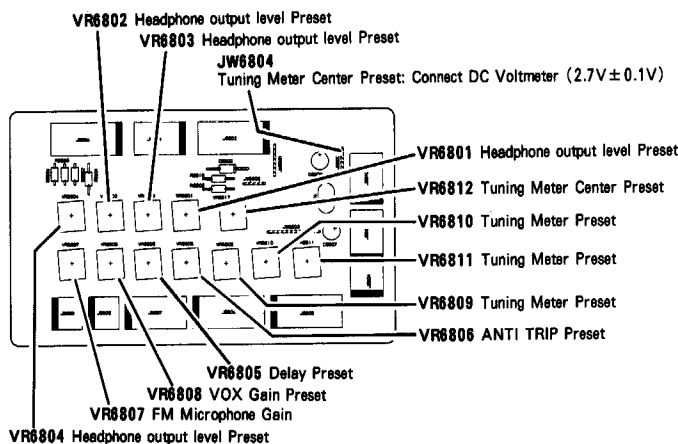
- Recall menu function 3-5 and select "A1-Pitch" using the MAIN VFO-A knob. Tune to 700 Hz using the **PITCH** knob ("C-700" displayed).
- Select CW mode, press the **SPOT** key, and adjust VR6811 for a centered tuning meter indication.
- Select menu function 4-2, select RTTY mode, and tune to 2210 Hz using the MAIN VFO-A knob.
- Select "bEEP-tun" using the SUB VFO-B knob, and adjust VR6810 for a centered tuning meter indication.
- Tune a 2125 Hz beep frequency using the MAIN VFO-A knob, and select **PKT** mode. Select "bEEP-tun" using the SUB VFO-B knob, and adjust VR6809 for a centered tuning meter indication.

VOX gain, ANTI TRIP and delay preset

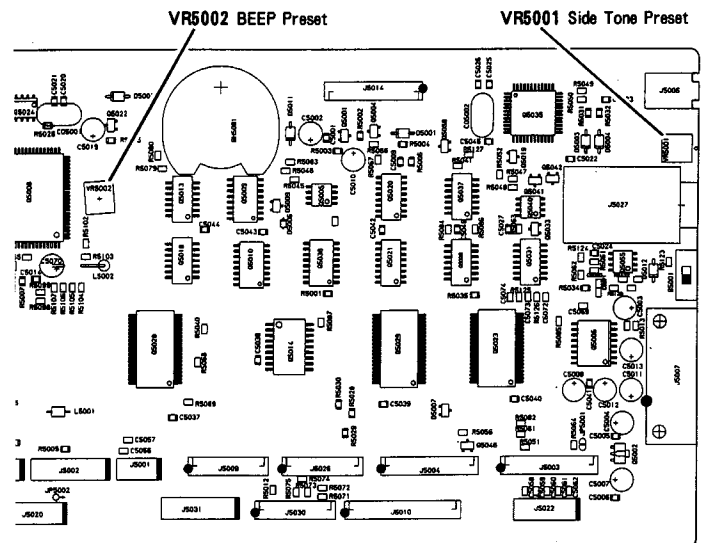
- Preset VR6805 (DLY), VR6806 (ANTI TRIP) and VR6808 (VOX gain) to their 12-o'clock positions.

BEEP and SIDETONE Preset

- Preset VR5001 (SIDETONE) and VR5002 (BEEP) to their 10-o'clock positions.



ALC Unit: Test & Alignment Points



CNTL Unit: Test & Alignment Points

Alignment

Notes:

Main Receive Signal Circuitry

High-Frequency Circuit

The receive signal, input from ANT connector A or B and selected by relays RL8701/RL8702 on the ANT Unit, passes through connector J8702, the HPF unit, and t/r relay RL6016 on the LPF Unit and is led to connector J1001 on the RF Unit from connector J6006.

The receive signal then passes through receive antenna switching relay RL1001 and an attenuator (-6 dB, -12 dB) which consists of resistors R1039, R1040, R1051, and R1064 and relays RL1002 and RL1003. It then enters a 5th-order Chebyshev low-pass filter (LPF) which consists of coils L1039 and L1040 and capacitors C1081, C1082, C1091, C1092, and C1093. After the signal is removed of frequency components of 30 MHz and over, it is led to a band-pass filter (BPF).

This BPF is a 5th-degree apolar Chebyshev type filter which divides the frequency range 100 kHz to 30 MHz into 11 bands. According to the receiving frequency, the appropriate band is selected by diodes D1003, D1004, D1007-D1010, D1015-D1019, D1025, D1026, D1029, D1030, D1035, D1036, D1039, D1040, D1044-D1049, D1053, D1054, D1056, and D1057. After the signal is removed of unwanted frequency components, it is applied to the high-frequency amplifier circuit.

The RF amplifier consists of low-band amplifier circuit FET Q1004, mid-band amplifier circuit FET Q1009, Q1011, Q1013, and Q1014, and high-band amplifier circuit Q1020. The appropriate amplifier circuit is selected* by D1005, D1006, D1013, D1014, D1023, D1032, D1037, D1041, and D1043. After amplification, the signal passes is applied to the 1st mixer circuit and sub-receive circuit (RX2 Unit).

***Note** - if *F1A2* is selected in Menu Program 8-4, RF signal input is input to the mid-band amplifier circuit.

Diodes D1001 and D1002, which are connected to the RF amplifier input and output, turn on (off) the amplifier circuit via the front-panel IPO switch.

1st Mixer Circuit/1st IF Circuit

The 1st mixer of the RF Unit consists of FET Q1027, Q1028, Q1030, and Q1031. The 1st local signal (70.555 ~ 100.455 MHz) from the LOCAL Unit is amplified by Q1021 and applied to each FET gate of the 1st mixer.

The resulting output signal (the difference between the local signal and receive signal) passes through dual monolithic crystal filter (MCF) XF1001/1002 (BW: ± 6 kHz) to obtain the 1st IF signal having a center frequency of 70.455 MHz. The signal is fed to the 2nd mixer circuit of the IF Unit after it is amplified by FET Q1029.

2nd Mixer Circuit/2nd IF Circuit

The 2nd mixer consists of FET Q2020 and Q2024 of the IF Unit. The 2nd local signal (62.24 MHz) from the LOCAL Unit is amplified by Q2027 and applied to each FET gate of the 2nd mixer.

The output from the 2nd mixer passes through monolithic crystal filter (MCF) XF2001, where it is stripped of unwanted signal components to become the 2nd IF signal (8.215 MHz). A portion of the 2nd IF signal from the mixer output is fed to the FM IF circuit through a noise blanker circuit and buffer-amplifier FET Q2003.

The 2nd IF signal that has passed through the MCF enters the noise blanker gate (NB Gate) which consists of D2014. It is then routed through either a crystal filter (XF2002, XF2003, U2002, U2005) or an attenuator (R2174, R2175, R2183), according to receiving mode (CW, SSB, or AM), to the 3rd mixer circuit after it is buffer-amplified by FET Q2052.

Noise Blanker Circuit

The signal sampled from the 2nd IF circuit is amplified by FET Q2009 and Q2010 on the IF Unit and then undergoes detection by D2006. This output passes through R2017 and R2027, C2006, and Q2001 to become an average AGC voltage for controlling the degree of amplification of the above FETs. Noise pulses contained in the output from D2026 are detected by Q2009 and Q2013 and used to control the NB Gate.

Circuit Description

3rd Mixer Circuit/3rd IF Circuit (IF Notch Circuit)

The 3rd mixer uses double-balanced mixer IC Q2021 (DBM) on the IF Unit. The 3rd local signal (8.67 MHz) from the LOCAL Unit is input to the DBM IC local port after it is buffer-amplified by Q2028. The signal output from the 3rd mixer passes through a ceramic filter, crystal filter, or mechanical filter (U2001, U2003, U2004, U2006, CF2002), to become the 455-kHz 3rd IF signal.

The 3rd IF signal that is buffer-amplified by Q2025 passes through a notch frequency control circuit which consists of L2004, C2063, C2064, and D2020. Attenuation in the IF notch circuit is controlled by VR2005. The 3rd IF is then buffer-amplified by Q2023 and further amplified in two stages by FET Q2026 and Q2029.

The IF signal is then buffer-amplified by Q2004 and Q2017, respectively. The output of Q2004 is applied to the AF Unit through connector J2002, and the output from Q2017 is input to the AGC circuit.

AGC Circuit

The AGC circuit consists of D2012 and D2013, transistor Q2018, etc. on the IF Unit. Output from the AGC circuit is input to the RF AGC circuit that consists of FET and PIN diodes of the IF amplifier stages, by which the output is controlled.

FM IF Circuit/FM Demodulator Circuit

The 2nd IF signal that has passed through buffer-amplifier FET Q2003 on the IF Unit, and the 3rd local signal (8.67 MHz) that has been buffer-amplified by Q2028 are input to IC Q2015 for FM demodulation.

The FM demodulator IC contains a mixer, limiter amplifier, filter amplifier, squelch trigger, and demodulator. The IF input signal is mixed with the 3rd local signal, band-limited by ceramic filter CF2001 (BW: ± 4 kHz), amplified by the limiter amplifier, and demodulated into an audio signal by the demodulator. It then passes through a filter (R2028, C2021) and connector J2004 and input to the AF Unit. The signal then enters analog switch IC Q3001-3 through a de-emphasis circuit which consists of R3060 and C3052.

The squelch circuit selectively amplifies the noise component of the demodulator output by the filter amplifier inside the FM IC and the active band-pass filter consisting of an externally attached resistor

and capacitor. This circuit uses a signal detected by D2001.

SSB/CW Demodulator Circuit

The 3rd IF signal from the IF Unit is applied to the SSB demodulator (SSB DET) of Q3007 on the AF Unit, which produces audio by applying the carrier signal from the DDS-CAR Unit to Q3007 after buffer-amplifying it by Q3020. Similarly, the CW signal is demodulated by a carrier signal which is offset by the pitch frequency.

The demodulated SSB and CW signals are each stripped of high-frequency components by an active low-pass filter consisting of op-amp IC Q3008-2 and IC Q3008-1. Then, they enter analog switch IC Q3001-2 and IC Q3001-4.

AM Demodulator Circuit

The 3rd IF signal from the IF Unit is input to I-DET Unit U3003 on the AF Unit, from which it enters IC Q3703 for AM demodulation.

The IC for AM demodulation consists mainly of an envelope detector, VCO, phase shifter, synchronous detector, and DC/AC detector. From the IF signal that is input to the IC, the envelope detector output and synchronous detector output are picked up.

The output from the demodulator circuit passes through analog switch Q3701-1 and Q3701-2 for switching between the synchronous detector output and envelope detector output. It then enters analog switch IC Q3001-1 after removed of the high-frequency components by an active low-pass filter (op-amp IC Q3013-1) on the AF Unit.

Low-Frequency Amplifier Circuit

The demodulated signal that is selected by one of analog switches IC Q3001-1 to IC Q3001-4 on the AF Unit according to receiving mode passes through the squelch switch, audio muting FET Q3002, low-frequency amplifier transistor Q3006, electronic volume IC Q3005, op-amp IC Q3014-1 for buffer-amplification, and IC Q3022 for low-frequency power to drive the internal or external speaker with a maximum output of approximately 1.5 W. The signal that passes through electronic volume IC Q3005 is also output to the headphone terminal after it is amplified by headphone amplifier IC Q3015-1.

Transmit Signal Circuitry

Microphone Amplifier Circuit

The audio signal from microphone jack J9421 on the MIC Unit is passed through board-in connector JP9421 and DISPLAY Unit's connectors (J5528 and J5529), amplified by transistor Q3048 on the AF Unit, and input to electronic volume IC Q3044 which is controlled by the MIC knob on the panel.

The output (audio signal) from the electronic volume is amplified by Q3045 and input to modulator circuit IC Q3046 through the buffer-amplifier transistor (Q3043). During FM reception, the audio signal is input to connector J2011 inside the IF Unit after its volume is adjusted by VR6807 on the ALC Unit.

The audio signal that has passed through the pre-emphasis circuit consisting of C2201 and R2228 on the IF Unit is mixed with a tone signal from the CNTL Unit and amplified and limited by op-amp IC Q2049-2 of the IDC circuit. The audio then passes through the splatter filter (secondary active low-pass filter) formed by op-amplifier IC Q2049-1, R2229 and R2230, and C2119 and C2206 is then input to the frequency-modulator circuit inside the IF Unit through VR2008 and VR2009 for setting frequency deviation.

SSB Modulator Circuit

The carrier signal appropriate to the transmitting mode (LSB, USB) is applied from the CAR-DDS Unit to balanced modulator (BM) IC Q3046 of the AF Unit and modulated by microphone audio.

The balanced modulator outputs the upper and lower side bands and carrier signal. The carrier and audio signal are suppressed and the carrier balance is adjusted by VR3012. As a result, the output signal obtained is a DSB signal with a carrier suppression ratio of 35 dB or more.

The side-band modulated signal (1st IF signal: 455 kHz) from the BM IC is input to mechanical filter XF9801 inside the SSB-FIL Unit on the IF Unit through buffer-amplifier Q3049, connector J3026, and IF Unit's connector J2009.

The DSB signal picks up the required side-band modulated signal by mechanical filter XF9801 inside the SSB-FIL Unit and applies it as an SSB signal to the transmission frequency mixer at the next stage.

AM Modulator Circuit

As in the SSB modulator circuit, a carrier signal appropriate to the transmitting mode (AM) from the CAR-DDS Unit and an audio signal from the microphone are input to balanced modulator (BM) IC Q3046 of the AF Unit.

The control signal from CPU IC Q5008 in the CNTL Unit causes a voltage of AM 9 V to be output from transistor array IC Q5025. This voltage is applied via VR3011 and D3018 to IC Q3046, causing the balanced modulator to lose balance. The carrier signal and modulated signal are then input to the Tx mixer via ceramic filter CF2002 inside the IF Unit.

Frequency Modulation Circuit

The FM circuit uses a voltage controlled crystal oscillator (VCXO) consisting mainly of IF Unit oscillator Q2044, X2001, varactor D2049, and L2026. The VCXO has a center frequency of 8.215 MHz.

The FM signal is produced by applying a signal from the FM microphone amplifier circuit to varactor D2049 and varying the crystal oscillator load capacity in proportion to the signal voltage. The FM signal is input to gate 1 of 2nd IF circuit FET Q2036 via Q2043 for buffer amplification and D2034.

CW (A1) Signal Generator Circuit

When the transmitting mode is CW (A1), the control signal from CPU IC Q5008 in the CNTL Unit causes a CW 9 V voltage to be output from transistor array IC Q5025. While microphone audio is cut off by Q3050, the voltage is applied to balanced modulator IC Q3046 via D3018, providing a carrier from the balanced modulator for input to the transmit signal circuit of the IF Unit.

1st IF Circuit/1st Mixer Circuit

The 455 kHz 1st IF signal from the modulator circuit is band-limited by the IF Unit's ceramic or mechanical filter CF2002, U2001 (XF9801) according to the selected mode (CW, SSB, or AM). It is then buffer-amplified by FET Q2037 and input to 1st mixer circuit IC2030.

As the 1st mixer, the IF Unit's double balanced mixer IC Q2030 (DBM) is used. A local signal (8.67 MHz) from the LOCAL Unit which is buffer-amplified by transistor Q2028 and input to the local port

Circuit Description

of DBM IC is mixed with the 455 kHz 1st IF signal to produce a 8.215 MHz 2nd IF signal.

2nd IF Circuit/2nd Mixer Circuit

The 2nd IF signal passes through either the IF Unit's crystal filter (XF2002, XF2003, U2002, U2005) or attenuator (R2174, R2175, R2183), whichever is appropriate to the selected mode (CW, BBS, or AM). It is then amplified by FET Q2036 and input to the 2nd mixer circuit.

The 2nd mixer consists of the IF Unit's FET Q2033 and Q2038. A 2nd local signal (62.24 MHz) from the LOCAL Unit is amplified by Q2027 and input to each FET gate. The signal that is output from the 2nd mixer is removed of unwanted signal components as it passes through a filter formed by T2014/T2017 and C2227 to obtain a 70.455 MHz 3rd IF signal.

3rd IF Circuit/3rd Mixer Circuit

The 3rd IF signal passes through T1023, is amplified by FET Q1034, then input to the 3rd mixer circuit via T1021. There it mixes with a local signal (72.255 ~100.455 MHz) generated by the LOCAL Unit to produce a transmit signal (1.8 MHz to 30 MHz) is generated.

High-Frequency Amplifier Circuit (Transmit Preamp. Circuit)

The transmit signal is passed through a low-pass filter which consisting of L1086/L1087 and C1208/C1209/C1212/C1213/C1214, wide-band amplified by Q1024, and input to the PA Unit via Q1022/Q1023 for buffer amplification and exits via connector J1007.

Power Amplifier Circuit

A transmit signal from the RF Unit is input to connector J6101 of the 100W-PA Unit .

The transmit signal (1.8 MHz to 30 MHz) input to the 100W-PA Unit is amplified by Q6101-Q6105 (pre-driver, driver, and final) and output from connector J6102 to the LPF Unit.

Low-Pass Filter Circuit

The transmit signal from the power amplifier circuit is input to connector J6001 of the LPF Unit and passed through an LPF consisting mainly of RL6001-RL6014, L6001-L6014, and various capacitors. The LPF is a 5th-degree simultaneous Chebyshev type

filter which divides the transmission frequency range (1.8 MHz to 30 MHz) into seven bands.

The low-pass filtered transmit signal is input to the ANT Unit through CM coupler L6015, tuner switching relay RL6015, ANT relay RL6016, and connector J6005.

The CM coupler, which consists mainly of L6015, TC6001, and C6056, samples a part of the transmission power to detect traveling-wave power and reflected-wave power. A detected voltage is produced by D6002-D6005, and is used for automatic level control (ALC).

ALC Circuit

The output from the CM coupler is, as the detected traveling-wave (FWD) and reflected-wave (REV) voltage, routed from connector JP6002 through connectors J6810/J6811 in the ALC Unit and applied to the ALC circuit via connector J3018 in the AF Unit.

The ALC circuit consists of an op-amplifier circuit for amplifying traveling-wave and reflected-wave voltage, time-constant ALC amplifier, and transmit signal control circuit in the IF Unit.

The traveling-wave voltage (FWD) from connector J3018 in the AF Unit is added with a DC control voltage which passes through the output power control, VR3003 (for setting transmission output, etc., on the panel), and is then applied to op-amplifier IC Q3026-1.

The detected reflected-wave voltage (REV) is added with a DC control voltage which passes through VR3088, and is then applied to op-amplifier IC Q3026-2. In high SWR conditions (SWR 1:3 or more), transmitter output is reduced and warning appears, thus, the PA Unit is protected.

The op-amp output passes through D3009 where the forward and reflected output from the op-amplifier are mixed and input to the ALC amplifier, which contains a time-constant circuit.

The ALC amplifier sufficiently amplifies the forward and reflected-wave output via transistor Q3025. This output then passes through a fast-attack, slow-delay RC time-constant circuit consisting of R3083/R3087 and C3069/C3157 for input to the Tx signal control circuit via connector J3015 and J2004 on the IF Unit.

The TX control circuit adjust the IF amplifier gain via gate 2 of FET Q2036 of the 8.215 MHz IF amplifier circuit to prevent the Tx output from exceeding the preset level.

Keying Circuit

When electronic keyer is used in CW mode, the bias of Q1024 and 2nd/3rd mixer FET Q2033/Q2038/Q1034 is controlled via NAND gate IC Q1026 and Q1019 to generate CW.

To limit modulation, keyer input is optimized by time-constant circuits, such as D1042, R1077, and C1129 of the bias control circuit, to limit bandwidth.

PLL Frequency Synthesizer (Main)

The PLL Frequency Synthesizer consists mainly of a master reference oscillator circuit, 2nd local oscillator circuit, 3rd local oscillator circuit, DDS-PLL/DDS-SUB/DDS-CAR units which digitally synthesize carrier outputs, and a PLL circuit which contains a voltage controlled oscillator (VCO).

Master Reference Oscillator Circuit

The master reference oscillator uses a Colpitts circuit (oscillation frequency: 10.48576 MHz) composed of Q4701, X4701, TC4701, and C4709/C4711. The reference oscillator signal passes through a low-pass filter composed of buffer amplifier Q4702, C4712/C4713, and L4701. It is then input to the LOCAL Unit via J4702, and also to the RX2, AF, and DSP-D Unit as the reference oscillation frequency.

DDS-CAR Unit/DDS-PLL Unit/DDS-SUB Unit

DDS IC Q3601/Q4502/Q4603 of the DDS (Direct Digital Synthesizer) Units each contain a shift register, selector, phase accumulator, and ROM.

The reference oscillation frequency (10.48576 MHz) that is input to each of the DDS Units is applied to DDS IC after amplified by transistors Q3603/Q4503/Q4601.

DDS outputs contain digital amplitude data corresponding to serial frequency data from CPU IC Q5008 of the CNTL Unit. The digital amplitude data is D/A-converted by ladder resistors RB3601/RB4501/RB4601 and passes through buffer amplifier Q3602/Q4501/Q4602 and Chebychev LPF to generate a sine wave. The DDS frequency range is 453.5 ~ 466.74 kHz (cf = 455.0 kHz) for CAR-DDS,

373.08 ~ 291.16 kHz for DDS-PLL, and 907.88 kHz \pm 620 Hz for DDS-SUB.

3rd Local Oscillator Circuit

The 3rd L.O. circuit generates a 1.81576 MHz signal by doubling the 907.88 kHz output from the SUB-DDS Unit on the LOCAL Unit by a filter composed of Q4039, T4010, C4153/C4164/C4170, and L4038. The doubled signal is input to mixer Q4027.

At the mixer, the 1.8-1576 MHz input signal is mixed with the 10.48576 MHz reference oscillation signal. The mixer output is stripped of unwanted frequency components by T4009 and monolithic filter XF4001 to generate the 8.67 MHz 3rd L.O. signal.

This signal is amplified by Q4029 and T4008 and passes through buffer amplifier Q4017 and a LPF composed of C4098/C4099/C4172 and L4022 for input to the IF Unit via connector J4003.

2nd Local Oscillator Circuit

The 2nd L.O. circuit is a Hartley-type overtone oscillator circuit (frequency: 62.24 MHz) composed of FET Q4003 T4001, and X4001 in the LOCAL Unit. It then passes through amplifier Q4012, T4006/T4007, and C4043, for input to the IF Unit via connector J4002.

1st Local Oscillator Circuit

VCO output is buffer-amplified by Q4004/Q4005 and passes through a LPF composed of L4003/L4004 and C4028, C4029, C4033-C4035. It is then input to the Tx/Rx frequency mixer circuit of the RF Unit via connector J4001.

PLL Circuit

The PLL circuit is a frequency mixing type composed of a VCO, mixer, PLL IC, and loop filter.

The VCO consists of four circuits—VCO1, VCO2, VCO3, and VCO4, with a frequency range of 70.555 ~ 100.455 MHz divided into four bands, allocated to the four VCO circuits. The range of VCO1 is further divided by a circuit which shifts the oscillation frequency. VCO1-VCO4 consist mainly of FET Q 4 0 0 9 / Q 4 0 1 6 / Q 4 0 2 3 / Q 4 0 3 2 , D4001/4002/4004/4005/4007/4008/4010/4011, TC4001-TC4004, and L4013/4020/4029/4035.

The VCO switching signal from connector J4004 is used to drive switching transistors

Circuit Description

Q4013/4021/4026/4037 to switch the source terminal of the oscillator FET.

VCO1 uses the VCO0 control signal to drive switching transistors Q4039/Q4040, apply a forward bias to D4013, and switch C4173 into the oscillator circuit, producing a frequency shift.

The 70.555~100.455 MHz VCO signal is input to mixer Q4001 via buffer amplifier FET Q4007 and buffer amplifier Q4006.

The 3rd local signal (8.67 MHz) that has been buffer-amplified by Q4022 and passed through the LPF composed of C4112/4113/4118-4120 and L4026/4027, the reference oscillator signal (10.48576 MHz) from the REF Unit that has been amplified by transistor Q4025, divided into 2.62144 MHz by 1/4-frequency divider Q4020, and passed through a low-pass filter composed of C4105/4106/4108-4110 and L4024/4025 are input to mixer Q4019 to obtain a 6.04856 MHz signal.

This 6.04856 MHz signal is stripped of unwanted signal components by ceramic filter CF4002 and input to mixer Q4010, together with the 291.16-373.08 kHz output frequency of the DDS-PLL Unit, to obtain a 5.67548~5.75740 MHz signal. This signal passes through CF4001 to mixer Q4002, together with the 62.24 MHz 2nd L.O. output that has been buffer-amplified by Q4011, to obtain a 67.91548~67.99740 MHz signal.

This signal passes through a BPF composed of T4003-T4005 and C4011/4012, buffer-amplified by Q4008, and input to mixer Q4001 via transformer T4002.

The mixer output from Q4001 (2.62144~32.52224 MHz) passes through a 9th-degree simultaneous Chebychev LPF composed of L4007-L4011 and C4048-C4052, C4061-C4066 is amplified by FET and Q4015/4018 and input to PLL IC Q4024.

At the same time, the 10.48576 MHz reference oscillator signal from the REF Unit is input to PLL IC Q4024 after it is amplified by Q4030 and passes through buffer amplifier Q4028 and a LPF composed of C4148/C4149 and L4033.

The phase is compared between the reference frequency and the frequency of the signal input to PLL IC, and a signal whose pulse corresponds to the phase difference is produced. The VCO frequency is

controlled by a loop filter which consists of an active filter composed of Q4033, Q4034/Q4038, R4089/R4091, and C4153 and a secondary lag filter composed of R4088 and C4059 / 4095 / 4128 / 4160 /4158.

Carrier Oscillation Signal Circuit

The 453.5~466.74 kHz (cf = 455.0 kHz) carrier output from the DDS-CAR Unit passes through buffer amplifier Q3020 and a LPF composed of L3002 and C3063/C3064. The signal path is switched by D3003/D3005 during Tx/Rx so that the signal is input to balanced modulator IC Q3046 and SSB detector Q3007.

RX2 Circuit

Receive Signal Flow

A portion of the receive signal from the RF Unit is input to J8002 of the RX2 Unit via J1003. It then passes through T8008 and input to 1st mixer Q8022/Q8027. The 47.31~77.21 MHz 1st L.O. signal output from the RX2 PLL circuit is input to the 1st mixer. The resulting 47.21 MHz 1st IF signal then passes through monolithic filter XF8001 (band width: ± 20 kHz), amplified by Q8024, and input to the 2nd mixer circuit.

The 46.755 MHz 2nd L.O. and the 1st IF signal are mixed in Q8023/Q8026 to generate a 455 kHz 2nd IF signal. This signal is then input to noise-blanker noise amplifier Q8008, noise gates (D8010/D8028), and FM signal buffer amplifier Q8001, respectively.

The 2nd IF signal, now removed of noise by the noise gates, is passed through either CF8002/CF8003 or U8001 to become the desired signal component. It is then amplified by FET Q8048 and Q8049 and input to the SSB demodulator circuit through a buffer amplifier.

The 2nd IF signal that has been input to the SSB demodulator circuit is input to IC Q8057, together with a carrier signal from the RX2 CAR-DDS Unit, and demodulated into an audio signal.

The demodulated audio signal is removed of wide-band frequency components as it passes through buffer amplifier transistor Q8017 and active LPF Q8013. It is then input to analog switch Q8006.

The signal that has passed through the buffer amplifier is passed on to the AM detector circuit and

AGC circuit. An AM signal detected by D8014 is input to analog switch Q8006.

The audio signal that has passed through analog switch Q8006 then passes through mute switch FET Q8002, and is amplified by Q8015, before input to the electronic volume of the AF Unit via connector J8001.

AGC Circuit Operation

The receive signal that has passed through buffer amplifier Q8029 is rectified by AGC detector D8017/8018 to control gate 2 of FET Q8024/Q8048 by transistor Q8021. This signal is also amplified by op-amplifier Q8005/Q8011 for S-meter and squelch control.

RX2 PLL Frequency Synthesizer

The 2nd L.O. circuit is a Hartley-type overtone oscillator circuit (frequency: 46.755 MHz) composed of FET Q8046 and crystal X8001 in the RX2 Unit and transformer T8018.

The oscillation signal from this circuit is input to the 2nd mixer via Q8044 and T8017/T8016. Like the main PLL circuit, the PLL circuit is a frequency mixing type composed mainly of a VCO, mixer, PLL IC, and loop filter.

The VCO consists of four circuits—VCO1 through VCO4. The 47.31~77.21 MHz oscillation frequency range is divided into four bands, which are allocated to the four VCO circuits.

VCO1 to VCO4 are composed of oscillator FET Q8034/8047/8051/8058, variable-capacity diodes D8021/8024/8027/8031, and oscillator coils L8007/8010/8020/8024. The VCO switching signal from connector J8003 drives switch transistors Q8040/8050/8056/8063 to switch the source line of each oscillator FET.

The oscillation signal (47.31 ~ 77.21 MHz) from VCO is input to mixer Q8043 through buffer amplifier FET Q8041 and buffer amplifier transistor Q8042.

The reference oscillator signal (10.48576 MHz) from the LOCAL Unit that has been amplified by Q8066/Q8060 and divided into 5.24288 MHz signals by Q8054 is input to mixer Q8055 through a LPF composed of C8152/8153/8164/8165/8166 and L8012/L8013.

At the same time, the 286.28~364.20 kHz output from the RX2 PLL-DDS Unit is input to mixer Q8055 to obtain a 5.52516~5.60708 MHz signal.

This signal passes through ceramic filter CF8004 and is input to mixer Q8038, together with the 46.755 MHz output of the 2nd L.O. that has been buffer-amplified by Q8045 to produce a 41.14792~41.22984 MHz signal. This is then passed through a BPF composed of T8013/T8014 and C8087, amplified by Q8037, and then input to mixer Q8043 via T8012.

The output of mixer Q8043 ranges from 6.1440 ~ 36.0488 MHz, and passes through a 9th-degree simultaneous Chebyshev LPF which is composed of L8015-L8019 and C8157-1861/C8168-8173. This is input to PLL IC Q8061 after it is amplified by FET Q8053 and transistor Q8052.

At the same time, the 10.48576 MHz reference oscillator signal from the LOCAL Unit is also input to PLL IC Q8061 via buffer amplifier Q8064 after amplification by Q8065.

The phase is compared between the reference frequency and the frequency of the signal input to the PLL IC, and a pulse corresponding to the phase difference is output to control the VCO frequency by a loop filter consisting of an active filter composed of FET Q8059, transistor Q8062, resistor, and capacitor and a secondary lag filter composed of a resistor and capacitor.

The controlled VCO output is amplified by Q8035/Q8036 and passed through a LPF composed of L8005/L8006 and C8098/C8099/C8104-8106. It is then input to the 1st mixer circuit through an attenuator.

DSP Circuit

The DSP circuit consists mainly of DSP (Digital Signal Processor) IC Q7101, AD/DA converter IC, and filter circuit. The functions performed by this circuit are SSB, AM demodulation, auto-notch, noise reducing, audio filtering, etc. in the receiving system and SSB generation/modulation and audio equalizing in the transmission system.

Analog-Digital Converter Circuit (Transmission System)

The audio signal from the microphone that has passed through electronic volume Q3044 in the AF Unit is input to the DSP-A Unit through connectors

Circuit Description

J3037/J7001. It then passes through a 5th-degree active HPF (cut-off frequency $f_c = 80$ Hz) composed of op-amplifier IC Q7004-1/Q7004-2, R7001-7004/R7007, and C7001/C7002/C7004-7006 to eliminate unwanted frequency components below the cut-off frequency.

The signal then passes through a inverting/non-inverting buffer amplifier circuit composed of op-amplifier IC Q7005-2 to Q7005-4 and input to A/D converter IC Q7001, where it is converted into a 16-bit digital signal. As 16-bit serial data, this signal is transmitted to DSP IC Q7101 in the DSP-D Unit via connector J7003.

Digital-Analog Converter Circuit (Transmission System)

The serial digital data input to the D/A converter IC Q7001 is converted into an analog signal and passed through a differential amplification type tertiary LPF (cut-off frequency $f_c = 18$ kHz) composed of op-amplifier IC Q7007-1/Q7007-2, R7037-R7043, and C7043-C7046 to suppress out-of-band, random noise, etc. The signal is then input to the AF Unit as an audio signal or SSB signal of 10.24 kHz suppressed carrier via connector J7001.

Digital Signal Processor Circuit (Transmission System)

In the transmission system, this circuit has a microphone equalizing function and digital modulator function. The A/D-converted signal data is subjected to tone quality processing and input to a digital modulator. When desired, it is possible to disable microphone equalizing and digital modulation. The serial audio data or SSB (LSB or USB) data processed by DSP IC is input to the D/A converter in the DSP-A Unit via connector J7103.

The signal from the DSP Unit is input to balanced modulator IC Q3046. When the DSP-enabled SSB modulation function is used, the balanced modulator IC operates as a double balanced mixer (frequency mixer). In this case, a carrier (local) signal ($f_{LSB} = 466.74$ kHz, $f_{USB} = 463.74$ kHz) generated by the DDS-CAR Unit and SSB signal of 10.24 kHz suppressed carrier apply a mixed output of 455 kHz differential frequency to ceramic filter CF2002 via connector J2009 in the IF Unit. Thus, this circuit performs the same operations as the analog circuit.

When only the equalizing function is used in A3 mode, the circuit operations after balanced modulator IC Q3046 are the same as those of the analog circuit.

Analog-Digital Converter Circuit (Receiving System)

The audio signal passing through balanced modulator IC Q3007 in the AF Unit or SSB signal of 10.24 kHz suppressed carrier is input to the DSP-A Unit via connectors J3037/J7001. It then passes through a inverting/non-inverting buffer amplifier circuit composed of op-amplifier IC Q7006-2 then to Q7006-4 and finally input to A/D converter IC Q7001, where it is converted into a 16-bit digital signal. As 16-bit serial data, this signal is input to DSP IC Q7101 in the DSP-D Unit via connector J7003.

Digital-Analog Converter Circuit (Receiving System)

The serial digital data that is input to D/A converter IC Q7001 is converted into analog data and passed through a differential amplification type tertiary LPF (cut-off frequency $f_c = 18$ kHz) composed of op-amplifier IC Q7008-1/Q7008-2, R7037-R7043, and C7043-C7046 to suppress out-of-band quantization noise, etc. It is then input to the AF Unit as an audio signal via connector J7001.

Digital Signal Processor Circuit (Receiving System)

During receive, this circuit performs audio processing and SSB/CW/AM demodulation. The A/D-converted signal data is subjected to digital demodulation and audio processing. When appropriate, it is possible to disable the digital demodulation and audio processing.

When the DSP demodulation function is used, balanced mixer IC Q3007 of the AF Unit operates as a double balanced mixer (frequency mixer). In this case, the 3rd IF signal (455 kHz) from the IF Unit is mixed with a carrier (local) signal of the frequency ($f_{LSB} = 466.74$ kHz, $f_{USB} = 463.74$ kHz) generated by the DDS-CAR Unit to produce a differential frequency of 10.24 kHz. The audio data processed by DSP IC is serially input to the D/A converter in the DSP-A Unit.

Control Circuitry

Microprocessor Circuit

The microprocessor circuit, which is composed of CPU IC Q5008 and EEPROM IC Q5024, performs various types of processing, such as the control of various control signals, serial I/O, A/D converter, dial counter circuit, key input, and display.

The EEPROM memorizes various parameters and settings (transmission frequency range, transmission output control) and carrier points according to transceiver version and the contents of memory channels.

Reset Circuit

The reset circuit consists mainly of CNTL Unit IC Q5005/5022/5039-5, capacitors, and resistors. This circuit controls the power-down input port, CPU reset input, keyer CPU, and related circuits.

Dial Counter Circuit

The dial counter circuit consists of two VFO dials, MEM dial, CLAR dial, and IC Q5026/Q5027. This circuit detects a two-phase pulse having a phase difference of 90 degrees and inputs it to CPU IC Q5008 as 8-bit parallel data.

Control Circuit

The control circuit consists of CNTL Unit IC Q5023/5025/5028-5039, etc. This circuit controls the switching of various switches, filters, transmit/receive mode, VCO, and bands and the input of signals.

Serial Data Communication Circuit

Data transfer to PLL IC, DDS-PLL, SUB, CAR, RX2-PLL, RX2-CAR Unit, indicators, keyer, DSP, etc. is performed by 3-wire system clock synchronous communication, whereas internal ANT tuner and CAT serial signals are transferred by 2-wire system asynchronous communications.

Various types of data, such as operating frequency, mode, and display, are processed by CPU IC Q5008 and transferred as serial signals to the appropriate devices by IC Q5013 / Q5018 / Q5020 / Q5021 / Q5037.

The CAT signal is converted to RS232 interface standard levels by IC Q5006 and output from connector J5007 of D-SUB pin 9.

Key Matrix Circuit

The key matrix circuit consists of DISPLAY Unit IC Q5506/Q5507, D5503-D5517, and panel key switches arranged on the matrix. When a key is pressed, this circuit reads the input data for processing by the CPU.

Analog-Digital Converter Circuit

Forward and reflected-wave voltage, ALC, power supply, S-meter, COMP meter, IF SHIFT/WIDTH VR, DSP switch, PITCH VR, shuttle jog, REMOTE terminal, etc. are selected by CNTL Unit IC Q5009/5010/5038 and input to the A/D port of CPU IC Q5008 for conversion into digital values to be processed.

The individual voltages converted into digital values are displayed as PO, SWR, ALC, IC, VCC, and S-meter indications on the LCD panel. Depending on the conditions of digitally-converted VRs, switches, etc., necessary control is effected.

LED Drive Circuit

The LED drive circuit consists of KEY Unit IC Q9501-Q9503 and LEDs. This circuit converts serial data from the CPU into parallel data and drives (turns on/off) the appropriate LEDs.

LCD Circuit

Data processed by the CPU IC is serially input to LCD driver IC Q5501-Q5504 of the DISPLAY Unit to drive LCD display DS5501. A cold cathode tube and exclusive DC-DC inverter unit are used for back lighting of the LCD. The inverter unit supply voltage is controlled by a dimmer circuit.

CTCSS Tone Generator Circuit

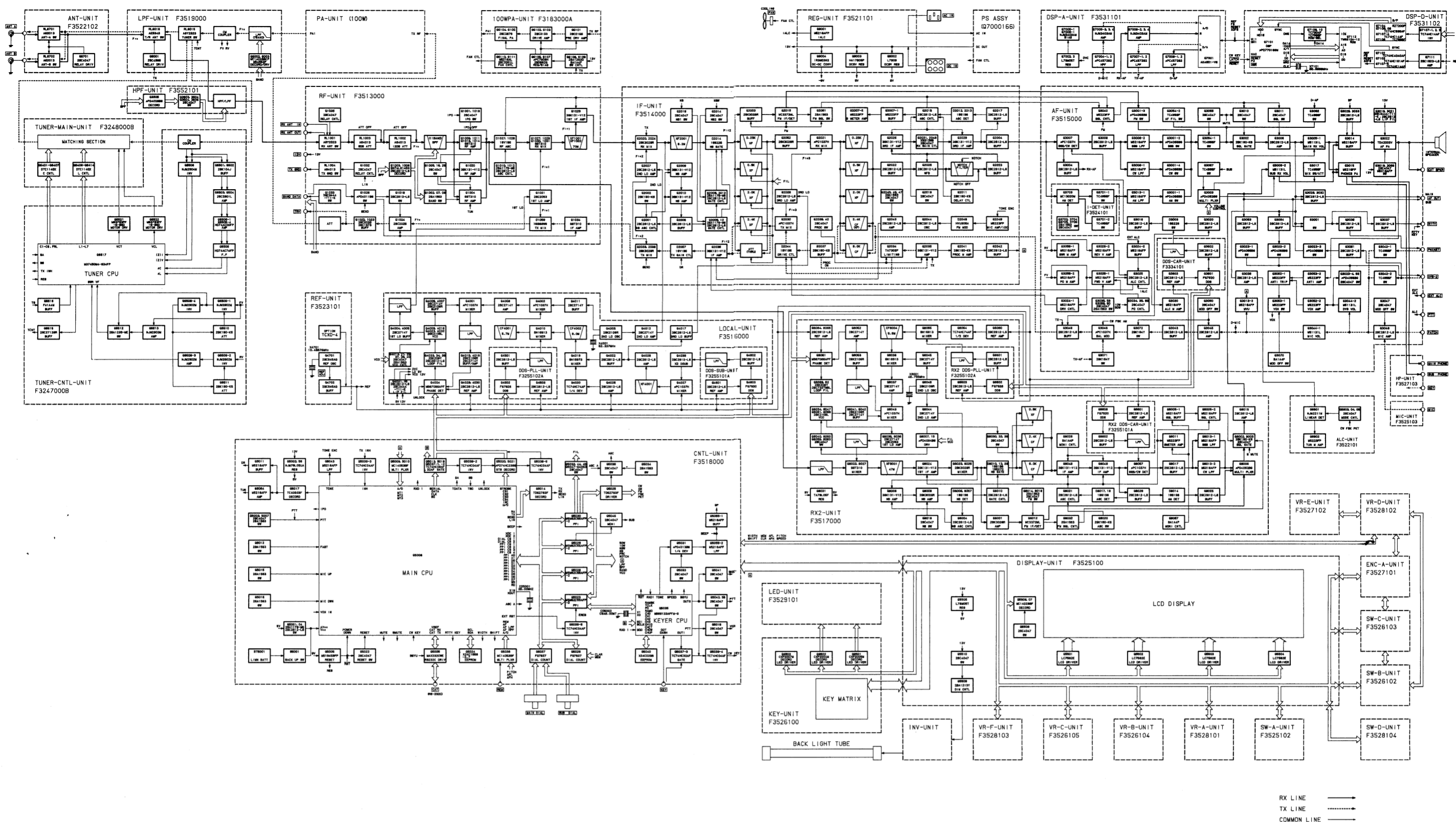
The CTCSS tone generator circuit consists mainly of CPU IC Q5008 and active filter IC Q5043-1. The tone generated by this circuit is input to the frequency modulator from connector J5011.

Electronic Keyer Circuit

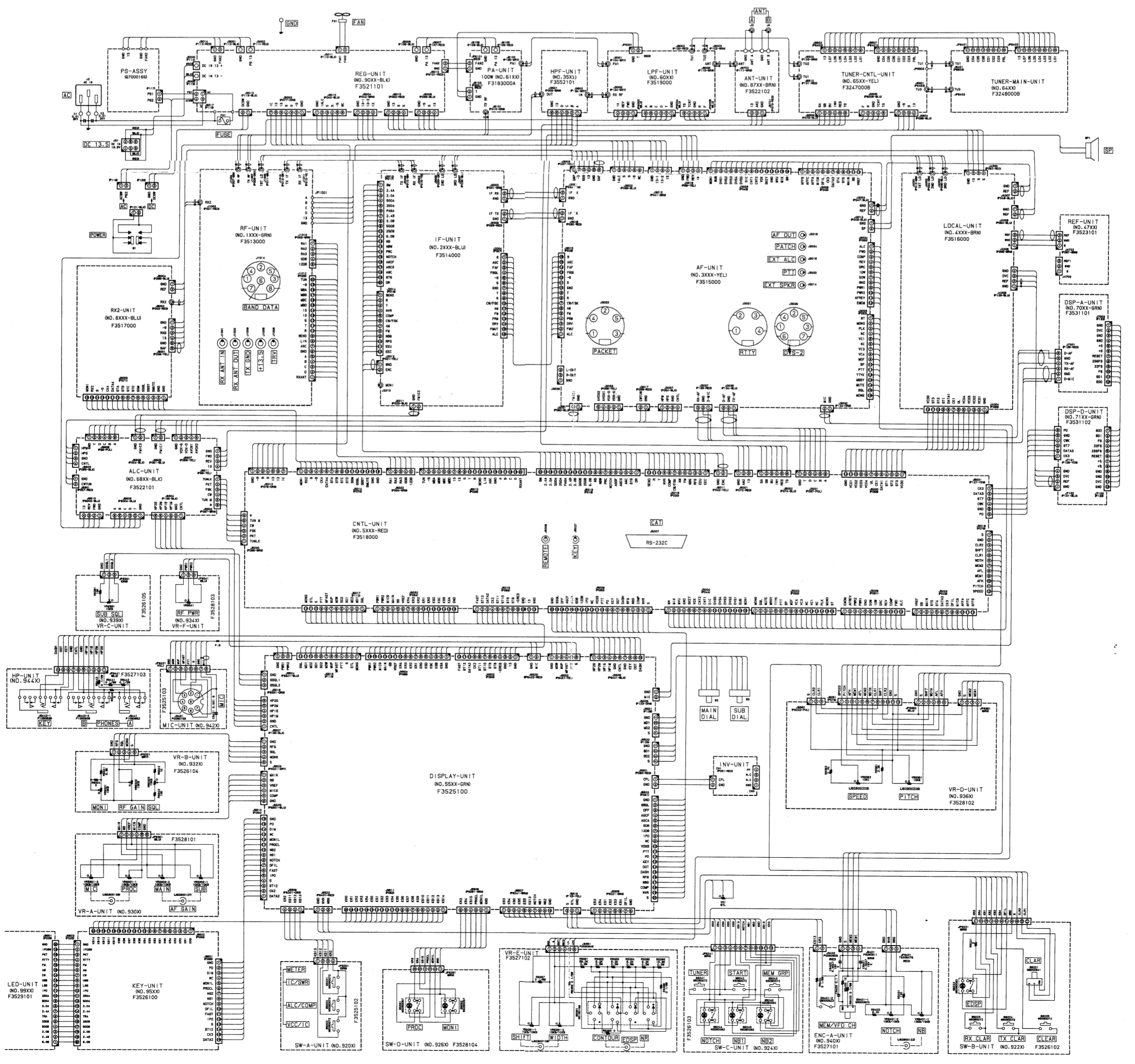
The electronic keyer circuit consists mainly of CNTL Unit IC Q5035/Q5031/Q5040 and speed control VR9362 (SPEED). When the CW mode is selected, this circuit controls the transmission operation. The key input from the keyer is connected to keyer IC from key jacks J9442-1/J5027, and its control signal is input to Q5019/Q5042/Q5041 for keying control in the CW mode.

Circuit Description

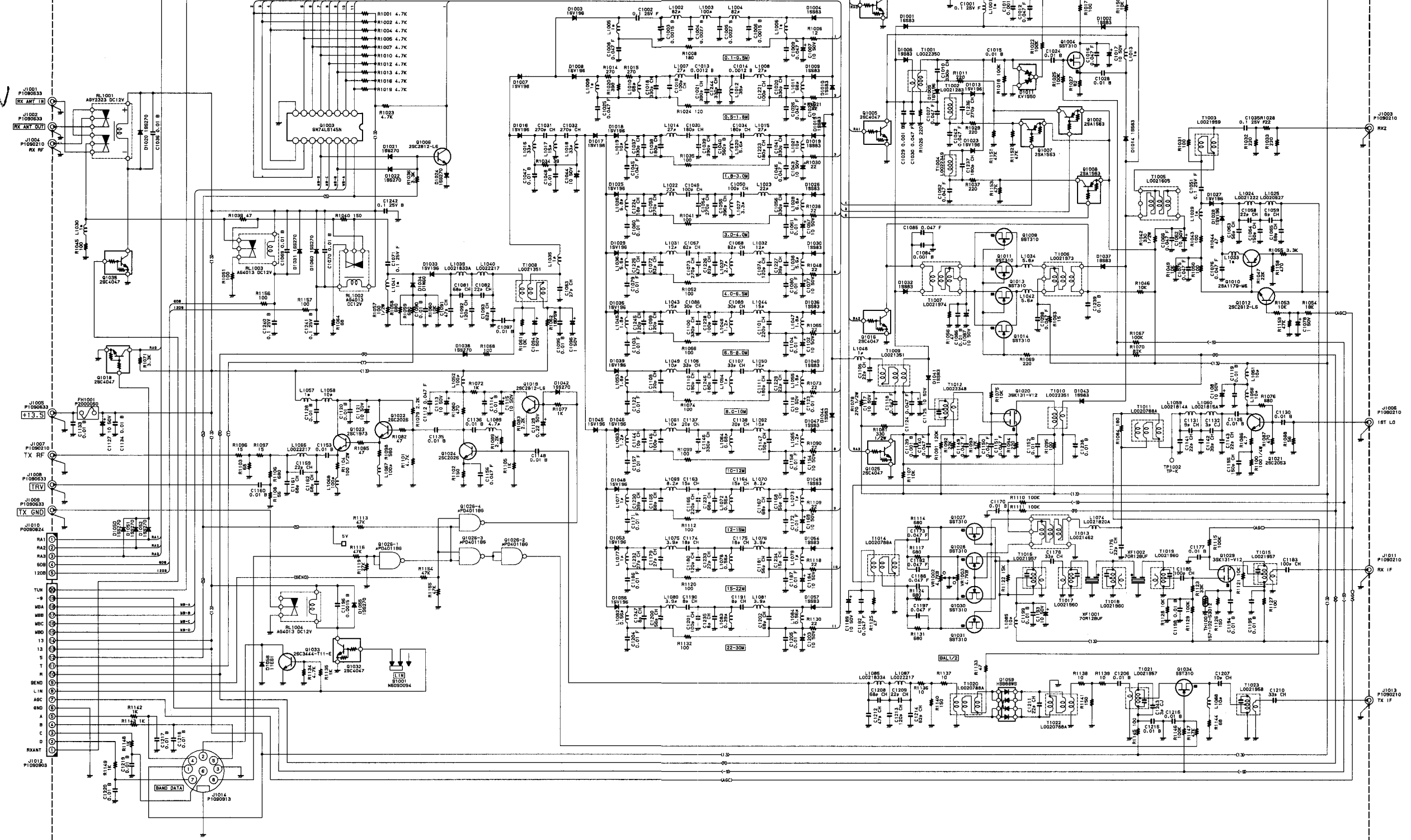
Notes:



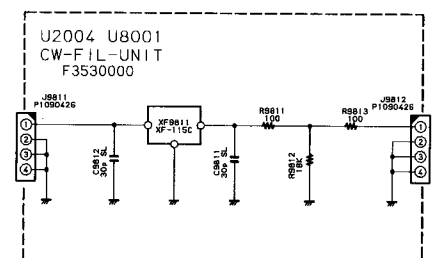
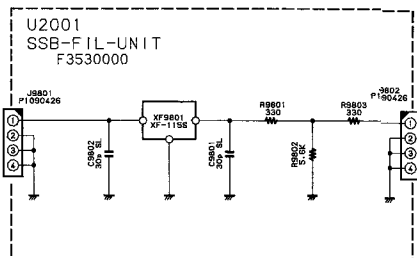
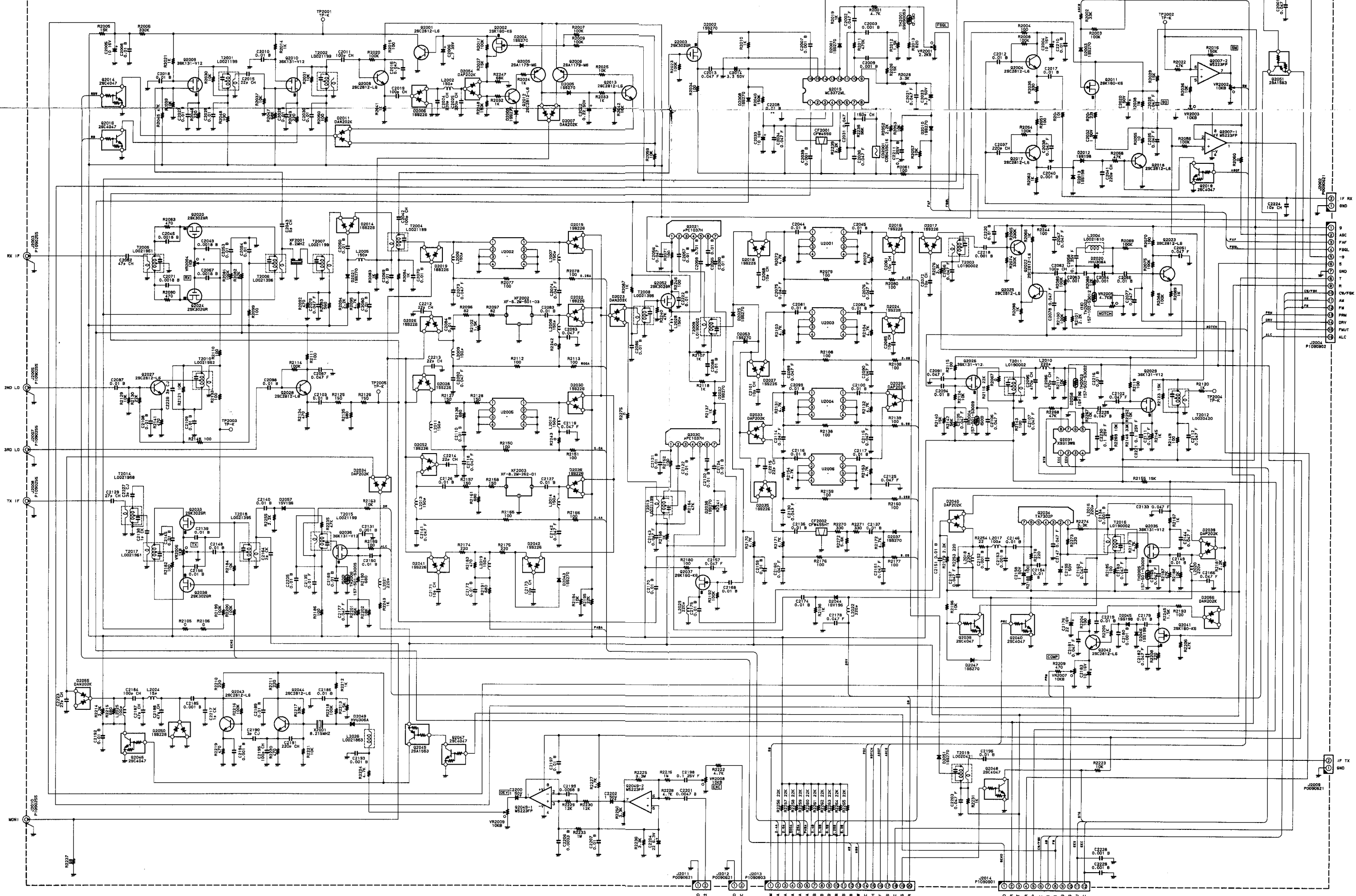
RX LINE \longrightarrow
 TX LINE \longrightarrow
 COMMON LINE \longrightarrow

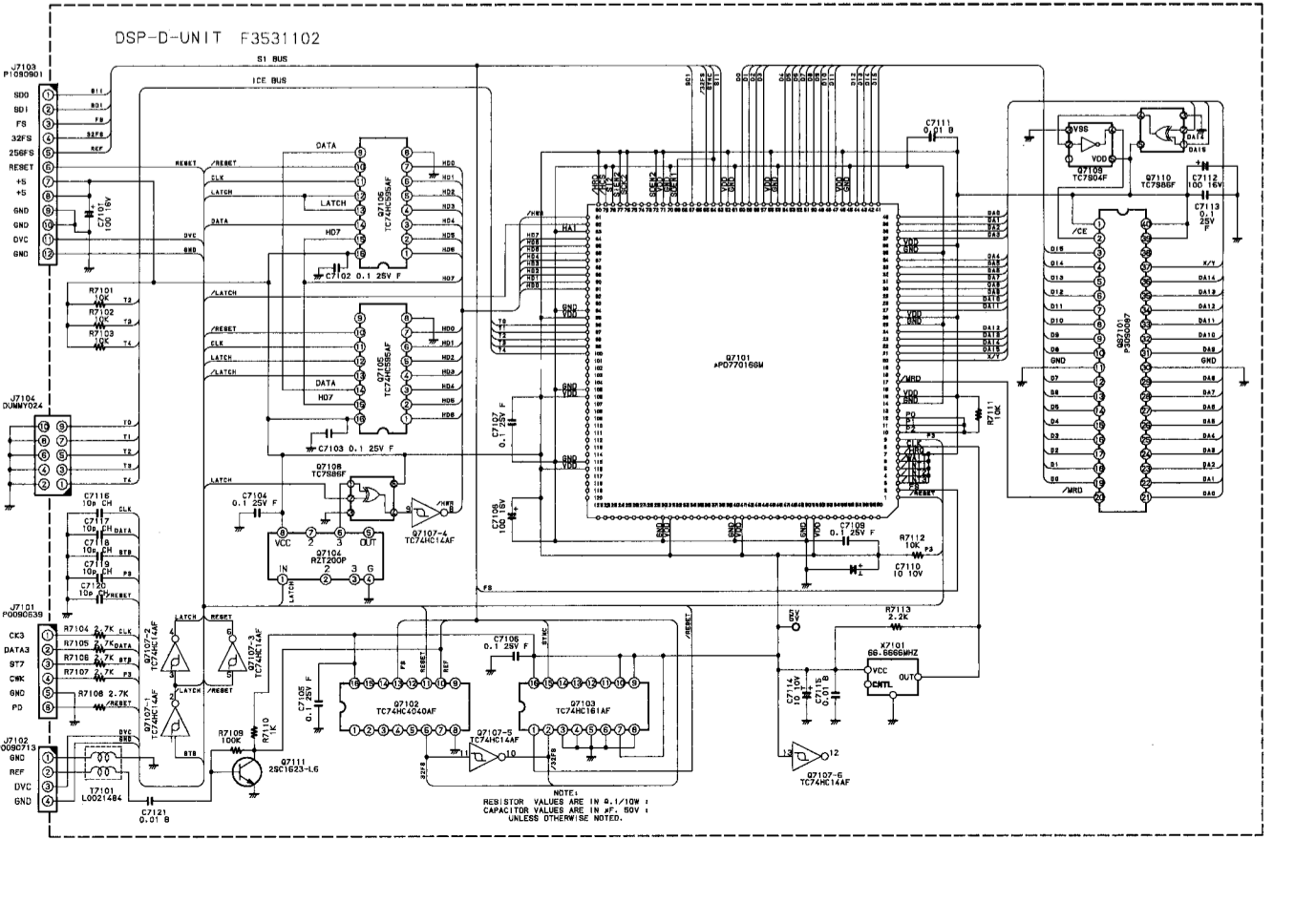
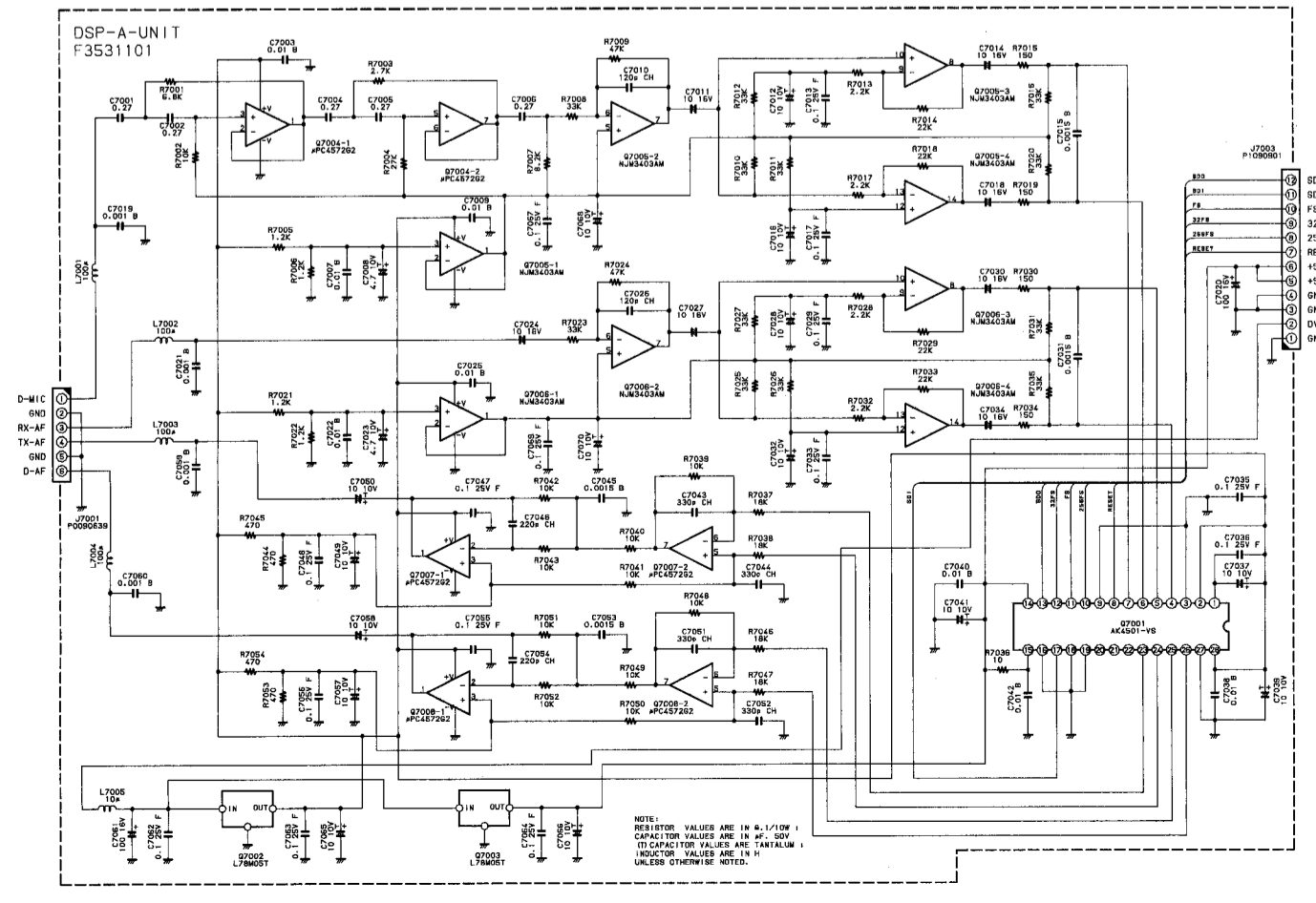
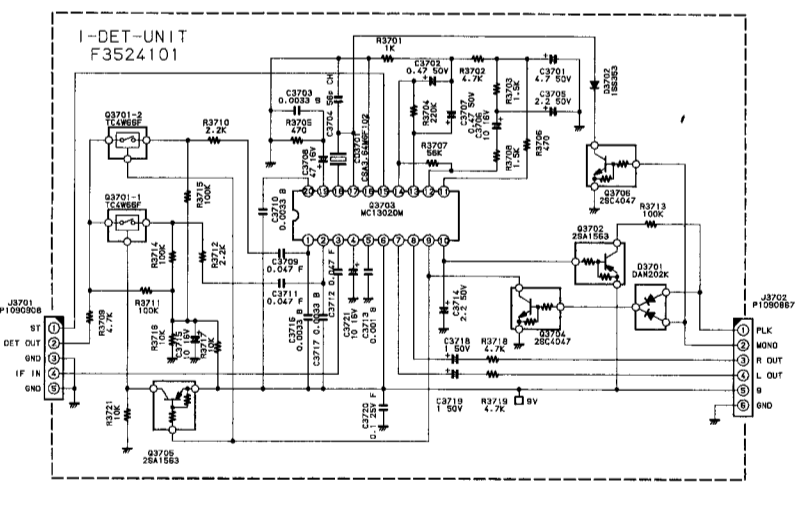
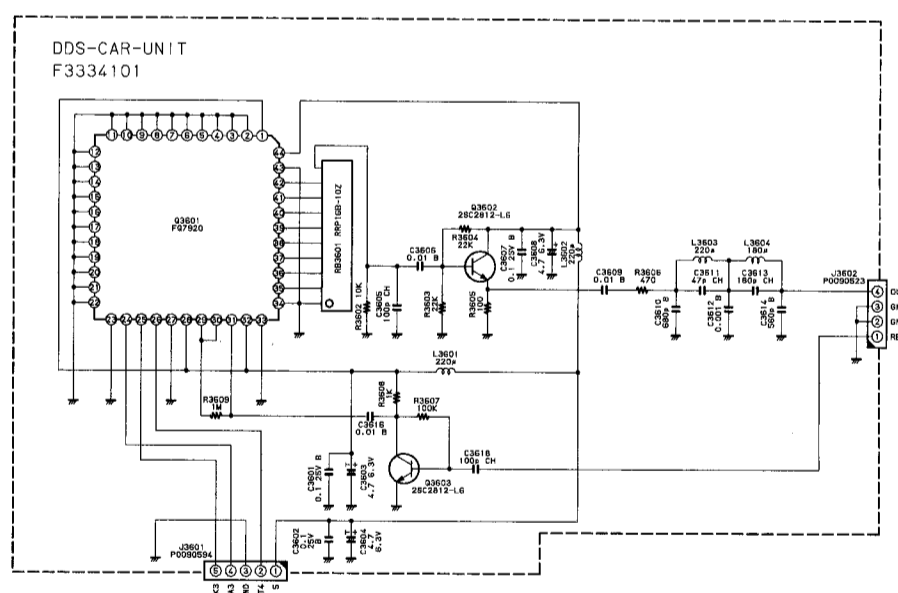
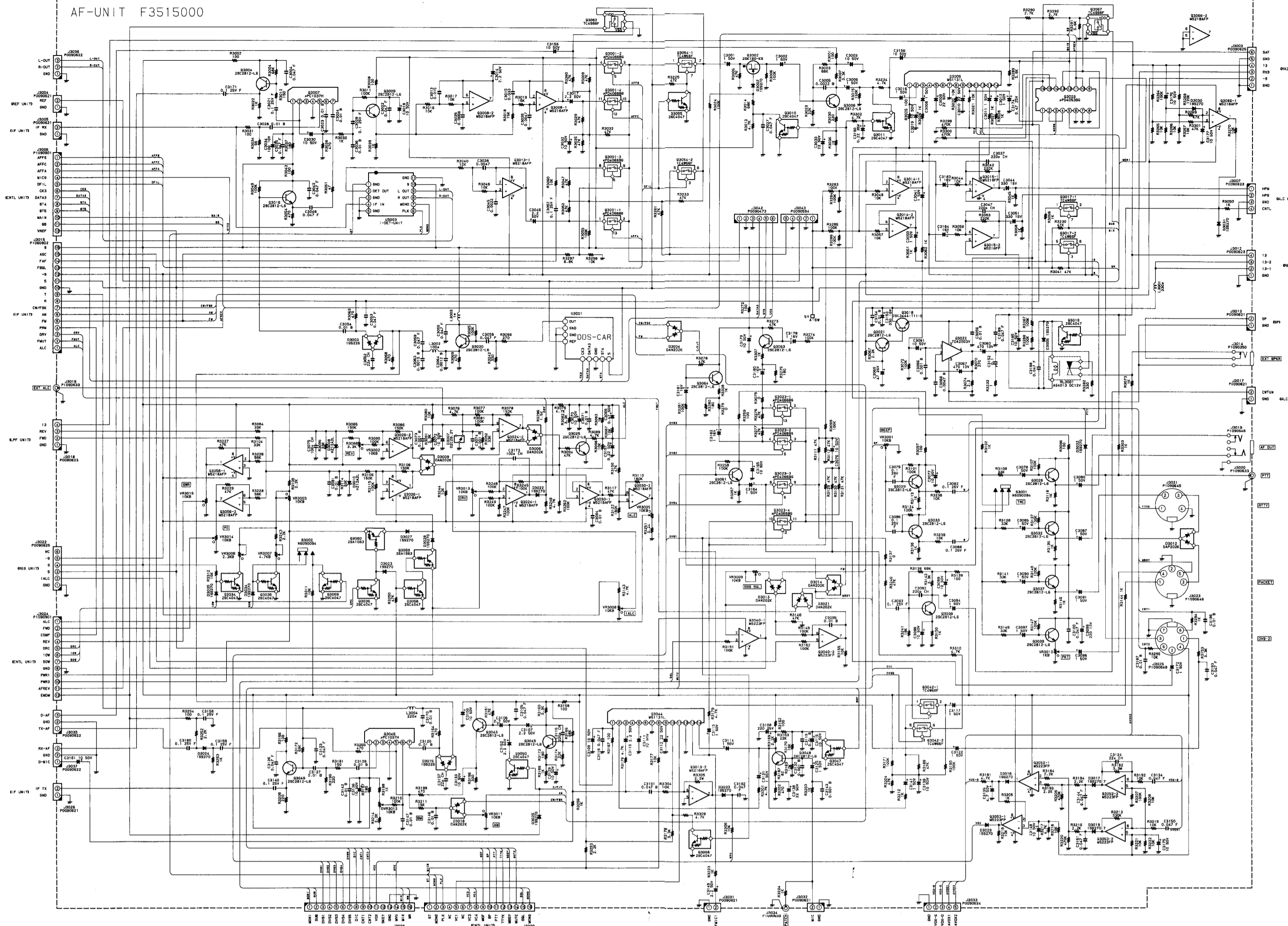


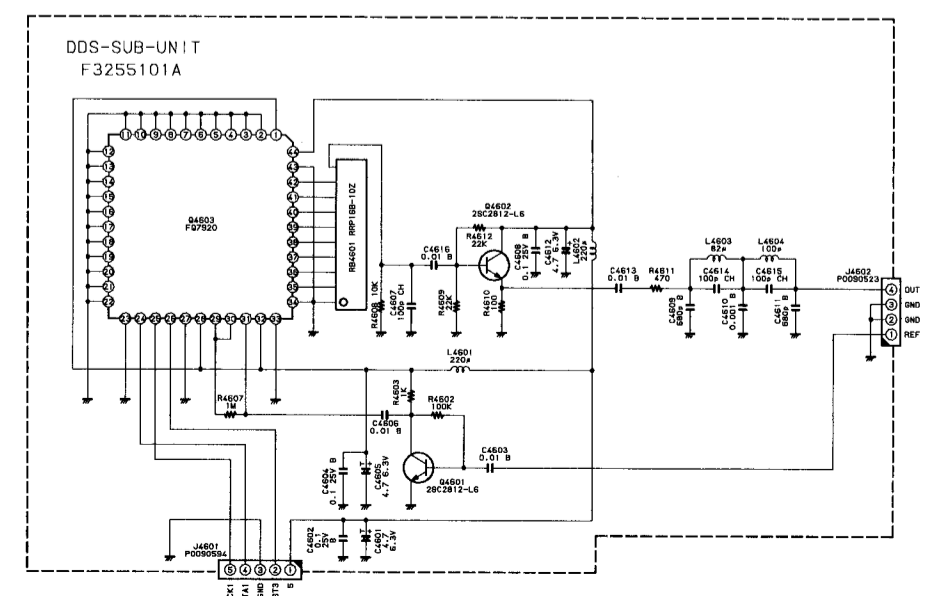
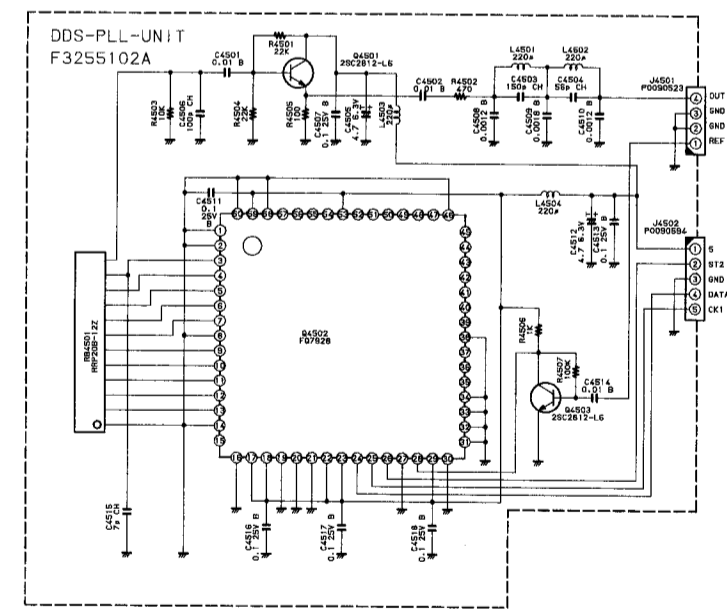
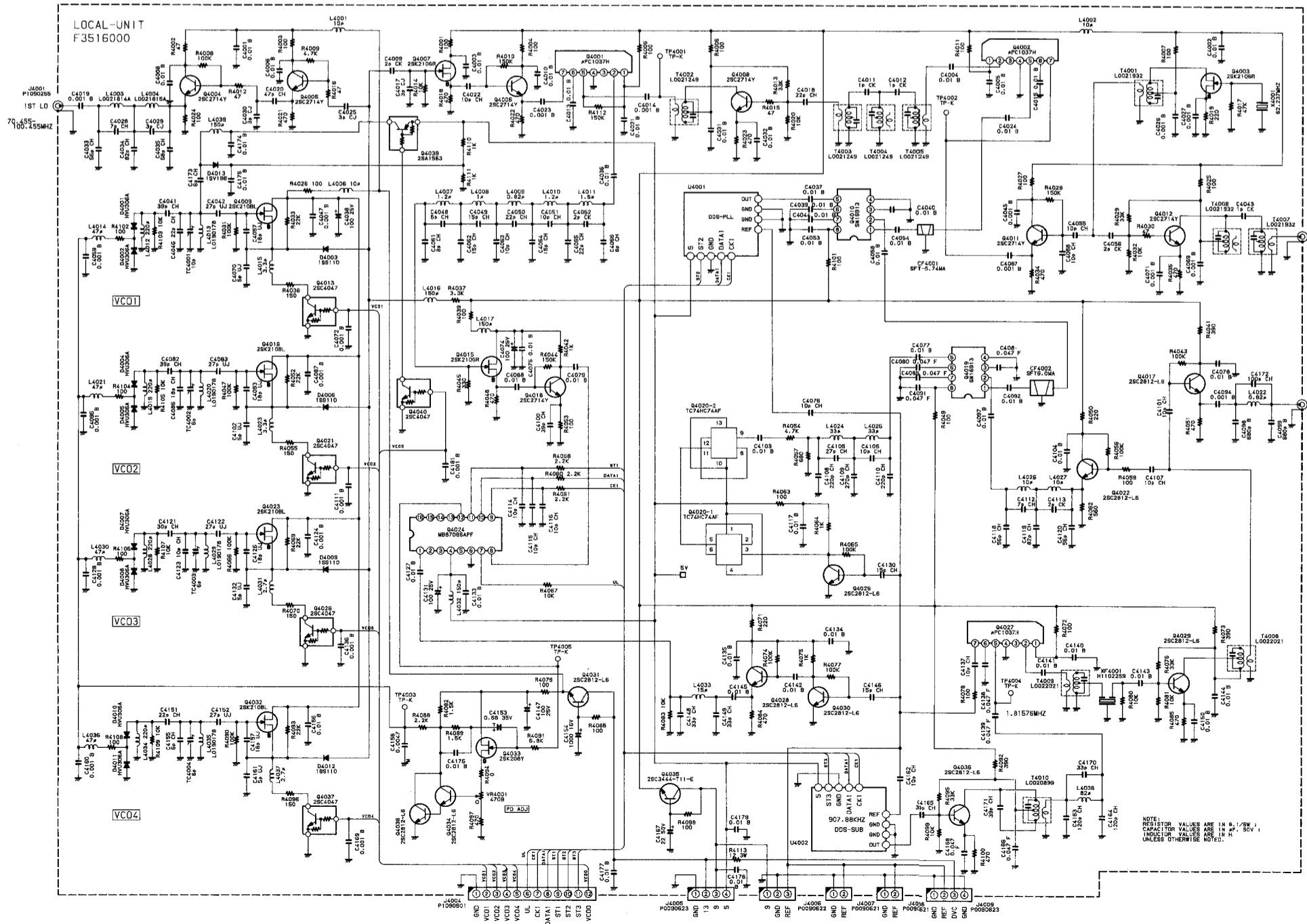
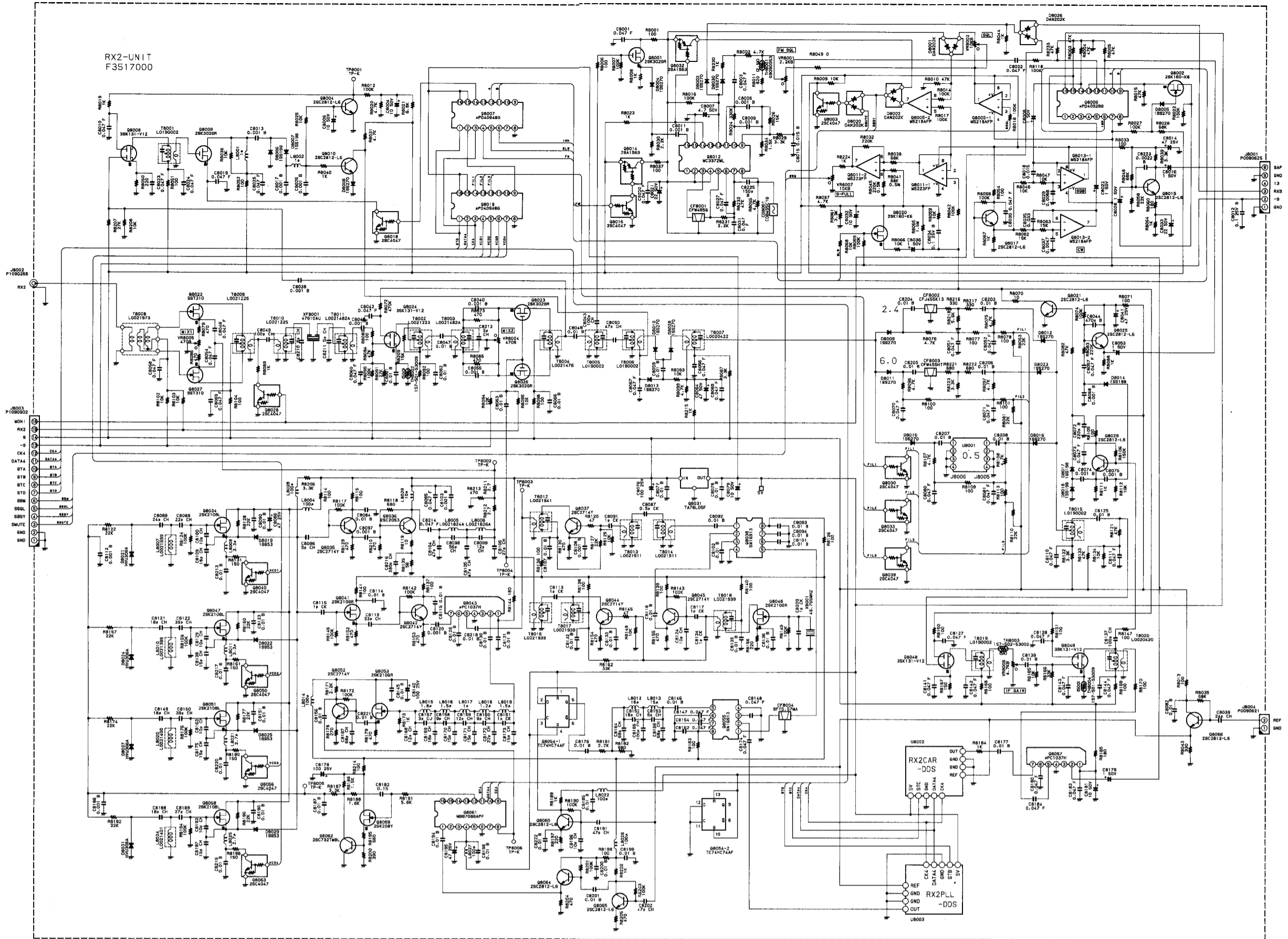
RF-UNIT
F3513000

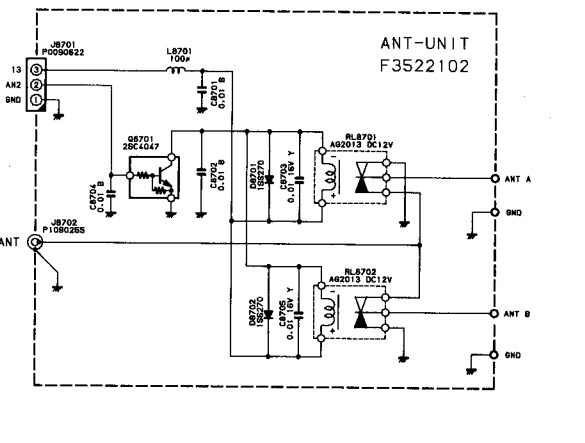
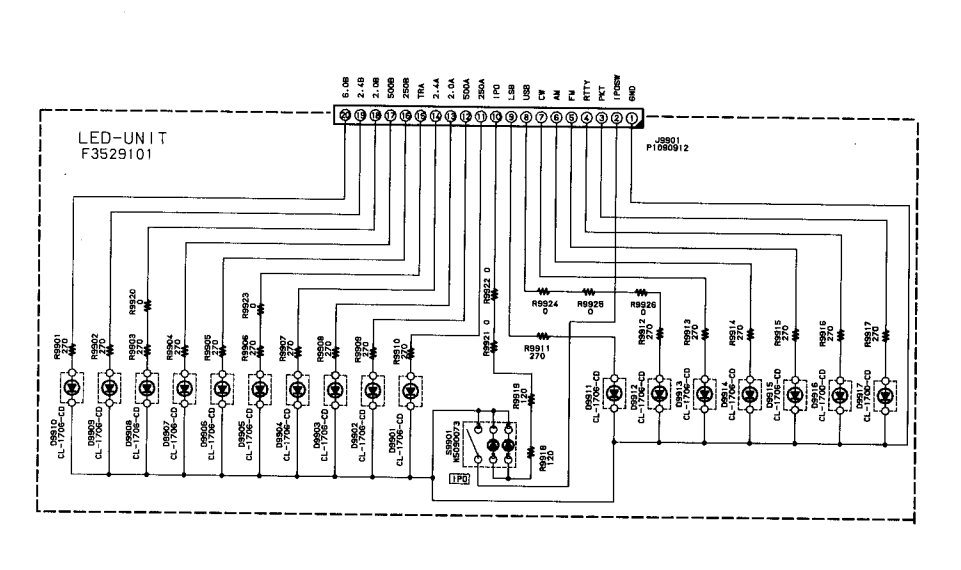
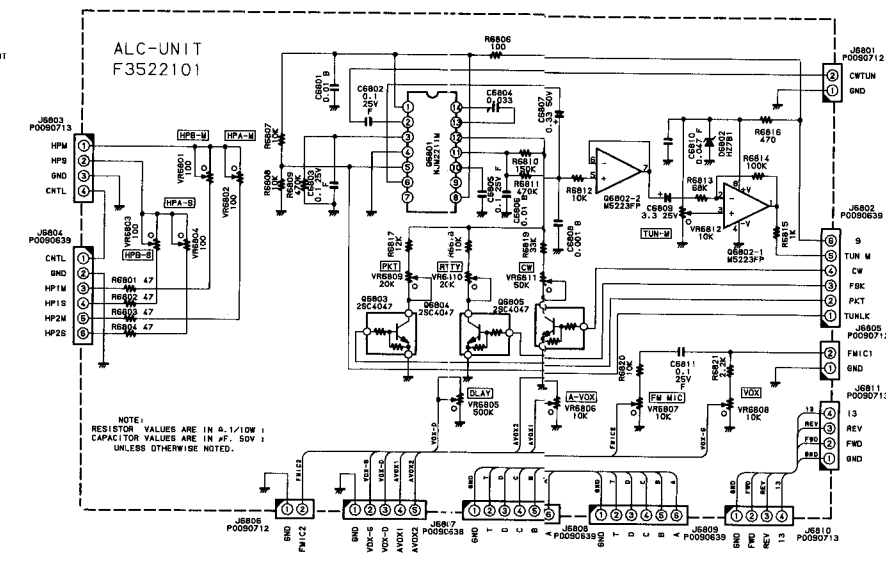
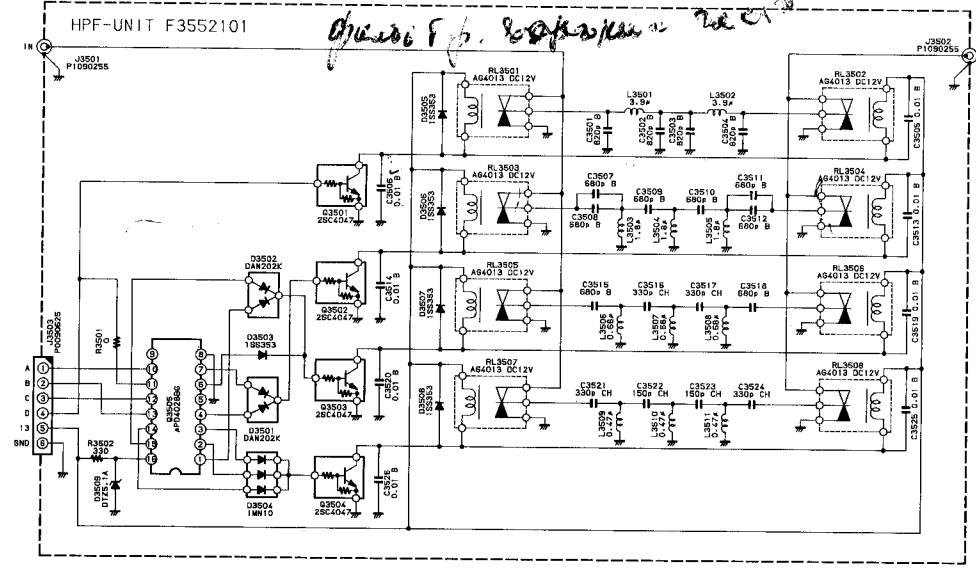
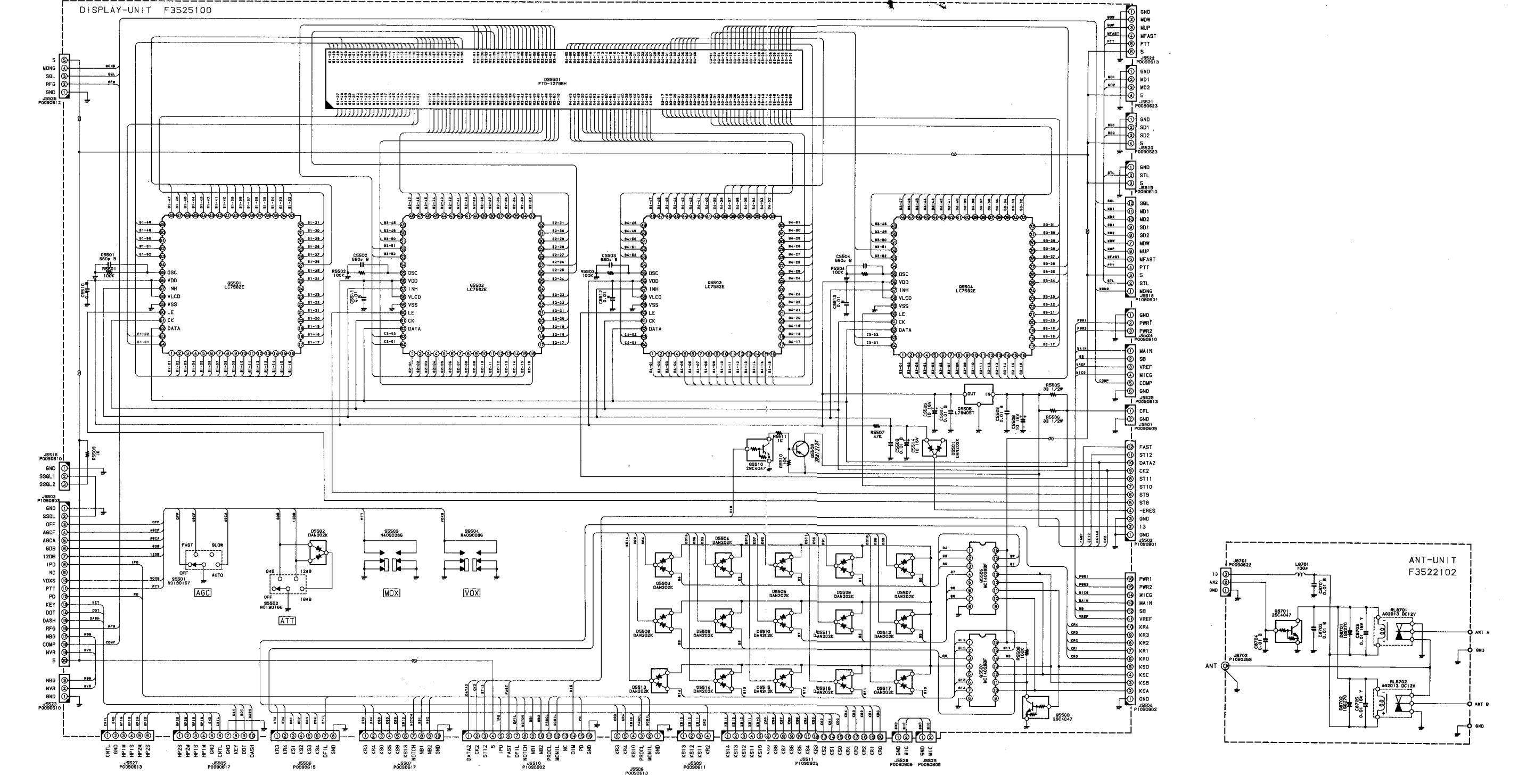
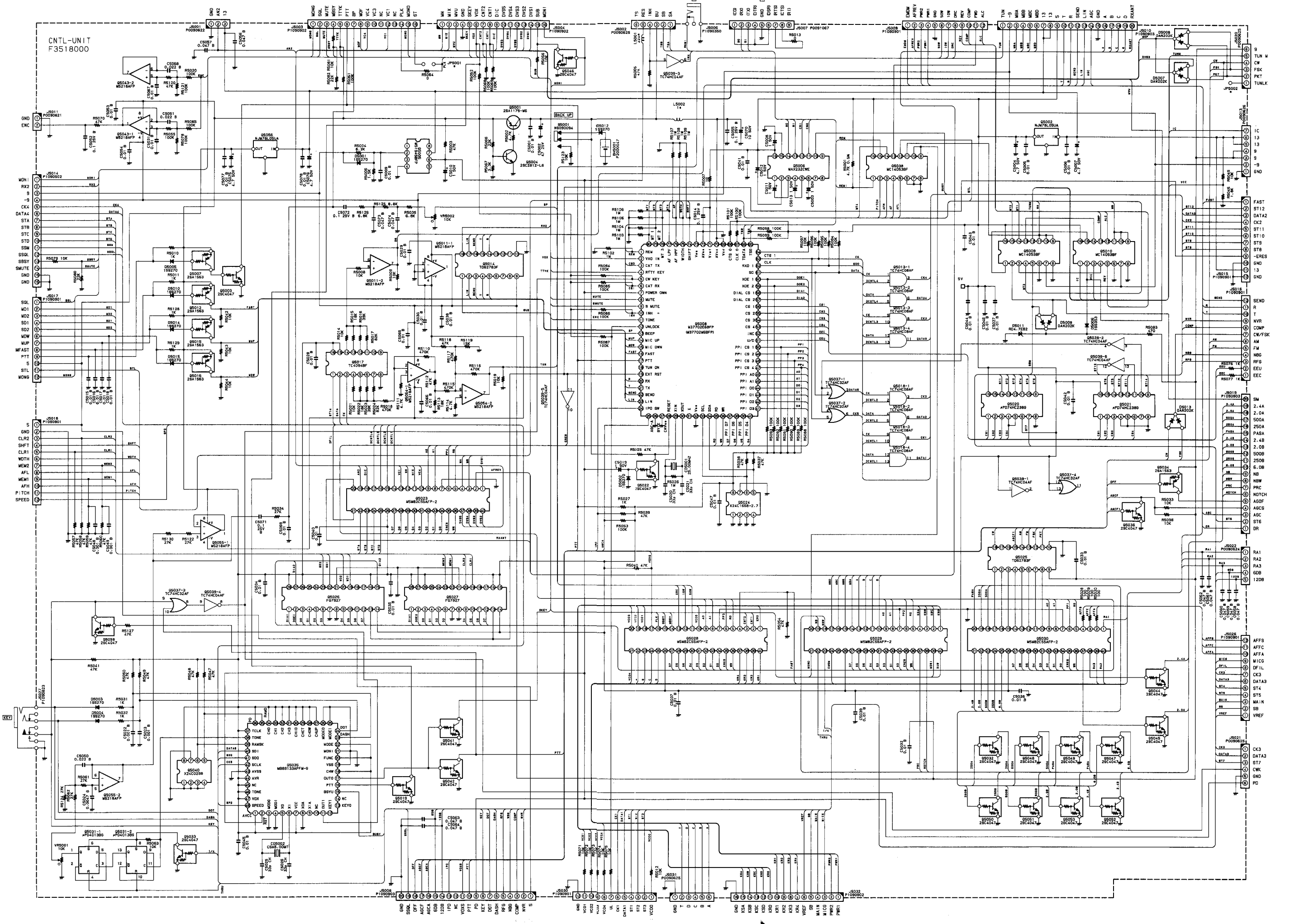


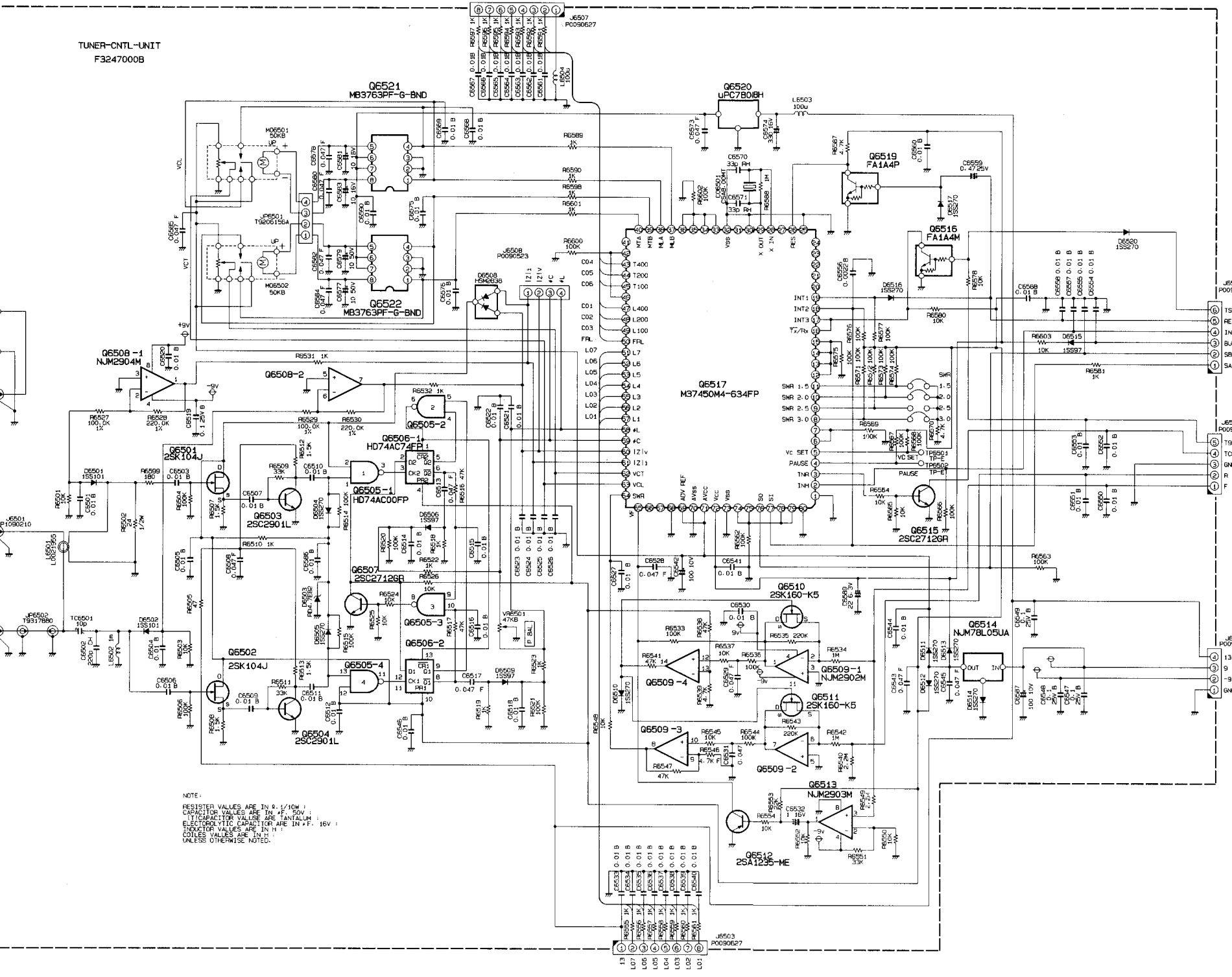
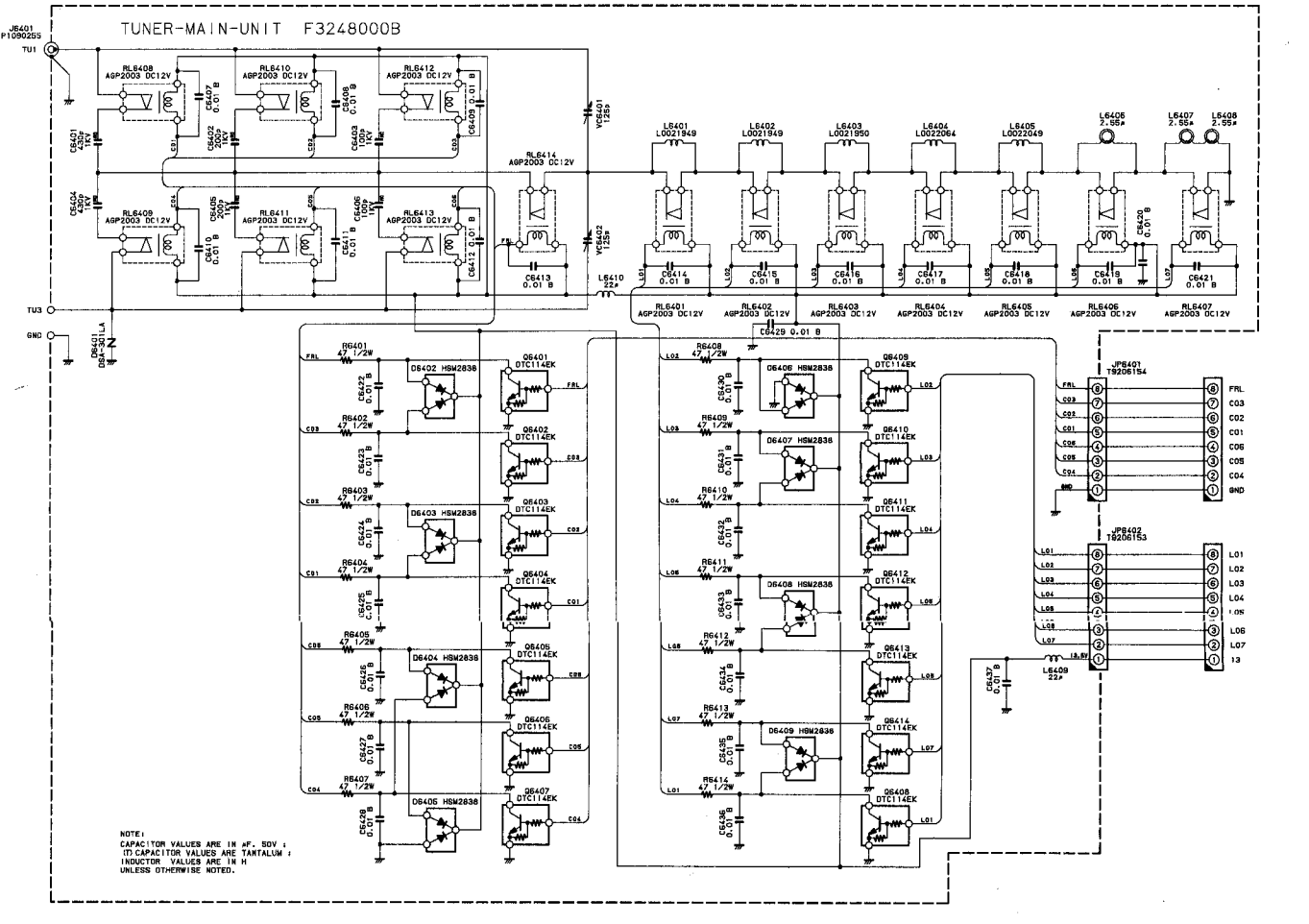
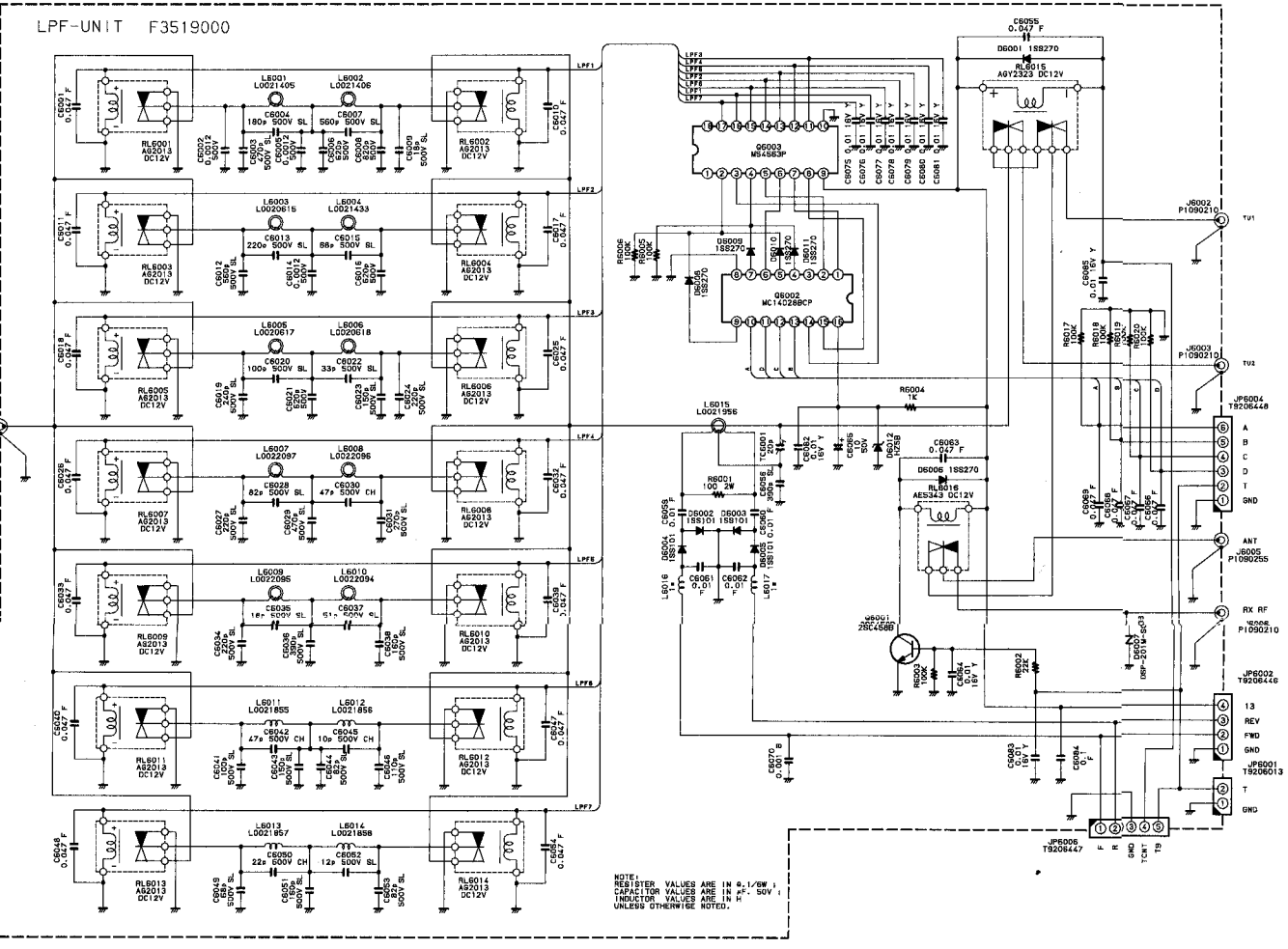
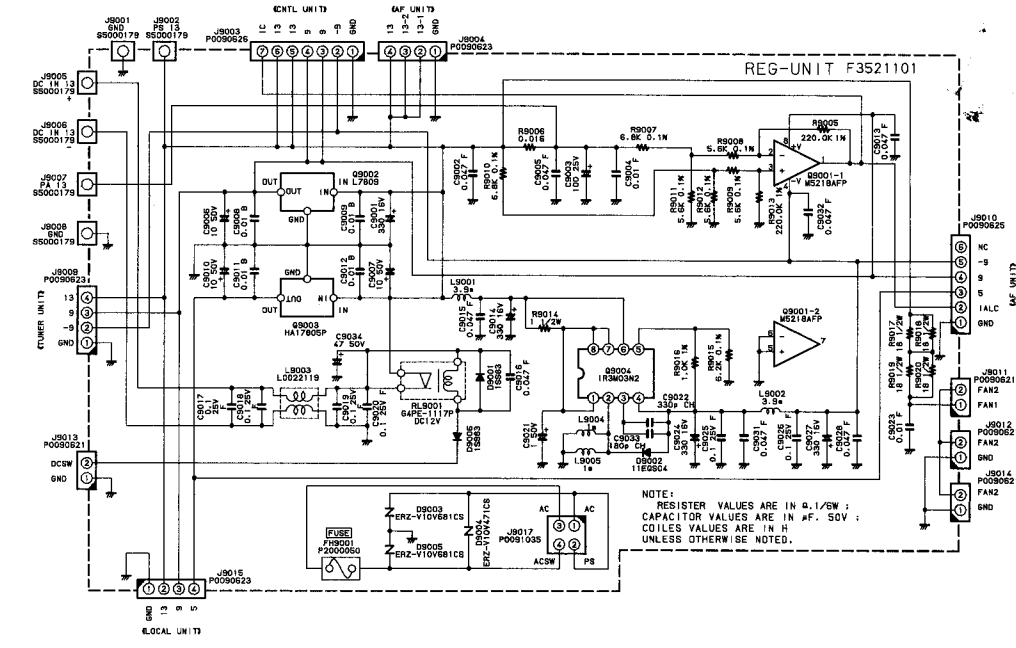
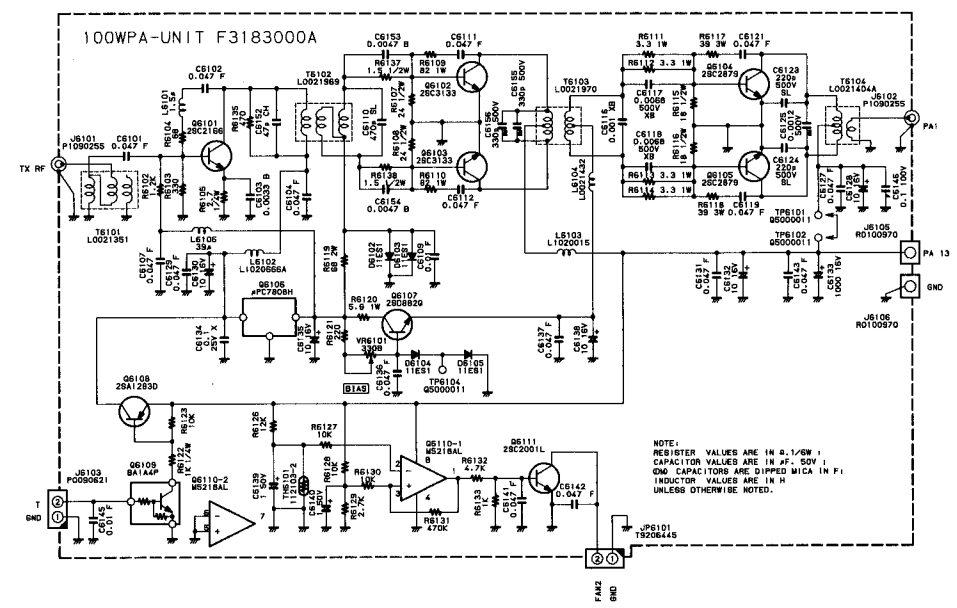
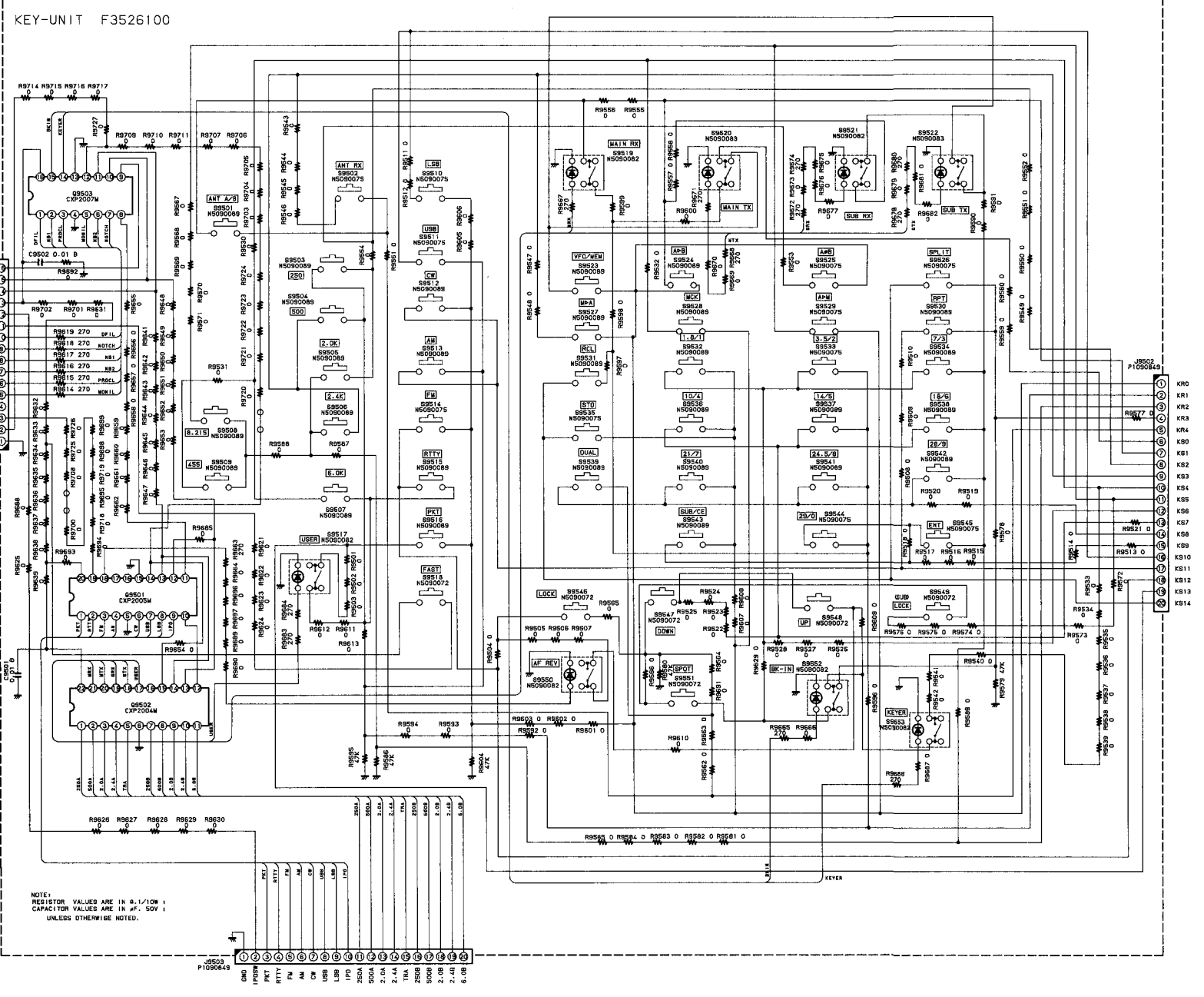
IF-UNIT F3514000



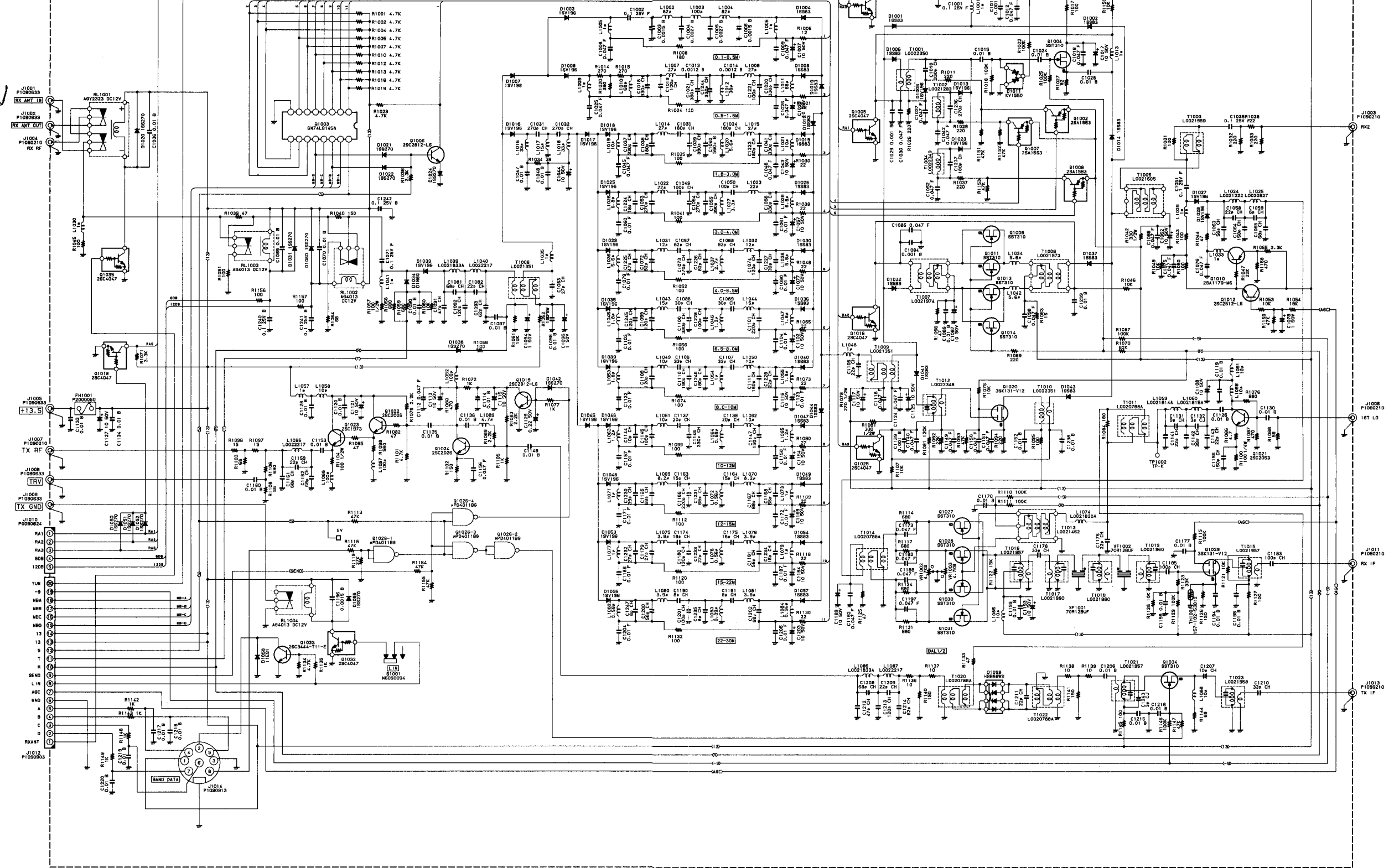




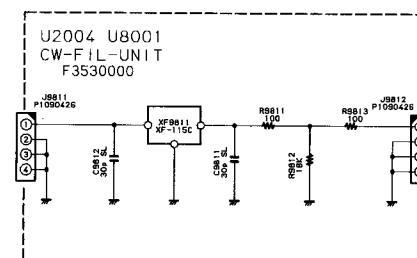
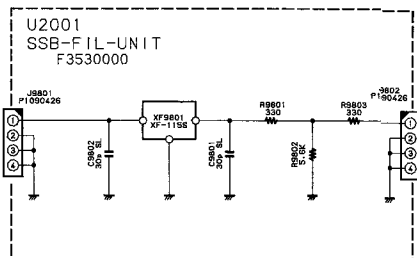
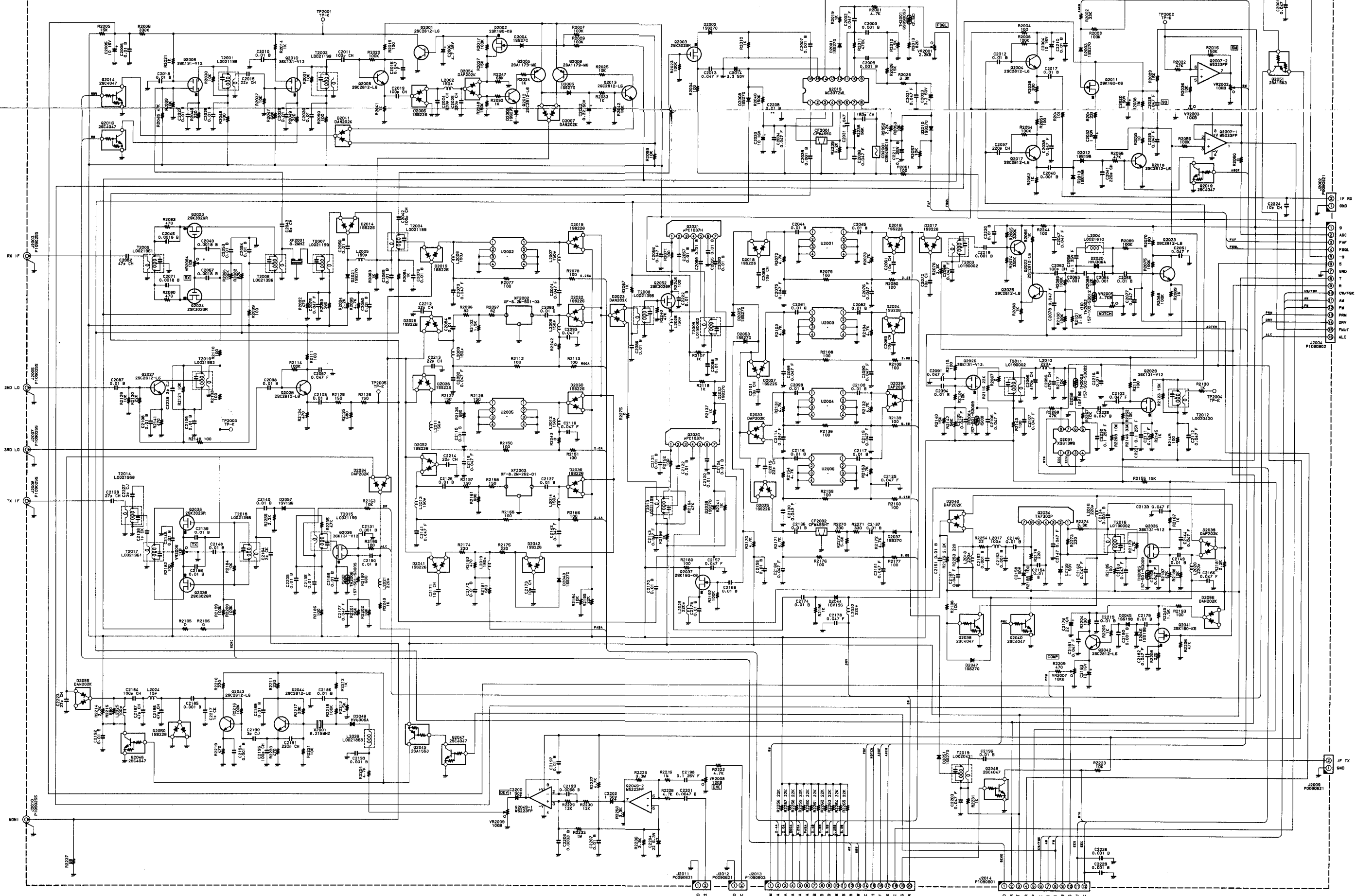




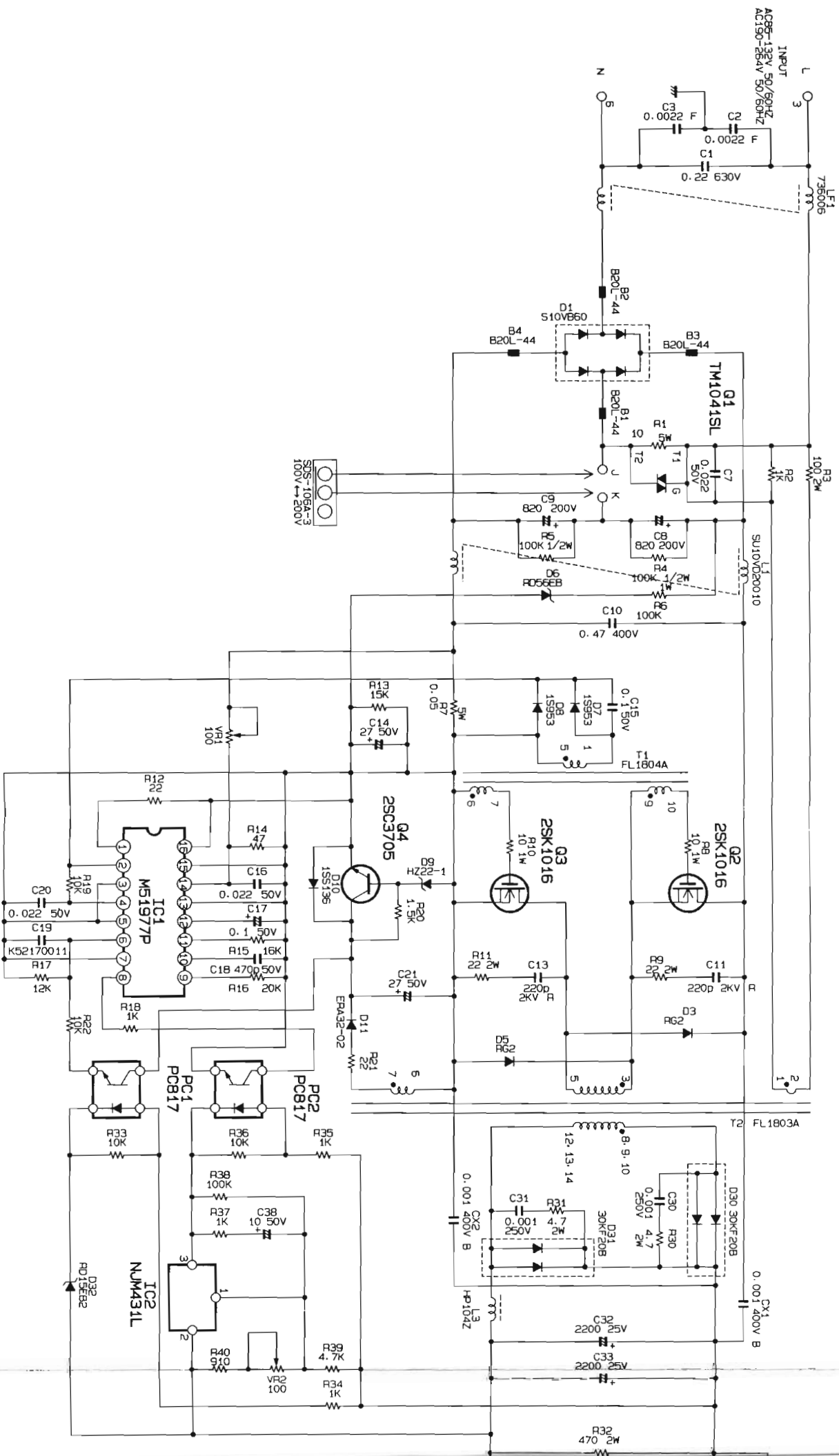
RF-UNIT
F3513000



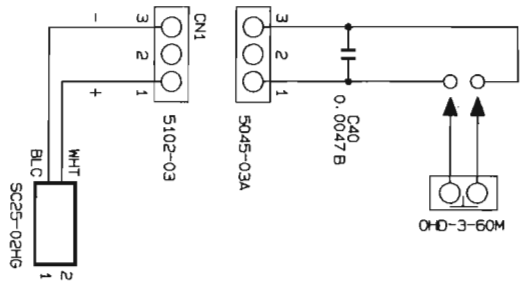
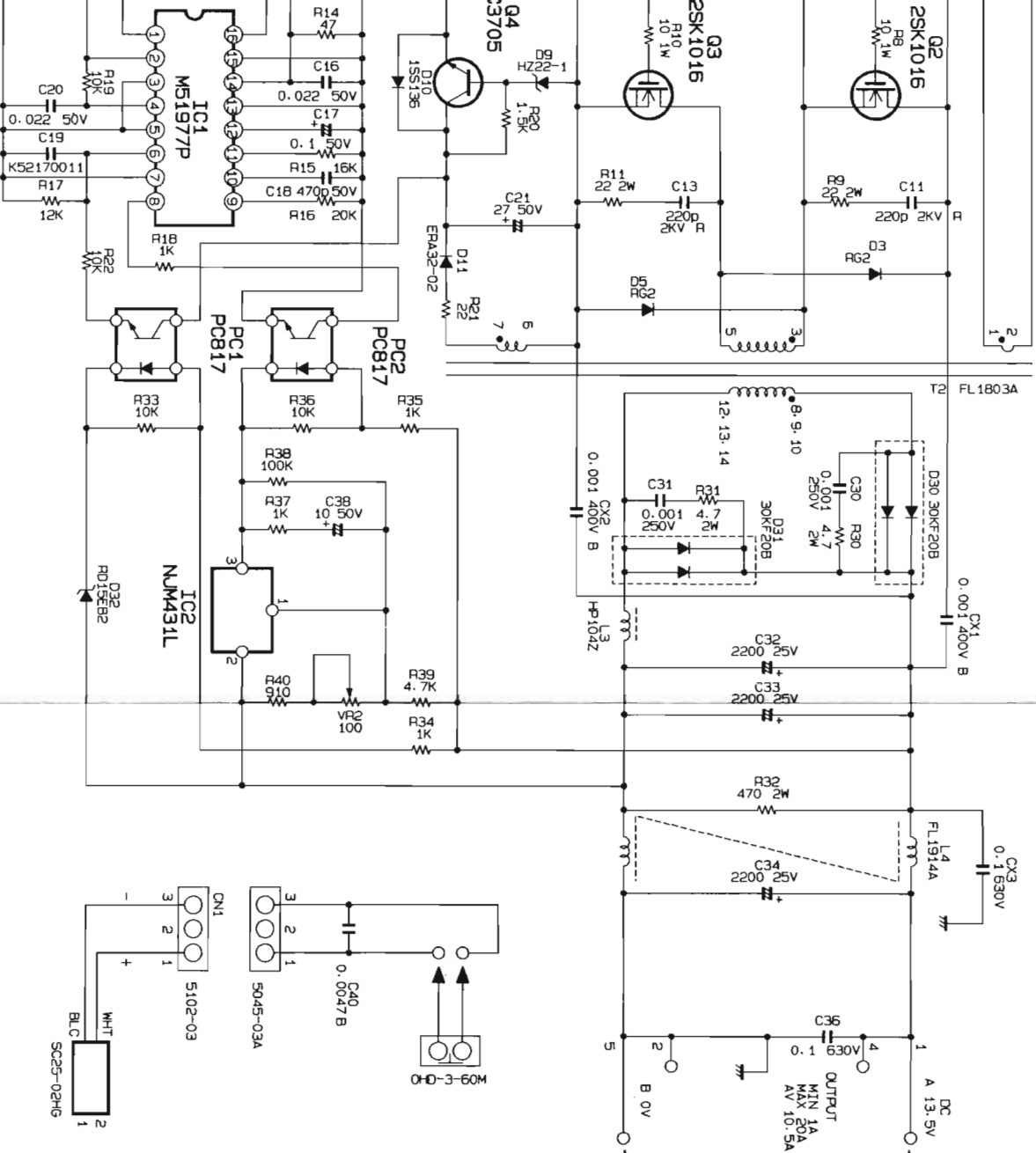
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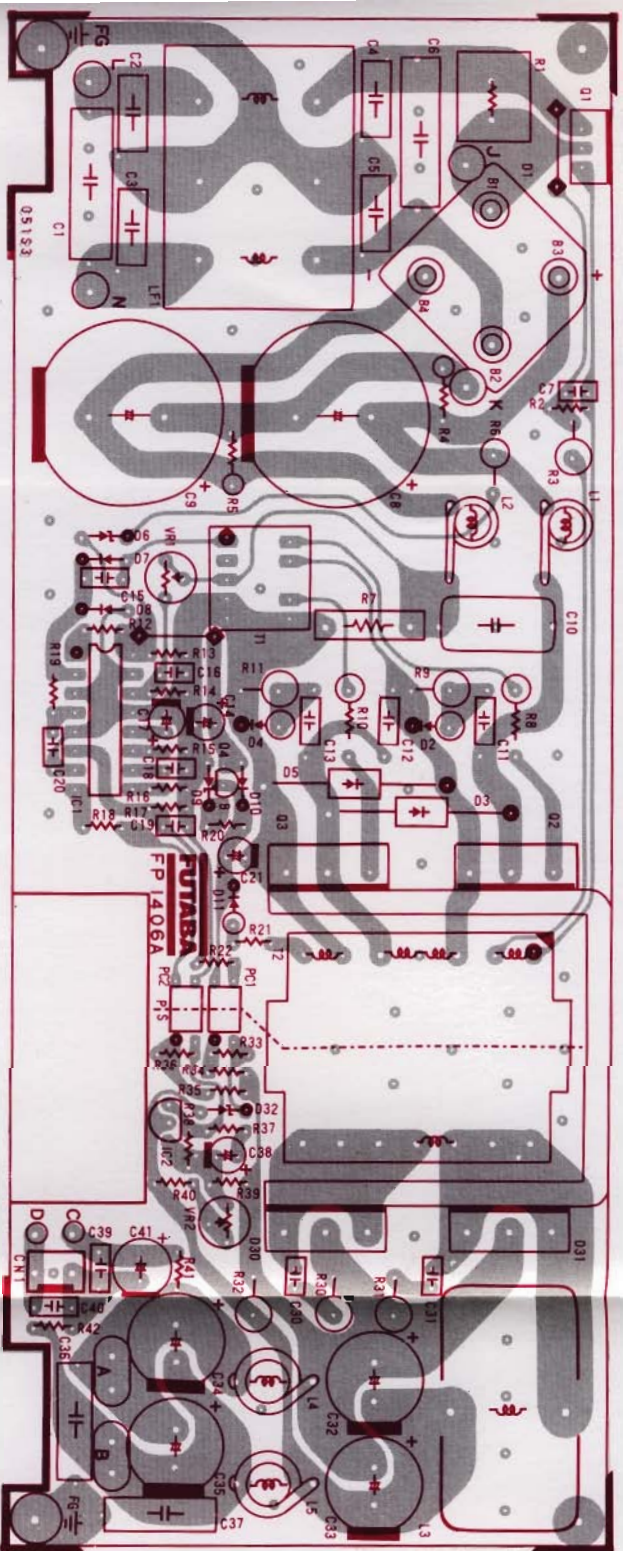


⚠ WARNING! - high voltages present

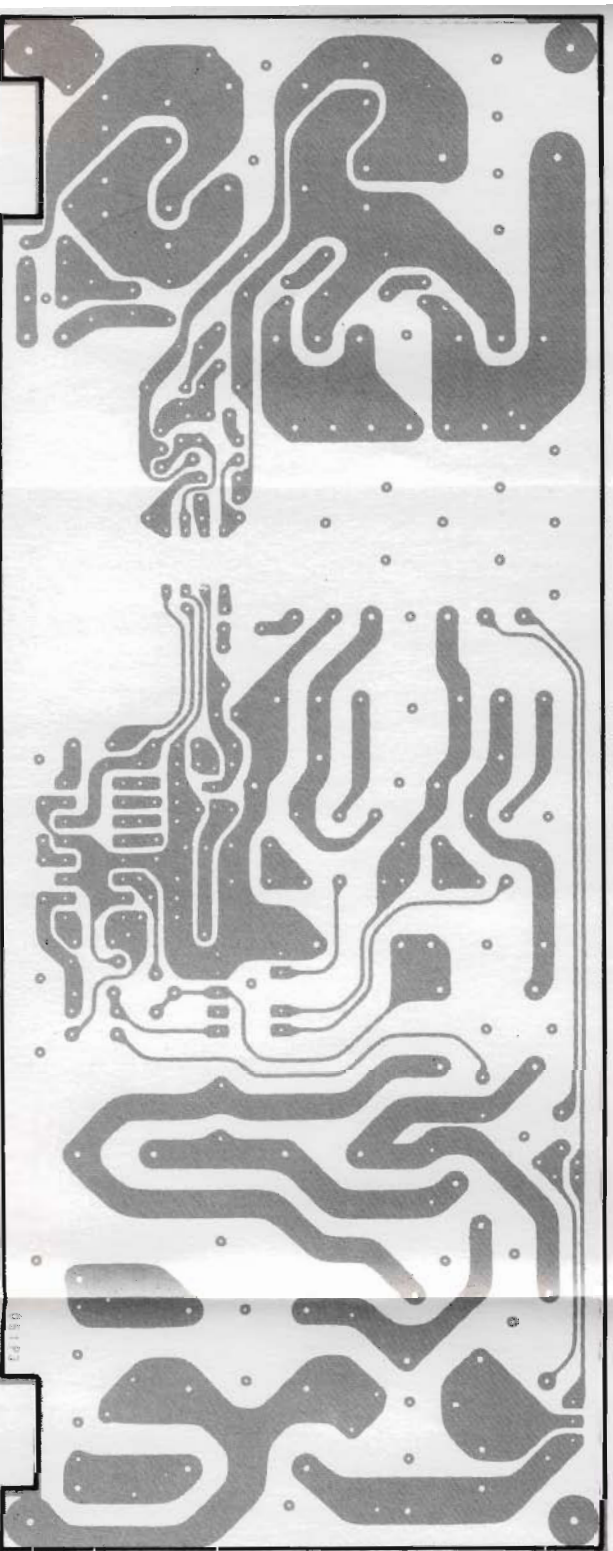


NOTE:
RESISTOR VALUES ARE IN Ω, 1/16W ;
CAPACITOR VALUES ARE IN μF, 50V ;
INDUCTOR VALUES ARE IN H ;
COILS VALUES ARE IN H ;
UNLESS OTHERWISE NOTED.





obverse view of component side



obverse view of solder side

Parts List

REF.	DESCRIPTION	VALUE	WV	TOL.	MFR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
*** PS UNIT ***										
B 0001	FERITE BEADS				B20L-44	L9190071				
B 0002	FERITE BEADS				B20L-44	L9190071				
B 0003	FERITE BEADS				B20L-44	L9190071				
B 0004	FERITE BEADS				B20L-44	L9190071				
C 0001	FILM CAP.	0.22uF	630V		MMH224K630	K52280006				
C 0002	CERAMIC CAP.	0.0022uF		F	DE7100F222MVA1-KC	K13269003				
C 0003	CERAMIC CAP.	0.0022uF		F	DE7100F222MVA1-KC	K13269003				
C 0007	FILM CAP.	0.22uF	50V		AMZ223K50	K52170008				
C 0008	AL. ELECTRO. CAP.	820uF	200V		CEAWF2D821M20	K40239004				
C 0009	AL. ELECTRO. CAP.	820uF	200V		CEAWF2D821M20	K40239004				
C 0010	FILM CAP.	0.47uF	400V		ECQB4474KF	K52260001				
C 0011	CERAMIC CAP.	220pF	2KV	R	DE5077R221K2K	K10339001				
C 0013	CERAMIC CAP.	220pF	2KV	R	DE5077R221K2K	K10339001				
C 0014	AL. ELECTRO. CAP.	27uF	50V		ECEA1HFE270	K40179051				
C 0015	FILM CAP.	0.1uF	50V		AMZ104K50	K52170009				
C 0016	FILM CAP.	0.022uF	50V		AMZ223K50	K52170008				
C 0017	AL. ELECTRO. CAP.	0.1uF	50V		CEUSM1HR10	K40179054				
C 0018	FILM CAP.	470pF	50V		AMZ471K50	K52170010				
C 0019	FILM CAP.	0.047uF	50V		AMZ473K50	K52170011				
C 0020	FILM CAP.	0.022uF	50V		AMZ223K50	K52170008				
C 0021	AL. ELECTRO. CAP.	27uF	50V		ECEA1HFE270	K40179051				
C 0030	FILM CAP.	0.001uF	250V		AMZ102K250	K52240005				
C 0031	FILM CAP.	0.001uF	250V		AMZ102K250	K52240005				
C 0032	AL. ELECTRO. CAP.	2200uF	25V		ECA1EFQ222L	K40149038				
C 0033	AL. ELECTRO. CAP.	2200uF	25V		ECA1EFQ222L	K40149038				
C 0034	AL. ELECTRO. CAP.	2200uF	25V		ECA1EFQ222L	K40149038				
C 0036	FILM CAP.	0.1uF	630V		MMH104K630	K52280007				
C 0038	AL. ELECTRO. CAP.	10uF	50V		CEUSM1H100	K40179053				
C 0040	CERAMIC CAP.	0.0047uF	50V	B	DD108B472K50	K10179038				
CN0001	CONNECTOR				5045-03A	P0090219				
CX0001	CERAMIC CAP.	0.001uF	400V	B	DE7090B102KVA1-KC	K10269002				
CX0002	CERAMIC CAP.	0.001uF	400V	B	DE7090B102KVA1-KC	K10269002				
CX0003	FILM CAP.	0.01uF	630V		MMH103K630	K52280008				
D 0001	DIODE				S10VB60	G2090501				
D 0003	DIODE				RG2	G2090502				
D 0005	DIODE				RG2	G2090502				
D 0006	DIODE				RD56EB	G2090503				
D 0007	DIODE				1S953	G2009530				
D 0008	DIODE				1S953	G2009530				
D 0009	DIODE				HZ22-1	G2090455				
D 0010	DIODE				1SS136	G2090504				
D 0011	DIODE				ERA32-02	G2090505				
D 0030	DIODE				30KF20B	G2090506				

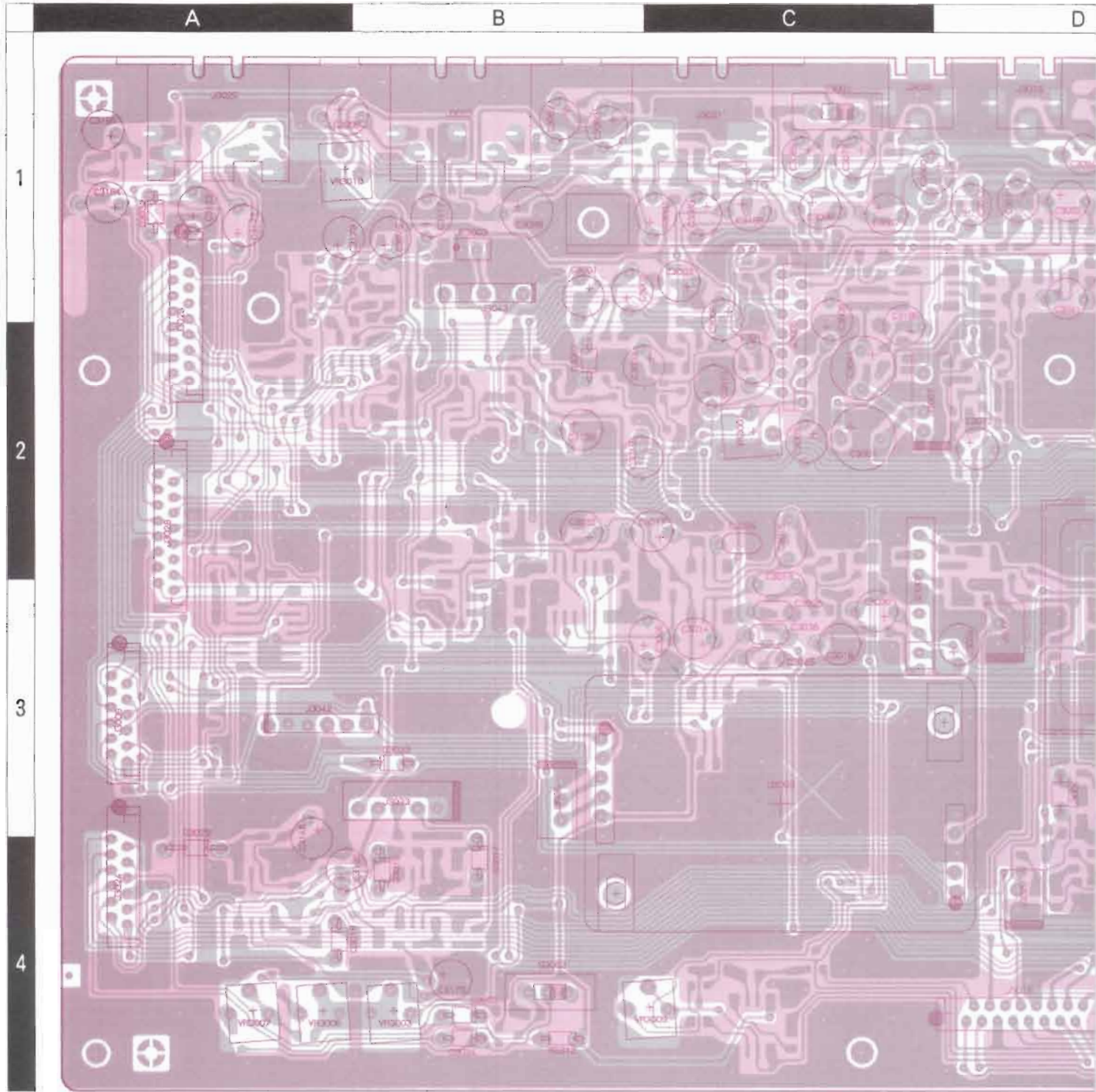
PS Unit

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D 0031	DIODE				30KF20B	G2090506				
D 0032	DIODE				RD15EB2	G2090507				
IC0001	IC				M51977P	G1091275				
IC0002	IC				NJM431L	G1091276				
L 0001	RFC				SU10VD20010	S8100251				
L 0003	RFC				HP104Z	S8100205				
L 0004	RFC				FL1914A	S8100252				
LF0001	LINE FILTER				736006	S8100201				
PC0001	PHOTO COUPLER				PC817	G0090006				
PC0002	PHOTO COUPLER				PC817	G0090006				
Q 0001	TRIAC				TM1041SL	G3090096				
Q 0002	FET				2SK1016	G3810160				
Q 0003	FET				2SK1016	G3810160				
Q 0004	TRANSISTOR				2SC3705	G3337050				
R 0001	FUSE RES.	10	5W		A53K10J	J31379001				
R 0002	CARBON FILM RES.	1K	1/6W		RD16PJ102	J01225102				
R 0003	METAL FILM RES.	100	2W		ERG-2SJ101	J22335101				
R 0004	CARBON FILM RES.	100K	1/2W		RD12TJ104	J01275104				
R 0005	CARBON FILM RES.	100K	1/2W		RD12TJ104	J01275104				
R 0006	METAL FILM RES.	100K	1W		RSU1-100K J	J22305104				
R 0007	CEMENT RES.	0.05	5W		MPC75-0.05 K	J31379002				
R 0008	METAL FILM RES.	10	1W		ERG-1SJ100	J22305100				
R 0009	METAL FILM RES.	22	2W		ERG-2SJ220	J22335220				
R 0010	METAL FILM RES.	10	1W		ERG-1SJ100	J22305100				
R 0011	METAL FILM RES.	22	2W		ERG-2SJ220	J22335220				
R 0012	CARBON FILM RES.	22	1/6W		RD16PJ220	J01225220				
R 0013	CARBON FILM RES.	15K	1/6W		RD16PJ153	J01225153				
R 0014	CARBON FILM RES.	47	1/6W		RD16PJ470	J01225470				
R 0015	CARBON FILM RES.	16K	1/6W		RD16PJ163	J01225163				
R 0016	CARBON FILM RES.	20K	1/6W		RD16PJ203	J01225203				
R 0017	CARBON FILM RES.	12K	1/6W		RD16PJ123	J01225123				
R 0018	CARBON FILM RES.	1K	1/6W		RD16PJ102	J01225102				
R 0019	CARBON FILM RES.	10K	1/6W		RD16PJ103	J01225103				
R 0020	CARBON FILM RES.	1.5K	1/6W		RD16PJ152	J01225152				
R 0021	CARBON FILM RES.	22	1/6W		RD16PJ220	J01225220				
R 0022	CARBON FILM RES.	10K	1/6W		RD16PJ103	J01225103				
R 0030	METAL FILM RES.	4.7	2W		ERX-2SJ4R7	J22335479				
R 0031	METAL FILM RES.	4.7	2W		ERX-2SJ4R7	J22335479				
R 0032	METAL FILM RES.	470	2W		ERG-2SJ471	J22339007				
R 0033	CARBON FILM RES.	10K	1/6W		RD16PJ103	J01225103				
R 0034	CARBON FILM RES.	1K	1/6W		RD16PJ102	J01225102				
R 0035	CARBON FILM RES.	1K	1/6W		RD16PJ102	J01225102				
R 0036	CARBON FILM RES.	10K	1/6W		RD16PJ103	J01225103				

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
R 0037	CARBON FILM RES.	1K	1/6W		RD16PJ102	J01225102				
R 0038	CARBON FILM RES.	100K	1/6W		RD16PJ104	J01225104				
R 0039	CARBON FILM RES.	4.7K	1/6W		RD16PJ472	J01225472				
R 0040	CARBON FILM RES.	910	1/6W		RD16PJ911	J01225911				
T 0001	DRIVER TRANS.				FL1804A	S8100202				
T 0002	CONVERTER TRANS.				FL1803A	S8100203				
VR0001	POT.	100			EVN-38C-A00-B12	S8100207				
VR0002	POT.	100			EVN-38C-A00-B12	S8100207				

Parts Layout

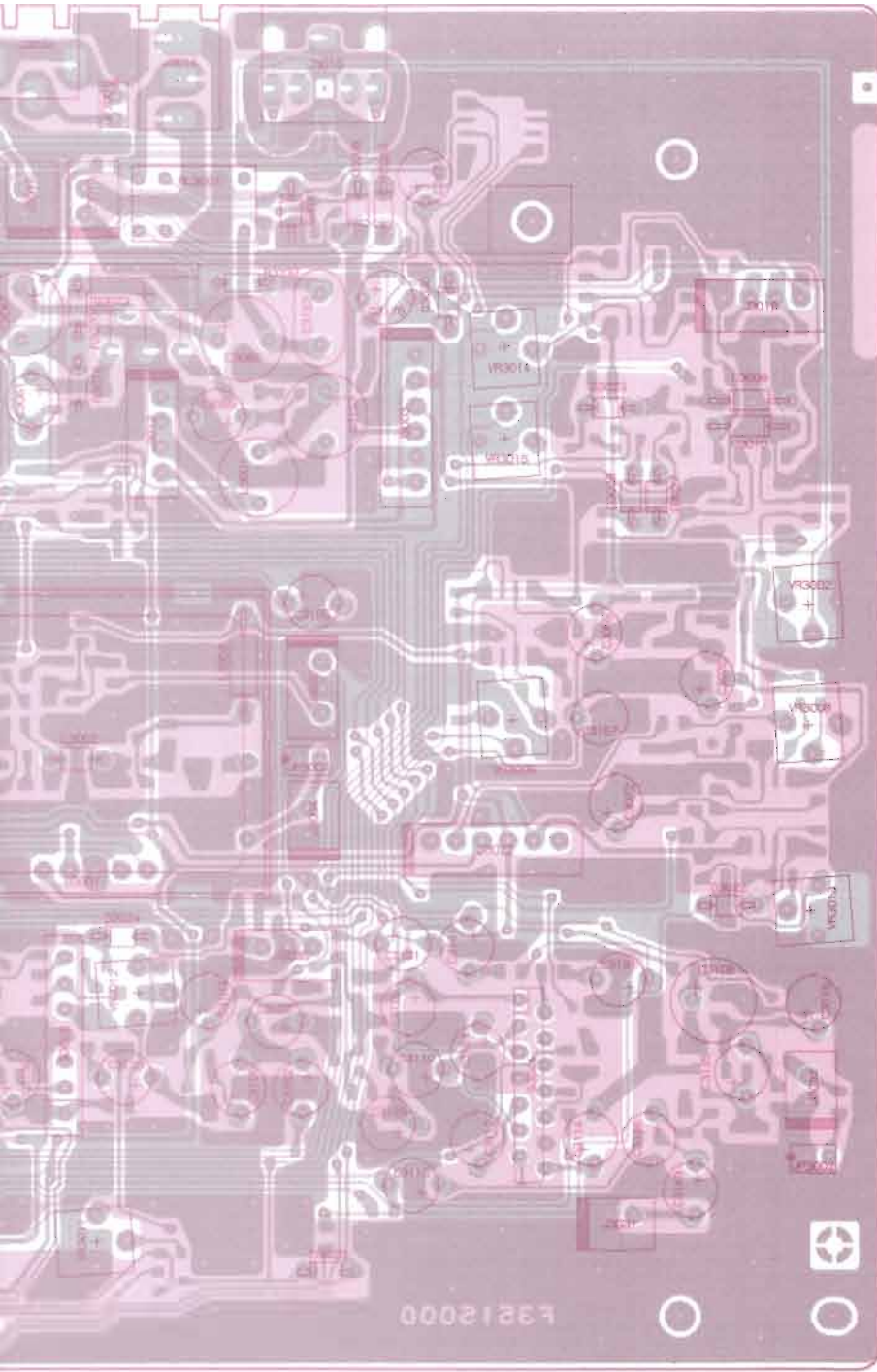
Pin 16



1. ST	2. MOND	1. MONI	2. SUB	1. AFPS	2. AFPC	1. ALC	2. FWD	4. CNTL	2. FMUT
3. PLK	4. NC	3. DVS1	4. DVS2	3. AEFA	4. MICG	3. CDMF	4. REV	3. GND	4. PRM
5. VC1	6. NC	5. DVS3	6. DVS4	5. DFIL	6. CK3	5. DRC	6. 10W	2. HPS	5. FM
7. VC3	8. VCA	7. DVS5	8. DIC	7. DATA	8. S14	7. 50W	8. GNU	1. HPM	7. CW/FSK
9. MOF	10. BP	9. CNT1	10. CNT2	9. ST5	10. MAIN	9. PWR1	10. PWIV	10. GND	9. I
11. PTT	12. TTYK	11. VOX	12. SKEY	11. SB	12. VREF	11. AFREV	12. EMOM	12. -B	11. I
13. MBSY	14. MUTE	13. GND	14. MVU	J3006	J3024	J3033	J3007	13. FSO	12. -B
15. SQL	16. MONG	15. MIX	16. MN	To CNT1 Unit J5026 (See Page 6J-3)	To CNT1 Unit J5009 (See Page 6J-3)	To ALC Unit J6807 (See Page 6P-1)	To ALC Unit J6803 (See Page 6P-1)	14. FAF	14. FAF
J3029	J3028	J3005	J3015					15. AUG	15. AUG
To CNTL Unit J5003 (See Page 6J-3)	To CNTL Unit J5004 (See Page 6J-3)	To IF Unit J2002 (See Page 6B-3)	To IF Unit J2004 (See Page 6B-3)						

E

F



2. CWTUN J3017
To ALC Unit J6801
(See Page 6P-1)
1. GND

2. SP J3013
To Speaker
1. GND

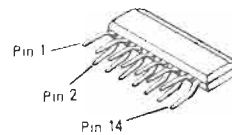
1. GND J3018
To ALC Unit J6811
(See Page 6P-1)
2. FWD
3. REV
4. 13

1. GND J3003
To RX2 Unit J8001
(See Page 6S-3)
2. -9
3. RX9
4. 13
5. GND
6. SAF

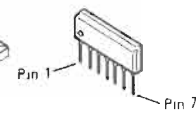
1. GND J3012
To REG Unit J9004
(See Page 6W-3)
2. 13-1
3. 13-2
4. 13

J3032
To Display Unit J5528
(See Page 6K-3)

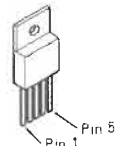
2. MIC
1. GND



M51131L
(Q3005, 3044)



μ PC1037H
(Q3007, 3046)



TDA2003
(Q3022)

J3028 2 IF TX
1. GND
To IF Unit J7009
(See Page 6B-3)
J3037 To DSP-A Unit J7001
(See Page 6Q-1)

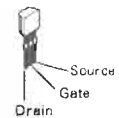
J3004 7 to 1
1. GND
To Local Unit J4007
(See Page 6F-3)

1. GND
2. IALC
3. 5
4. 9
5. -9
6. NC
J3022
To REG Unit J9010
(See Page 6W-3)

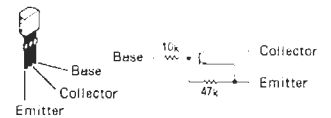
1. GND
2. FMIC1
J3031
To ALC Unit J6805
(See Page 6P-1)

1. TX AF
2. GND
3. D-AF
J3035
To DSP-A Unit J7801
(See Page 6Q-1)

obverse view of component side

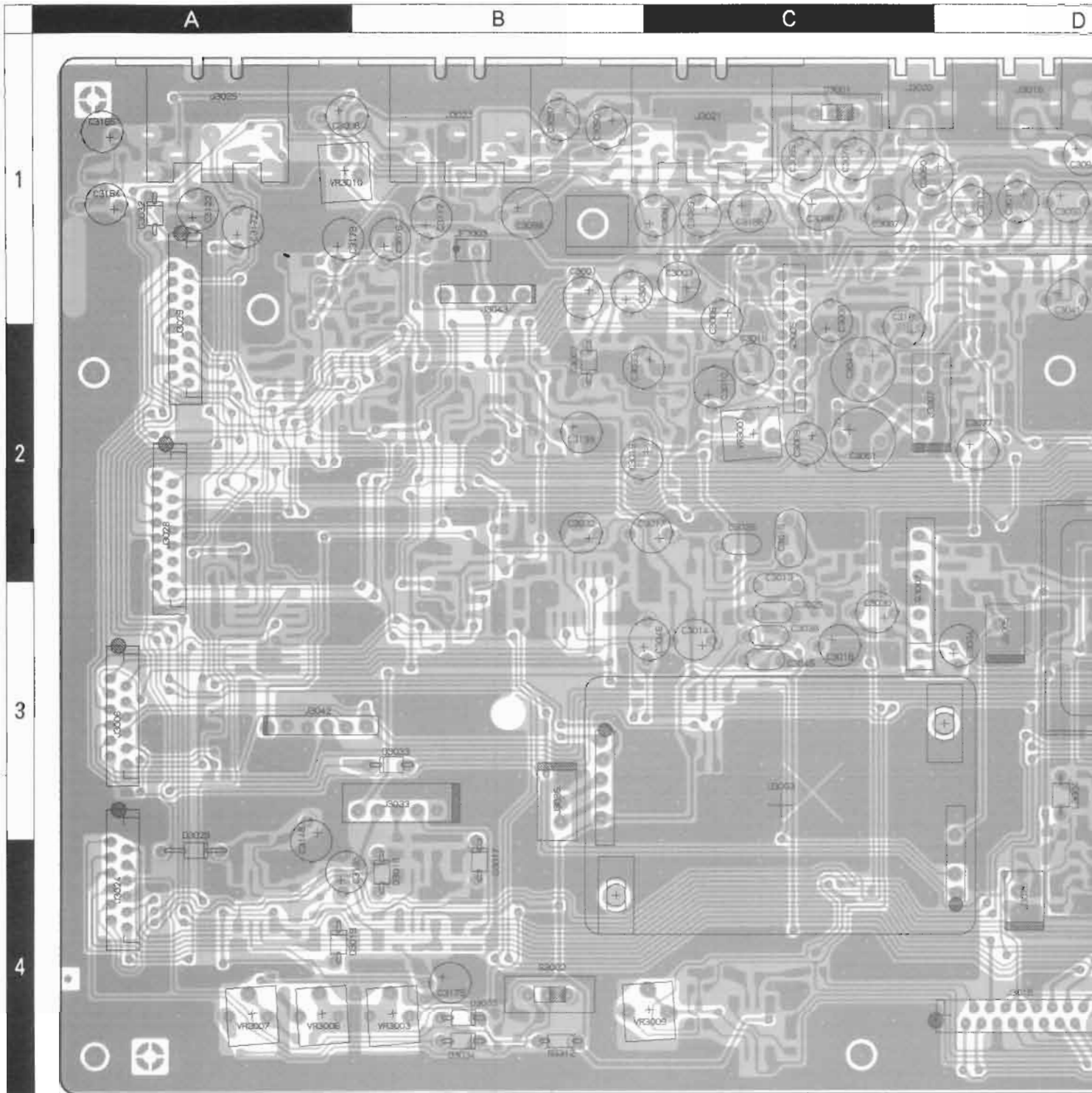


2SK184
(Q3071, 3072)



BA1A4P
(Q3070)

Parts Layout



- J3029
To CNTL Unit J5003
(See Page 6J-3)
- | | |
|----------|----------|
| 1. ST | 2. MONO |
| 3. PLK | 4. NC |
| 5. VC1 | 6. NC |
| 7. VC3 | 8. VC4 |
| 9. MOF | 10. BP |
| 11. PTT | 12. TTYK |
| 13. MBSY | 14. MUTE |
| 15. SOL | 16. MONG |

- J3028
To CNTL Unit J5004
(See Page 6J-3)
- | | |
|---------|----------|
| 1. MONI | 2. SUB |
| 3. DVS1 | 4. DVS2 |
| 5. DVS3 | 6. DVS4 |
| 7. DVS5 | 8. DIC |
| 9. CNT1 | 10. CNT2 |
| 11. VOX | 12. SKEY |
| 13. GND | 14. MVU |
| 15. MIX | 16. MN |

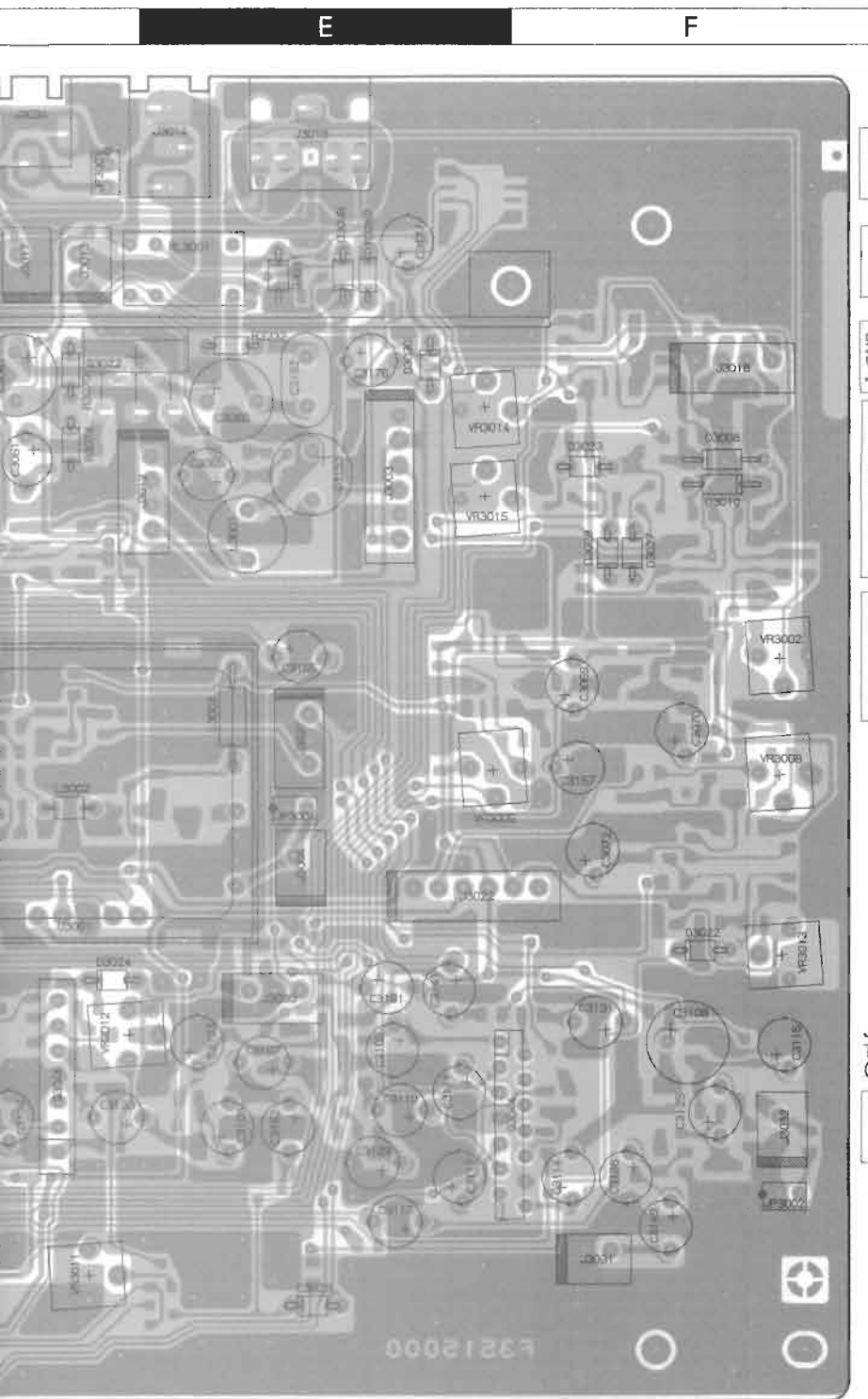
- J3006
To CNTL Unit J5026
(See Page 6J-3)
- | | |
|---------|----------|
| 1. AFFS | 2. AFFC |
| 3. AFFA | 4. MICG |
| 5. OFIL | 6. CK3 |
| 7. DATA | 8. ST4 |
| 9. ST5 | 10. MAIN |
| 11. SB | 12. VREF |

- J3024
To CNTL Unit J5009
(See Page 6J-3)
- | | |
|-----------|----------|
| 1. ALC | 2. FWD |
| 3. COMP | 4. REV |
| 5. DRC | 6. 10W |
| 7. 50W | 8. GND |
| 9. PWR1 | 10. PWR2 |
| 11. AFREV | 12. EMDM |

- J3003
To ALC Unit J6807
(See Page 6P-1)
- | | |
|----------|----------|
| 5. AVOX2 | 4. AVOX1 |
| 3. VOX-D | 2. VOX-G |
| 1. GND | |

- J3007
To ALC Unit J6803
(See Page 6P-1)
- | | |
|---------|-----------|
| 4. CNTL | 2. FMUT |
| 3. GND | 4. PRM |
| 2. HPS | 5. PM |
| 1. HPM | 7. CW/FSK |
| | 8. R |
| | 9. T |
| | 10. GND |
| | 11.5 |
| | 12. -9 |
| | 13. FSOL |
| | 14. FAF |
| | 15. AGC |
| | 16. G |

- J3015
To IF Unit J2004
(See Page 6B-3)
- | | |
|----------|--------|
| 2. IF RX | 1. GND |
|----------|--------|



2. CWTUN J3017
To ALC Unit J6801
(See Page 6P-1)
1. GND

2. SP J3013
To Speaker
1. GND

1. GND J3018
2. FWD To ALC Unit J6811
3. REV (See Page 6P-1)
4. 13

1. GND J3003
2. -9 To RX2 Unit J8001
3. RX9 (See Page 6S-3)
4. 13
5. GND
6. SAF

1. GND J3012
2. 13-1 To REG Unit J9004
3. 13-2 (See Page 6W-3)
4. 13

J3032
To Display Unit J5528
(See Page 6K-3)

2. MIC
1. GND

J3026
To IF Unit J2009
(See Page 6B-3)
2. JF TX
1. GND

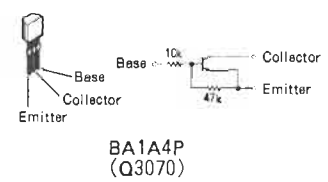
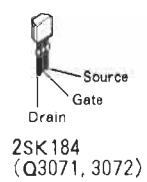
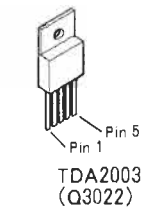
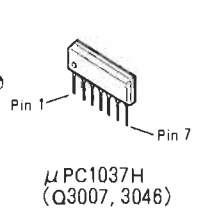
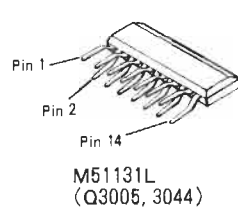
J3037
To DSP-A Unit J7001
(See Page 6Q-1)
1. D-MIC
2. GND
3. RX-AF

J3022
To REG Unit J9010
(See Page 6W-3)
1. GND
2. IALC
3, 5
4, 8
5, -8
6. NC

J3031
To ALC Unit J6805
(See Page 6P-1)
1. GND
2. FMIC1

J3004
To Local Unit J4007
(See Page 6F-3)
2. REF
1. GND

J3035
To DSP-A Unit J7001
(See Page 6Q-1)
1. TX-AF
2. GND
3. D-AF



obverse view of component side

Parts List

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
*** AF UNIT ***										
	PCB with Components (W/ DDS-CAR, I-DET UNIT)					CP5123002				
	Printed Circuit Board					F3515000				
C 3001	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3002	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3003	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3004	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3005	CHIP CAP.	0.0022uF	50V	B	GRM40B222M50PT	K22170809				
C 3006	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3008	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3009	AL. ELECTRO. CAP.	22uF	50V		50V220M5X11TR5	K46170022				
C 3010	AL. ELECTRO. CAP.	22uF	50V		50V220M5X11TR5	K46170022				
C 3011	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3012	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3013	FILM CAP.	0.015uF	50V		NNMTP153K50	K56170021				
C 3014	AL. ELECTRO. CAP.	2.2uF	50V		50V2R2M5X11TR5	K46170018				
C 3015	FILM CAP.	0.033uF	50V		NNMTP333K50	K56170023				
C 3016	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3017	AL. ELECTRO. CAP.	2.2uF	50V		50V2R2M5X11TR5	K46170018				
C 3018	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3019	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3021	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				
C 3022	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3023	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3024	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3025	FILM CAP.	0.0047uF	50V		NNMTP472K50	K56170018				
C 3026	FILM CAP.	0.0047uF	50V		NNMTP472K50	K56170018				
C 3027	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3028	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3029	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				
C 3030	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3032	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3033	AL. ELECTRO. CAP.	22uF	50V		50V220M5X11TR5	K46170022				
C 3034	AL. ELECTRO. CAP.	100uF	10V		10V101M5X11TR5	K46100004				
C 3035	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3036	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3038	FILM CAP.	0.0047uF	50V		NNMTP472K50	K56170018				
C 3041	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3042	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3044	AL. ELECTRO. CAP.	330uF	16V		16V331M8X11TR5	K46120002				
C 3045	FILM CAP.	0.0022uF	50V		NNMTP222K50	K56170016				
C 3046	AL. ELECTRO. CAP.	2.2uF	50V		50V2R2M5X11TR5	K46170018				
C 3048	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3050	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3051	AL. ELECTRO. CAP.	330uF	16V		16V331M8X11TR5	K46120002				
C 3052	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				

AF Unit

REF.	DESCRIPTION	VALUE	WV	TOL.	MFR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
C 3053	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3054	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3055	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3056	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3058	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3059	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3060	AL. ELECTRO. CAP.	470uF	10V		10V471M8X11TR5	K46100006				
C 3061	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3062	CHIP CAP.	22pF	50V	CH	GRM40CH220J50PT	K22170219				
C 3063	CHIP CAP.	0.0012uF	50V	B	GRM40B122M50PT	K22170806				
C 3064	CHIP CAP.	0.0012uF	50V	B	GRM40B122M50PT	K22170806				
C 3065	AL. ELECTRO. CAP.	47uF	25V		25V470M5X11TR5	K46140004				
C 3066	CHIP CAP.	0.047uF	50V	B	GRM40B473M50PT	K22170823				
C 3067	AL. ELECTRO. CAP.	470uF	10V		10V471M8X11TR5	K46100006				
C 3068	CHIP CAP.	0.0047uF	50V	B	GRM40B472M50PT	K22170813				
C 3069	AL. ELECTRO. CAP.	0.47uF	50V		50VR47M5X11TR5	K46170016				
C 3070	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3071	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3072	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3073	CHIP CAP.	0.001uF	50V	B	GRM40B102M50PT	K22170805				
C 3074	CHIP CAP.	0.001uF	50V	B	GRM40B102M50PT	K22170805				
C 3075	CHIP CAP.	100pF	50V	CH	GRM40CH101J50PT	K22170235				
C 3076	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3077	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3078	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3079	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				
C 3080	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3081	CHIP CAP.	100pF	50V	CH	GRM40CH101J50PT	K22170235				
C 3082	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				
C 3084	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3085	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3086	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				
C 3087	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3088	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				
C 3089	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3090	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3091	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3092	CHIP CAP.	220pF	50V	CH	GRM40CH221J50PT	K22170243				
C 3093	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				
C 3094	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3095	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3096	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3097	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3098	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3099	AL. ELECTRO. CAP.	220uF	10V		10V221M6X11TR5	K46100005				
C 3100	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3103	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3105	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3106	AL. ELECTRO. CAP.	2.2uF	50V		50V2R2M5X11TR5	K46170018				

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY ADR
C 3107	AL. ELECTRO. CAP.	2.2uF	50V		50V2R2M5X11TR5	K46170018			
C 3108	AL. ELECTRO. CAP.	220uF	25V		25V221M8X11TR5	K46140006			
C 3109	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021			
C 3110	AL. ELECTRO. CAP.	2.2uF	50V		50V2R2M5X11TR5	K46170018			
C 3111	AL. ELECTRO. CAP.	22uF	50V		50V220M5X11TR5	K46170022			
C 3112	AL. ELECTRO. CAP.	22uF	50V		50V220M5X11TR5	K46170022			
C 3113	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017			
C 3114	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017			
C 3115	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021			
C 3116	CHIP CAP.	220pF	50V	CH	GRM40CH221J50PT	K22170243			
C 3117	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017			
C 3118	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008			
C 3119	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817			
C 3120	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817			
C 3122	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017			
C 3123	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008			
C 3124	CHIP CAP.	22pF	50V	CH	GRM40CH220J50PT	K22170219			
C 3125	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017			
C 3126	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008			
C 3127	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817			
C 3128	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817			
C 3129	AL. ELECTRO. CAP.	47uF	50V		50V470M6X11TR5	K46170024			
C 3131	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017			
C 3132	CHIP CAP.	0.001uF	50V	B	GRM40B102M50PT	K22170805			
C 3133	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021			
C 3134	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008			
C 3135	AL. ELECTRO. CAP.	4.7uF	50V		50V4R7M5X11TR5	K46170020			
C 3136	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021			
C 3137	CHIP CAP.	22pF	50V	CH	GRM40CH220J50PT	K22170219			
C 3138	AL. ELECTRO. CAP.	47uF	50V		50V470M6X11TR5	K46170024			
C 3139	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021			
C 3140	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005			
C 3141	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017			
C 3142	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817			
C 3143	CHIP CAP.	0.001uF	50V	B	GRM40B102M50PT	K22170805			
C 3144	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008			
C 3146	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817			
C 3147	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817			
C 3148	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021			
C 3149	AL. ELECTRO. CAP.	2.2uF	50V		50V2R2M5X11TR5	K46170018			
C 3150	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008			
C 3151	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008			
C 3152	FILM CAP.	0.1uF	50V		NNMTP104K50	K56170026			
C 3153	AL. ELECTRO. CAP.	330uF	16V		16V331M8X11TR5	K46120002			
C 3154	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817			
C 3155	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021			
C 3156	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021			
C 3157	AL. ELECTRO. CAP.	0.22uF	50V		50VR22M5X11TR5	K46170014			
C 3159	TANTALUM CAP.	10uF	16V		DN1C100M1S	K70127106			

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REF.	DESCRIPTION	VALUE	WV	TOL.	MFRG'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
C 3160	TANTALUM CAP.	10uF	16V		DN1C100M1S	K70127106				
C 3161	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3164	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3165	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3170	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				
C 3171	CHIP CAP.	0.1uF	25V	F	GRM40F104Z25PT	K22141005				
C 3172	AL. ELECTRO. CAP.	1uF	50V		50V010M5X11TR5	K46170017				
C 3173	CHIP CAP.	100pF	50V	CH	GRM40CH101J50PT	K22170235				
C 3174	TANTALUM CHIP CAP.	0.47uF	25V		TESVA1E474M1-8R	K78140009				
C 3175	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3176	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3177	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3178	TANTALUM CHIP CAP.	1uF	16V		TESVA1C105M1-8R	K78120009				
C 3179	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3180	TANTALUM CHIP CAP.	1uF	16V		TESVA1C105M1-8R	K78120009				
C 3181	TANTALUM CHIP CAP.	1uF	16V		TESVA1C105M1-8R	K78120009				
C 3182	TANTALUM CHIP CAP.	1uF	16V		TESVA1C105M1-8R	K78120009				
C 3183	TANTALUM CHIP CAP.	10uF	6.3V		TEMSVA0J106M-8R	K78080027				
C 3184	TANTALUM CHIP CAP.	10uF	6.3V		TEMSVA0J106M-8R	K78080027				
C 3185	AL. ELECTRO. CAP.	10uF	50V		50V100M5X11TR5	K46170021				
C 3186	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3187	CHIP CAP.	0.01uF	50V	B	GRM40B103M50PT	K22170817				
C 3188	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3189	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3190	TANTALUM CHIP CAP.	0.22uF	35V		TESVA1V224M1-8R	K78160027				
C 3191	CHIP CAP.	0.047uF	50V	B	GRM40B473M50PT	K22170823				
C 3192	CHIP CAP.	0.1uF	25V	B	GRM40B104M25PT	K22140811				
C 3193	CHIP CAP.	0.047uF	50V	F	GRM40F473Z50PT	K22171008				
C 3194	CERAMIC CAP.	0.1uF	50V	F	UPO50F104Z-A-B	K28179003				
C 3195	TANTALUM CAP.	10uF	16V		DN1C100M1S	K70127106				
C 3196	TANTALUM CAP.	10uF	16V		DN1C100M1S	K70127106				
C 3197	CHIP CAP.	0.001uF	50V	B	GRM40B102M50PT	K22170805				
C 3198	CHIP CAP.	0.001uF	50V	B	GRM40B102M50PT	K22170805				
D 3002	DIODE				1SS270TJ	G2060004				
D 3003	DIODE				1SS226 TE85R	G2070003				
D 3004	DIODE				DAN202K T146	G2070182				
D 3005	DIODE				1SS270TJ	G2060004				
D 3006	DIODE				DAN202K T146	G2070182				
D 3007	DIODE				02CZ8.2Y TE85R	G2070146				
D 3008	DIODE				HZ12A2L TE	G2060015				
D 3009	DIODE				DAN202K T146	G2070182				
D 3010	DIODE				HZ12A2L TE	G2060015				
D 3012	DIODE				DAP202K T146	G2070180				
D 3013	DIODE				DAN202K T146	G2070182				
D 3014	DIODE				DAN202K T146	G2070182				
D 3015	DIODE				1SS226 TE85R	G2070003				
D 3016	DIODE				1SS270TJ	G2060004				
D 3017	DIODE				1SS270TJ	G2060004				
D 3018	DIODE				DAN202K T146	G2070182				
D 3019	DIODE				1SS270TJ	G2060004				

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
D 3021	DIODE				DAN202K T146	G2070182				
D 3022	DIODE				1SS270TJ	G2060004				
D 3023	DIODE				1SS270TJ	G2060004				
D 3024	DIODE				1SS270TJ	G2060004				
D 3025	DIODE				1SS270TJ	G2060004				
D 3027	DIODE				1SS270TJ	G2060004				
D 3028	DIODE				1SS270TJ	G2060004				
D 3029	DIODE				1SS270TJ	G2060004				
D 3030	DIODE				1SS270TJ	G2060004				
D 3031	DIODE				1SS270TJ	G2060004				
D 3032	DIODE				1SS270TJ	G2060004				
D 3033	DIODE				1SS270TJ	G2060004				
D 3034	DIODE				1SS270TJ	G2060004				
D 3035	DIODE				1SS270TJ	G2060004				
D 3036	DIODE				1SS270TJ	G2060004				
D 3037	DIODE				1SS270TJ	G2060004				
J 3003	CONNECTOR				SC25-06WS	P0090625				
J 3004	CONNECTOR				SC25-02WS	P0090621				
J 3005	CONNECTOR				SC25-02WS	P0090621				
J 3006	CONNECTOR				12FMZ-BT	P1090901				
J 3007	CONNECTOR				SC25-04WS	P0090623				
J 3012	CONNECTOR				SC25-04WS	P0090623				
J 3013	CONNECTOR				SC25-02WS	P0090621				
J 3014	CONNECTOR				SG8035#01	P1090350				
J 3015	CONNECTOR				16FMZ-BT	P1090902				
J 3016	CONNECTOR				JPJ2545-01-510	P1090633				
J 3017	CONNECTOR				SC25-02WS	P0090621				
J 3018	CONNECTOR				SC25-04WS	P0090623				
J 3019	CONNECTOR				HSJ0916-01-010	P1090546				
J 3020	CONNECTOR				JPJ2545-01-510	P1090633				
J 3021	CONNECTOR				TCS5073-14-4151	P1090645				
J 3022	CONNECTOR				SC25-06WS	P0090625				
J 3023	CONNECTOR				TCS5073-15-4151	P1090646				
J 3024	CONNECTOR				12FMZ-BT	P1090901				
J 3025	CONNECTOR				TCS5073-17-4151	P1090648				
J 3026	CONNECTOR				SC25-02WS	P0090621				
J 3028	CONNECTOR				16FMZ-BT	P1090902				
J 3029	CONNECTOR				16FMZ-BT	P1090902				
J 3031	CONNECTOR				SC25-02WS	P0090621				
J 3032	CONNECTOR				SC25-02WS	P0090621				
J 3033	CONNECTOR				SC25-05WS	P0090624				
J 3034	CONNECTOR				JPJ2545-01-510	P1090633				
J 3035	CONNECTOR				SC25-03WS	P0090622				
J 3036	CONNECTOR				SC25-03WS	P0090622				
J 3037	CONNECTOR				SC25-03WS	P0090622				
J 3040	CONNECTOR				3022-05B	P0090594				
J 3041	CONNECTOR				3022-06B	P0090473				
J 3042	CONNECTOR				3022-06B	P0090473				

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REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
J 3043	CONNECTOR				3022-05B	P0090594				
JP3001	WIRE-ASSY					T9206055				
JP3003	WIRE-ASSY					T9206055				
L 3001	M. RFC	330uH			RCR-875D-331K	L1190393				
L 3002	M. RFC	100uH			LAP02TA101K	L1790070				
L 3003	M. RFC	1mH			LAL03TA102K	L1790119				
L 3004	M. RFC	220uH			LAP02TA221K	L1790074				
L 3005	M. RFC	1mH			LAL03TA102K	L1790119				
Q 3001	IC				UPD4066BG-T2	G1091035				e3
Q 3002	FET				2SK160-T2B K6	G3801607F				d1
Q 3003	IC				UPD4053BG-T2	G1091034				f3
Q 3004	TRANSISTOR				2SC2812L6-TA	G3328127F				c2
Q 3005	IC				M51131L	G1091077				C2
Q 3006	TRANSISTOR				2SC2812L6-TA	G3328127F				d2
Q 3007	IC				UPC1037H	G1090101				C3
Q 3008	IC				M5218AFP-600C	G1091607				d3
Q 3009	TRANSISTOR				2SC2812L6-TA	G3328127F				d3
Q 3010	TRANSISTOR				2SC4047-TA	G3340477				d2
Q 3011	TRANSISTOR				2SC4047-TA	G3340477				d2
Q 3013	IC				M5218AFP-600C	G1091607				d3
Q 3014	IC				M5218AFP-600C	G1091607				c1
Q 3015	IC				M5216FP	G1091784				c1
Q 3016	TRANSISTOR				2SC2812L6-TA	G3328127F				c2
Q 3017	IC				TC4W66F TE12L	G1091493				c2
Q 3018	TRANSISTOR				2SC3444-T11-1E	G3334448E				b2
Q 3019	TRANSISTOR				2SC4047-TA	G3340477				b1
Q 3020	TRANSISTOR				2SC2812L6-TA	G3328127F				b3
Q 3021	TRANSISTOR				2SC2812L6-TA	G3328127F				b2
Q 3022	IC				TDA2003	G1090769				E1
Q 3023	IC				UPD4066BG-T2	G1091035				e2
Q 3024	IC				M5218AFP-600C	G1091607				a3
Q 3025	TRANSISTOR				2SC2812L6-TA	G3328127F				a2
Q 3026	IC				M5218AFP-600C	G1091607				a2
Q 3028	TRANSISTOR				2SC2812L6-TA	G3328127F				d1
Q 3029	TRANSISTOR				2SC2812L6-TA	G3328127F				c2
Q 3030	IC				M5218AFP-600C	G1091607				a2
Q 3032	TRANSISTOR				2SC2812L6-TA	G3328127F				d1
Q 3033	TRANSISTOR				2SC2812L6-TA	G3328127F				c2
Q 3034	TRANSISTOR				2SC4047-TA	G3340477				f4
Q 3035	TRANSISTOR				2SC4047-TA	G3340477				f4
Q 3036	TRANSISTOR				2SC4047-TA	G3340477				a2
Q 3037	TRANSISTOR				2SC2812L6-TA	G3328127F				d1
Q 3038	TRANSISTOR				2SC2812L6-TA	G3328127F				d1
Q 3039	TRANSISTOR				2SC2812L6-TA	G3328127F				e1
Q 3040	IC				M5223FP-600C	G1090990				d4
Q 3042	IC				TC4W66F TE12L	G1091493				e2
Q 3043	TRANSISTOR				2SC2812L6-TA	G3328127F				b4

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
Q 3044	IC				M51131L	G1091077				F4
Q 3045	TRANSISTOR				2SC2812L6-TA	G3328127F				b4
Q 3046	IC				UPC1037H	G1090101				D3
Q 3047	TRANSISTOR				2SC4047-TA	G3340477				a3
Q 3048	TRANSISTOR				2SC2812L6-TA	G3328127F				a4
Q 3049	TRANSISTOR				2SC2812L6-TA	G3328127F				c4
Q 3050	TRANSISTOR				2SC4047-TA	G3340477				b4
Q 3052	IC				M5223FP-600C	G1090990				e4
Q 3053	IC				M5223FP-600C	G1090990				f4
Q 3054	IC				TC4W66F TE12L	G1091493				e2
Q 3055	TRANSISTOR				2SC4047-TA	G3340477				e3
Q 3056	IC				M5218AFP-600C	G1091607				a1
Q 3058	TRANSISTOR				2SC4047-TA	G3340477				a2
Q 3059	TRANSISTOR				2SA1563-TB	G3115638				a2
Q 3060	TRANSISTOR				2SA1563-TB	G3115638				a2
Q 3061	TRANSISTOR				2SC2812L6-TA	G3328127F				f1
Q 3062	IC				TC4S66F TE85R	G1090893				e3
Q 3063	TRANSISTOR				2SC2812L6-TA	G3328127F				e2
Q 3064	TRANSISTOR				2SC2812L6-TA	G3328127F				e1
Q 3066	IC				M5218AFP-600C	G1091607				a1
Q 3067	IC				TC4S66F TE85R	G1090893				f2
Q 3068	TRANSISTOR				2SC4047-TA	G3340477				a3
Q 3069	TRANSISTOR				2SC4047-TA	G3340477				e4
Q 3070	TRANSISTOR				BA1A4P-T	G3050003				
Q 3071	FET				2SK184Y(TPE4)	G3801844Y				
Q 3072	FET				2SK184Y(TPE4)	G3801844Y				
R 3001	CHIP RES.	100		1/10W 5%	RMC1/10T 101J	J24205101				
R 3002	CHIP RES.	100		1/10W 5%	RMC1/10T 101J	J24205101				
R 3003	CHIP RES.	68K		1/10W 5%	RMC1/10T 683J	J24205683				
R 3004	CHIP RES.	68K		1/10W 5%	RMC1/10T 683J	J24205683				
R 3005	CHIP RES.	47K		1/10W 5%	RMC1/10T 473J	J24205473				
R 3006	CHIP RES.	100K		1/10W 5%	RMC1/10T 104J	J24205104				
R 3007	CHIP RES.	3.3K		1/10W 5%	RMC1/10T 332J	J24205332				
R 3008	CHIP RES.	100		1/10W 5%	RMC1/10T 101J	J24205101				
R 3009	CHIP RES.	47K		1/10W 5%	RMC1/10T 473J	J24205473				
R 3011	CHIP RES.	100K		1/10W 5%	RMC1/10T 104J	J24205104				
R 3012	CHIP RES.	150		1/10W 5%	RMC1/10T 151J	J24205151				
R 3013	CHIP RES.	4.7K		1/10W 5%	RMC1/10T 472J	J24205472				
R 3014	CHIP RES.	68K		1/10W 5%	RMC1/10T 683J	J24205683				
R 3015	CHIP RES.	150K		1/10W 5%	RMC1/10T 154J	J24205154				
R 3016	CHIP RES.	10K		1/10W 5%	RMC1/10T 103J	J24205103				
R 3017	CHIP RES.	10K		1/10W 5%	RMC1/10T 103J	J24205103				
R 3018	CHIP RES.	15K		1/10W 5%	RMC1/10T 153J	J24205153				
R 3019	CHIP RES.	15K		1/10W 5%	RMC1/10T 153J	J24205153				
R 3020	CHIP RES.	10K		1/10W 5%	RMC1/10T 103J	J24205103				
R 3021	CHIP RES.	10K		1/10W 5%	RMC1/10T 103J	J24205103				
R 3022	CHIP RES.	1K		1/10W 5%	RMC1/10T 102J	J24205102				
R 3023	CHIP RES.	22K		1/10W 5%	RMC1/10T 223J	J24205223				

AF Unit

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
R 3024	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3025	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3026	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3027	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3028	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3029	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3030	CHIP RES.	220	1/10W	5%	RMC1/10T 221J	J24205221				
R 3031	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3032	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3033	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3034	CHIP RES.	56	1/10W	5%	RMC1/10T 560J	J24205560				
R 3035	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3036	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3037	CHIP RES.	180	1/10W	5%	RMC1/10T 181J	J24205181				
R 3038	CHIP RES.	470	1/10W	5%	RMC1/10T 471J	J24205471				
R 3039	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3040	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3041	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3042	CHIP RES.	220K	1/10W	5%	RMC1/10T 224J	J24205224				
R 3043	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3044	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3045	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3046	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3047	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3048	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3049	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3050	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3051	CHIP RES.	47	1/10W	5%	RMC1/10T 470J	J24205470				
R 3052	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3053	CHIP RES.	220K	1/10W	5%	RMC1/10T 224J	J24205224				
R 3054	CHIP RES.	470	1/10W	5%	RMC1/10T 471J	J24205471				
R 3055	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3056	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3057	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3058	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3059	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3060	CHIP RES.	27K	1/10W	5%	RMC1/10T 273J	J24205273				
R 3061	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3062	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3063	CHIP RES.	470	1/10W	5%	RMC1/10T 471J	J24205471				
R 3065	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3066	CHIP RES.	270	1/10W	5%	RMC1/10T 271J	J24205271				
R 3067	CHIP RES.	2.2K	1/10W	5%	RMC1/10T 222J	J24205222				
R 3068	CHIP RES.	470	1/10W	5%	RMC1/10T 471J	J24205471				
R 3069	CHIP RES.	470	1/10W	5%	RMC1/10T 471J	J24205471				
R 3070	CARBON FILM RES.	270	1/6W	5%	RD16TPJ271	J07225271				
R 3072	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3073	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3074	CARBON FILM RES.	2.2	1/6W	5%	RD16TPJ2R2	J07225229				

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
R 3075	CHIP RES.	4.7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3076	CHIP RES.	4.7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3077	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3078	CHIP RES.	150K	1/10W	5%	RMC1/10T 154J	J24205154				
R 3079	CHIP RES.	0	1/10W	5%	RMC1/10T 000J	J24205000				
R 3080	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3081	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3082	CHIP RES.	3.3K	1/10W	5%	RMC1/10T 332J	J24205332				
R 3083	CHIP RES.	1M	1/10W	5%	RMC1/10T 105J	J24205105				
R 3084	CHIP RES.	33K	1/10W	5%	RMC1/10T 333J	J24205333				
R 3085	CHIP RES.	150K	1/10W	5%	RMC1/10T 154J	J24205154				
R 3086	CHIP RES.	150K	1/10W	5%	RMC1/10T 154J	J24205154				
R 3087	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3088	CHIP RES.	3.3K	1/10W	5%	RMC1/10T 332J	J24205332				
R 3089	CHIP RES.	4.7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3090	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3091	CHIP RES.	3.9K	1/10W	5%	RMC1/10T 392J	J24205392				
R 3092	CHIP RES.	33K	1/10W	5%	RMC1/10T 333J	J24205333				
R 3094	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3095	CHIP RES.	33K	1/10W	5%	RMC1/10T 333J	J24205333				
R 3096	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3097	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3098	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3099	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3100	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3101	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3102	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3104	CHIP RES.	33K	1/10W	5%	RMC1/10T 333J	J24205333				
R 3105	CHIP RES.	150K	1/10W	5%	RMC1/10T 154J	J24205154				
R 3106	CHIP RES.	150K	1/10W	5%	RMC1/10T 154J	J24205154				
R 3107	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3108	CHIP RES.	33K	1/10W	5%	RMC1/10T 333J	J24205333				
R 3109	CHIP RES.	2.2K	1/10W	5%	RMC1/10T 222J	J24205222				
R 3110	CHIP RES.	180K	1/10W	5%	RMC1/10T 184J	J24205184				
R 3111	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3112	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3114	CHIP RES.	33K	1/10W	5%	RMC1/10T 333J	J24205333				
R 3115	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3117	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3118	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3119	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3122	CHIP RES.	180K	1/10W	5%	RMC1/10T 184J	J24205184				
R 3124	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3127	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3128	CHIP RES.	33K	1/10W	5%	RMC1/10T 333J	J24205333				
R 3129	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3130	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3131	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3135	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				

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REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
R 3136	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3137	CHIP RES.	0	1/10W	5%	RMC1/10T 000J	J24205000				
R 3138	CHIP RES.	68K	1/10W	5%	RMC1/10T 683J	J24205683				
R 3139	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3140	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3141	CHIP RES.	33K	1/10W	5%	RMC1/10T 333J	J24205333				
R 3142	CHIP RES.	3. 3K	1/10W	5%	RMC1/10T 332J	J24205332				
R 3143	CHIP RES.	4. 7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3144	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3145	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3146	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3147	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3148	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3149	CHIP RES.	33K	1/10W	5%	RMC1/10T 333J	J24205333				
R 3150	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3151	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3152	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3153	CHIP RES.	3. 3K	1/10W	5%	RMC1/10T 332J	J24205332				
R 3155	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3158	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3160	CHIP RES.	3. 3K	1/10W	5%	RMC1/10T 332J	J24205332				
R 3161	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3162	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3163	CHIP RES.	22K	1/10W	5%	RMC1/10T 223J	J24205223				
R 3164	CHIP RES.	470	1/10W	5%	RMC1/10T 471J	J24205471				
R 3166	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3167	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3169	CHIP RES.	2. 2K	1/10W	5%	RMC1/10T 222J	J24205222				
R 3170	CHIP RES.	18K	1/10W	5%	RMC1/10T 183J	J24205183				
R 3171	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3172	CHIP RES.	68K	1/10W	5%	RMC1/10T 683J	J24205683				
R 3173	CHIP RES.	180	1/10W	5%	RMC1/10T 181J	J24205181				
R 3174	CHIP RES.	22K	1/10W	5%	RMC1/10T 223J	J24205223				
R 3176	CHIP RES.	220	1/10W	5%	RMC1/10T 221J	J24205221				
R 3177	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3178	CHIP RES.	3. 3K	1/10W	5%	RMC1/10T 332J	J24205332				
R 3179	CHIP RES.	4. 7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3181	CHIP RES.	150	1/10W	5%	RMC1/10T 151J	J24205151				
R 3182	CHIP RES.	3. 3M	1/10W	5%	RMC1/10T 335J	J24205335				
R 3183	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3184	CHIP RES.	2. 2K	1/10W	5%	RMC1/10T 222J	J24205222				
R 3186	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3187	CHIP RES.	82	1/10W	5%	RMC1/10T 820J	J24205820				
R 3189	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3190	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3191	CHIP RES.	4. 7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3192	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3193	CHIP RES.	2. 2K	1/10W	5%	RMC1/10T 222J	J24205222				
R 3194	CHIP RES.	2. 2K	1/10W	5%	RMC1/10T 222J	J24205222				

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
R 3195	CHIP RES.	220	1/10W	5%	RMC1/10T 221J	J24205221				
R 3196	CHIP RES.	330	1/10W	5%	RMC1/10T 331J	J24205331				
R 3197	CHIP RES.	180	1/10W	5%	RMC1/10T 181J	J24205181				
R 3198	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3199	CHIP RES.	470	1/10W	5%	RMC1/10T 471J	J24205471				
R 3201	CHIP RES.	4.7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3202	CHIP RES.	470	1/10W	5%	RMC1/10T 471J	J24205471				
R 3203	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3204	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3205	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3206	CHIP RES.	470K	1/10W	5%	RMC1/10T 474J	J24205474				
R 3207	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3208	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3209	CHIP RES.	220	1/10W	5%	RMC1/10T 221J	J24205221				
R 3210	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3211	CHIP RES.	15K	1/10W	5%	RMC1/10T 153J	J24205153				
R 3212	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3213	CHIP RES.	330K	1/10W	5%	RMC1/10T 334J	J24205334				
R 3214	CHIP RES.	2.2K	1/10W	5%	RMC1/10T 222J	J24205222				
R 3215	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3216	CHIP RES.	2.2K	1/10W	5%	RMC1/10T 222J	J24205222				
R 3217	CHIP RES.	4.7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3218	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3219	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3220	CHIP RES.	470K	1/10W	5%	RMC1/10T 474J	J24205474				
R 3221	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3222	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3223	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3224	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3225	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3226	CHIP RES.	56K	1/10W	5%	RMC1/10T 563J	J24205563				
R 3227	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3228	CHIP RES.	56K	1/10W	5%	RMC1/10T 563J	J24205563				
R 3229	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3230	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3232	CARBON FILM RES.	1	1/6W	5%	RD16TPJ010	J07225010				
R 3233	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3234	CHIP RES.	4.7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3238	CHIP RES.	4.7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3239	CHIP RES.	4.7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3240	CARBON FILM RES.	47K	1/6W	5%	RD16TPJ473	J07225473				
R 3241	CHIP RES.	18K	1/10W	5%	RMC1/10T 183J	J24205183				
R 3242	CHIP RES.	330	1/10W	5%	RMC1/10T 331J	J24205331				
R 3243	CHIP RES.	2.2K	1/10W	5%	RMC1/10T 222J	J24205222				
R 3244	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3245	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3246	CHIP RES.	4.7K	1/10W	5%	RMC1/10T 472J	J24205472				
R 3247	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3248	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				

AF Unit

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY	ADR
R 3249	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3250	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3251	CHIP RES.	8.2K	1/10W	5%	RMC1/10T 822J	J24205822				
R 3252	CARBON FILM RES.	100K	1/6W	5%	RD16PJ104	J01225104				
R 3253	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3254	CHIP RES.	27K	1/10W	5%	RMC1/10T 273J	J24205273				
R 3255	CHIP RES.	270	1/10W	5%	RMC1/10T 271J	J24205271				
R 3256	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3257	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3258	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3259	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3260	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3261	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3262	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3264	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3265	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3266	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3267	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3268	CHIP RES.	120K	1/10W	5%	RMC1/10T 124J	J24205124				
R 3269	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3270	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3272	CHIP RES.	100	1/10W	5%	RMC1/10T 101J	J24205101				
R 3273	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3274	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3275	CHIP RES.	180	1/10W	5%	RMC1/10T 181J	J24205181				
R 3276	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3277	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3278	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473				
R 3279	CHIP RES.	0	1/10W	5%	RMC1/10T 000J	J24205000				
R 3280	CHIP RES.	180	1/10W	5%	RMC1/10T 181J	J24205181				
R 3281	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3282	CARBON FILM RES.	330	1/6W	5%	RD16TPJ331	J07225331				
R 3283	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3284	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3285	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3286	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104				
R 3287	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3288	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3289	CHIP RES.	3.3K	1/10W	5%	RMC1/10T 332J	J24205332				
R 3290	CHIP RES.	2.7K	1/10W	5%	RMC1/10T 272J	J24205272				
R 3291	CHIP RES.	3.3K	1/10W	5%	RMC1/10T 332J	J24205332				
R 3292	CHIP RES.	2.7K	1/10W	5%	RMC1/10T 272J	J24205272				
R 3293	CHIP RES.	2.2K	1/10W	5%	RMC1/10T 222J	J24205222				
R 3294	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102				
R 3295	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3296	CHIP RES.	1.5K	1/10W	5%	RMC1/10T 152J	J24205152				
R 3297	CHIP RES.	6.8K	1/10W	5%	RMC1/10T 682J	J24205682				
R 3298	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103				
R 3299	CHIP RES.	470K	1/10W	5%	RMC1/10T 474J	J24205474				

REF.	DESCRIPTION	VALUE	WV	TOL.	MFGR'S DESIG	YAESU P/N	VERS.	LOT.	LAY ADR
R 3300	CHIP RES.	470K	1/10W	5%	RMC1/10T 474J	J24205474			
R 3301	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473			
R 3302	CHIP RES.	4. 7K	1/10W	5%	RMC1/10T 472J	J24205472			
R 3303	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102			
R 3304	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103			
R 3305	CHIP RES.	2. 2M	1/10W	5%	RMC1/10T 225J	J24205225			
R 3306	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103			
R 3307	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102			
R 3308	CHIP RES.	1K	1/10W	5%	RMC1/10T 102J	J24205102			
R 3309	CHIP RES.	4. 7K	1/10W	5%	RMC1/10T 472J	J24205472			
R 3310	CHIP RES.	4. 7K	1/10W	5%	RMC1/10T 472J	J24205472			
R 3311	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103			
R 3314	CHIP RES.	1M	1/10W	5%	RMC1/10T 105J	J24205105			
R 3315	CARBON FILM RES.	10K	1/6W	5%	RD16TPJ103	J07225103			
R 3316	CARBON FILM RES.	10K	1/6W	5%	RD16TPJ103	J07225103			
R 3317	CARBON FILM RES.	68K	1/6W	5%	RD16TPJ683	J07225683			
R 3318	CARBON FILM RES.	1K	1/6W	5%	RD16TPJ102	J07225102			
R 3319	CARBON FILM RES.	100K	1/6W	5%	RD16PJ104	J01225104			
R 3320	CHIP RES.	10K	1/10W	5%	RMC1/10T 103J	J24205103			
R 3321	CHIP RES.	100K	1/10W	5%	RMC1/10T 104J	J24205104			
R 3322	CHIP RES.	47K	1/10W	5%	RMC1/10T 473J	J24205473			
RL3001	RELAY		DC12V		AG4013	M1190090			
S 3001	SLIDE SWITCH				SSSS912N-2A-OR	N6090094			
S 3002	SLIDE SWITCH				SSSS912N-2A-OR	N6090094			
VR3001	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3002	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3003	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3005	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3006	POT.	2. 2K		B	RH0638CJ3R 2. 2KB	J51808222			
VR3007	POT.	4. 7K		B	RH0638CS3R 4. 7KB	J51808472			
VR3008	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3009	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3010	POT.	1K		B	RH0638C13R 1KB	J51808102			
VR3011	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3012	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3013	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3014	POT.	10K		B	RH0638C14R 10KB	J51808103			
VR3015	POT.	10K		B	RH0638C14R 10KB	J51808103			
	THERMAL CONDUCTOR					Q9000548			
	NUT BOARD					R0102810			
	SHIELD COVER					R0131640			
	HEATSINK PLATE					R0132050			
	CARD SPACER (2pcs)					S6000191			